DSP56301

24-Bit Digital Signal Processor

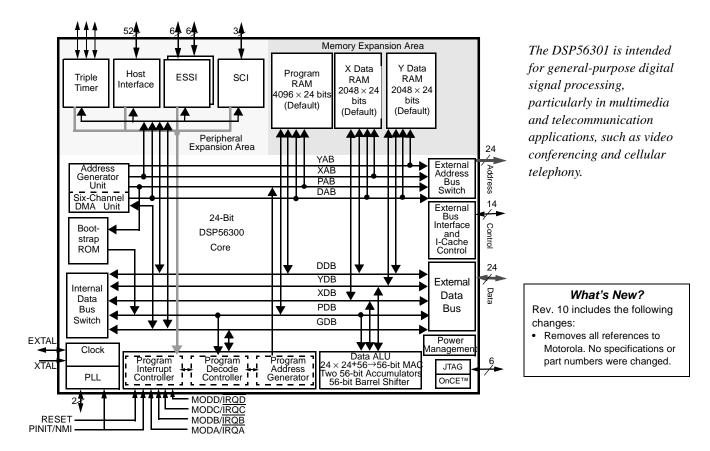


Figure 1. DSP56301 Block Diagram

The DSP56301 is a member of the DSP56300 core family of programmable CMOS Digital Signal Processors (DSPs). This family uses a high-performance, single clock cycle per instruction engine. Significant architectural features of the DSP56300 core family include a barrel shifter, 24-bit addressing, instruction cache, and DMA. The DSP56301 offers 80/100 MIPS using an internal 80/100 MHz clock at 3.0-3.6 volts. The DSP56300 core family offers a rich instruction set and low power dissipation, as well as increasing levels of speed and power, enabling wireless, telecommunications, and multimedia products.



Table of Contents

	DSP56301 Features	ii
	Target Applications	
	Product Documentation	iv
Chapter 1	Signals/Connections	
•	1.1 Power	1-4
	1.2 Ground	1-4
	1.3 Clock	1-5
	1.4 Phase Lock Loop (PLL)	1-5
	1.5 External Memory Expansion Port (Port A)	1-6
	1.6 Interrupt and Mode Control	1-9
	1.7 Host Interface (HI32)	
	1.8 Enhanced Synchronous Serial Interface 0 (ESSI0)	
	1.9 Enhanced Synchronous Serial Interface 1 (ESSI1)	
	1.10 Serial Communication Interface (SCI)	
	1.11 Timers	
	1.12 JTAG/OnCE Interface	1-21
Chapter 2	Specifications	
•	2.1 Maximum Ratings	2-1
	2.2 Absolute Maximum Ratings	
	2.3 Thermal Characteristics	2-2
	2.4 DC Electrical Characteristics	2-2
	2.5 AC Electrical Characteristics	2-4
Chapter 3	Packaging	
onapto. o	3.1 TQFP Package Description	3-2
	3.2 TQFP Package Mechanical Drawing	
	3.3 MAP-BGA Package Description	
	3.4 MAP-BGA Package Mechanical Drawing	
Chantar 4	-	
Chapter 4	Design Considerations	4.1
	4.1 Thermal Design Considerations	
	4.2 Electrical Design Considerations	
	4.4 PLL Performance Issues	
	4.5 Input (EXTAL) Jitter Requirements	
		4-4
Chapter A	Power Consumption Benchmark	
Index		
Data S	heet Conventions	

OVERBAR	Indicates a signal that is active when pulled low (For example, the RESET pin is active when low.)				
"asserted"	Means that a high true	e (active high) signal is l	nigh or that a low true (active lo	ow) signal is low	
"deasserted"	Means that a high true	e (active high) signal is l	low or that a low true (active lo	w) signal is high	
Examples:	Signal/Symbol	mal/Symbol Logic State Signal State Voltage			
	PIN	True	Asserted	V_{IL}/V_{OL}	
	PIN	False	Deasserted	V_{IH}/V_{OH}	
	PIN	True	Asserted	V_{IH}/V_{OH}	
	PIN	False	Deasserted	V_{IL}/V_{OL}	

Note: Values for V_{IL} , V_{OL} , V_{IH} , and V_{OH} are defined by individual product specifications.

DSP56301 Features

High-Performance DSP56300 Core

- 80/100 million instructions per second (MIPS) with a 80/100 MHz clock at 3.0-3.6 V
- Object code compatible with the DSP56000 core with highly parallel instruction set
- Data Arithmetic Logic Unit (Data ALU) with fully pipelined 24 × 24-bit parallel Multiplier-Accumulator (MAC), 56-bit parallel barrel shifter (fast shift and normalization; bit stream generation and parsing), conditional ALU instructions, and 24-bit or 16-bit arithmetic support under software control
- Program Control Unit (PCU) with Position Independent Code (PIC) support, addressing modes
 optimized for DSP applications (including immediate offsets), internal instruction cache
 controller, internal memory-expandable hardware stack, nested hardware DO loops, and fast
 auto-return interrupts
- Direct Memory Access (DMA) with six DMA channels supporting internal and external accesses; one-, two-, and three-dimensional transfers (including circular buffering); end-of-block-transfer interrupts; and triggering from interrupt lines and all peripherals
- Phase Lock Loop (PLL) allows change of low-power Divide Factor (DF) without loss of lock and output clock with skew elimination
- Hardware debugging support including On-Chip Emulation (OnCE™) module, Joint Test Action Group (JTAG) Test Access Port (TAP)

Internal Peripherals

- 32-bit parallel PCI/Universal Host Interface (HI32), PCI Rev. 2.1 compliant with glueless interface to other DSP563xx buses or ISA interface requiring only 74LS45-style buffers
- Two enhanced synchronous serial interfaces (ESSI), each with one receiver and three transmitters (allows six-channel home theater)
- Serial communications interface (SCI) with baud rate generator
- Triple timer module
- Up to forty-two programmable general-purpose input/output (GPIO) pins, depending on which peripherals are enabled

Internal Memories

- 3 K × 24-bit bootstrap ROM
- 8 K × 24-bit internal RAM total
- Program RAM, Instruction Cache, X data RAM, and Y data RAM sizes are programmable:

Program RAM Size	Instruction Cache Size	X Data RAM Size	Y Data RAM Size	Instruction Cache	Switch Mode
$4096 \times 24 \text{ bits}$	0	$2048 \times 24 \text{ bits}$	$2048 \times 24 \text{ bits}$	disabled	disabled
$3072 \times 24 \text{ bits}$	1024×24 -bit	$2048 \times 24 \text{ bits}$	$2048 \times 24 \text{ bits}$	enabled	disabled
$2048 \times 24 \text{ bits}$	0	$3072 \times 24 \text{ bits}$	$3072 \times 24 \text{ bits}$	disabled	enabled
1024 × 24 bits	1024 × 24-bit	3072 × 24 bits	3072 × 24 bits	enabled	enabled

External Memory Expansion

- Data memory expansion to two 16 M × 24-bit word memory spaces in 24-Bit mode or two 64 K × 16-bit memory spaces in 16-Bit Compatibility mode
- Program memory expansion to one 16 M \times 24-bit words memory space in 24-Bit mode or 64 K \times 16-bit in 16-Bit Compatibility mode
- · External memory expansion port
- Chip Select Logic for glueless interface to SRAMs
- Internal DRAM Controller for glueless interface to dynamic random access memory (DRAMs)

Reduced Power Dissipation

- Very low-power CMOS design
- Wait and Stop low-power standby modes
- Fully static design specified to operate down to 0 Hz (dc)
- Optimized power management circuitry (instruction-dependent, peripheral-dependent, and mode-dependent)

Packaging

The DSP56301 is available in a 208-pin thin quad flat pack (TQFP) or a 252-pin molded array process-ball grid array (MAP-BGA) package. Both packages are available in lead-bearing and lead-free versions.

Target Applications

Examples of target applications include:

- · Wireless and wireline infrastructure applications
- Multi-channel wireless local loop systems
- · DSP resource boards
- · High-speed modem banks
- · Packet telephony

Product Documentation

The three documents listed in the following table are required for a complete description of the DSP56301 and are necessary to design properly with the part. Documentation is available from the following sources. (See the back cover for detailed information.)

- A local Freescale distributor
- · A Freescale semiconductor sales office
- A Freescale Literature Distribution Center
- The World Wide Web (WWW)

Table 1. DSP56301 Documentation

Name	Description	Order Number
DSP56300 Family Manual	Detailed description of the DSP56300 family processor core and instruction set	DSP56300FM/AD
DSP56301 User's Manual	Detailed functional description of the DSP56301 memory configuration, operation, and register programming	DSP56301UM/D
DSP56301 Technical Data	DSP56301 features list and physical, electrical, timing, and package specifications	DSP56301

iv Freescale Semiconductor

Signals/Connections

1

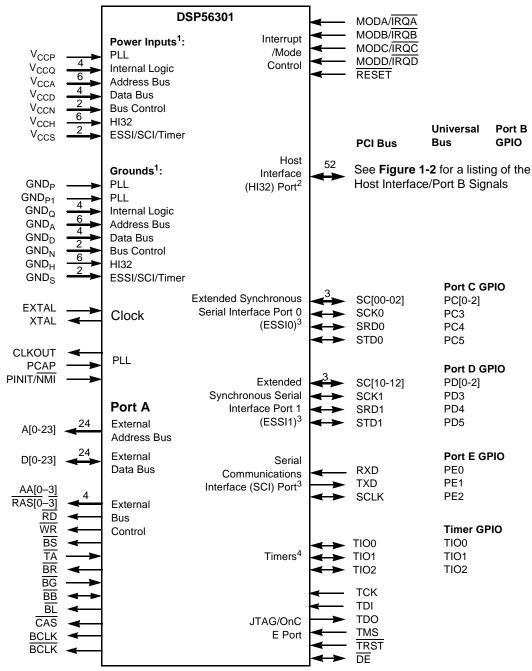
The DSP56301 input and output signals are organized into functional groups, as shown in **Table 1-1** and illustrated in **Figure 1-1**. The DSP56301 operates from a 3 V supply; however, some of the inputs can tolerate 5 V. A special notice for this feature is added to the signal descriptions of those inputs.

Table 1-1. DSP56301 Functional Signal Groupings

Functional Group		Signa	ber of als by ge Type	Detailed Description
		TQFP	MAP- BGA	
Power (V _{CC}) ¹		25	45	Table 1-2
Ground (GND) ¹		26	38	Table 1-3
Clock		2	2	Table 1-4
PLL		3	3	Table 1-5
Address Bus	D	24	24	Table 1-6
Data Bus	- Port A ²	24	24	Table 1-7
Bus Control	1	15	15	Table 1-8
Interrupt and Mode Control	1	5	5	Table 1-9
Host Interface (HI32)	Port B ³	52	52	Table 1-11
Enhanced Synchronous Serial Interface (ESSI)	Ports C and D ⁴	12	12	Table 1-12 and Table 1-13
Serial Communication Interface (SCI)	Port E ⁵	3	3	Table 1-14
Timer			3	Table 1-15
JTAG/OnCE Port			6	Table 1-16

Notes:

- The number of available power and ground signals is package-dependent. In the TQFP package specific pins are dedicated internally to device subsystems. In the MAP-BGA package, power and ground connections (except those providing PLL power) connect to internal power and ground planes, respectively.
- 2. Port A signals define the external memory interface port, including the external address bus, data bus, and control signals.
- 3. Port B signals are the HI32 port signals multiplexed with the GPIO signals.
- 4. Port C and D signals are the two ESSI port signals multiplexed with the GPIO signals.
- 5. Port E signals are the SCI port signals multiplexed with the GPIO signals.
- **6.** Each device also includes several no connect (NC) pins. The number of NC connections is package-dependent: the TQFP has 9 NCs and the MAP-BGA has 20 NCs. Do not connect any line, component, trace, or via to these pins. See **Chapter 3** for details.



- Notes: 1. Power and ground connections are shown for the TQFP package. The MAP-BGA package uses one V_{CCP} for the PLL power input and 44 V_{CC} pins that connect to an internal power plane. The MAP-BGA package uses two ground connections for the PLL (GND_P and GND_{P1}) and 36 GND pins that connect to an internal ground plane.
 - 2. The HI32 port supports PCI and non-PCI bus configurations. Twenty-four HI32 signals can also be configured as GPIO signals (PB[0–23]).
 - The ESSI0, ESSI1, and SCI signals are multiplexed with the Port C GPIO signals (PC[0-5]), Port D GPIO signals (PD[0-5]), and Port E GPIO signals (PE[0-2]), respectively.
 - 4. TIO[0-2] can be configured as GPIO signals.

Figure 1-1. Signals Identified by Functional Group

DSP56301 Technical Data, Rev. 10

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				Host Port (HP)
DSP56301	PCI Bus	Universal Bus	Port B GPIO	Reference
	HAD0	HA3	PB0	HP0
	HAD1	HA4	PB1	HP1
	HAD2	HA5	PB2	HP2
	HAD3	HA6	PB3	HP3
	HAD4	HA7	PB4	HP4
	HAD5	HA8	PB5	HP5
	HAD6	HA9	PB6	HP6
	HAD7	HA10	PB7	HP7
	HAD8	HD0	PB8	HP8
	HAD9	HD1	PB9	HP9
	HAD10	HD2	PB10	HP10
	HAD11	HD3	PB11	HP11
	HAD12	HD4	PB12	HP12
	HAD13	HD5	PB13	HP13
	HAD14	HD6	PB14	HP14
	HAD15	HD7	PB15	HP15
	HC0/HBE0	HA0	PB16	HP16
	HC1/HBE1	HA1	PB17	HP17
	HC2/HBE2	HA2	PB18	HP18
	HC3/HBE3	Tie to pull-up or V _{CC}	PB19	HP19
Host Interface (HI32)/	HTRDY	HDBEN	PB20	HP20
	HIRDY	HDBDR	PB21	HP21
Port B Signals	HDEVSEL	HSAK	PB22	HP22
	HLOCK	HBS	PB23	HP23
	HPAR	HDAK	Internal disconnect	HP24
	HPERR	HDRQ	Internal disconnect	HP25
	HGNT	HAEN	Internal disconnect	HP26
	HREQ	HTA	Internal disconnect	HP27
	HSERR	HIRQ	Internal disconnect	HP28
	HSTOP	HWR/HRW	Internal disconnect	HP29
	HIDSEL	HRD/HDS	Internal disconnect	HP30
	HFRAME	Tie to pull-up or V _{CC}	Internal disconnect	HP31
	HCLK	Tie to pull-up or V _{CC}	Internal disconnect	HP32
	HAD16	HD8	Internal disconnect	HP33
	HAD17	HD9	Internal disconnect	HP34
	HAD18	HD10	Internal disconnect	HP35
	HAD19	HD11	Internal disconnect	HP36
	HAD20	HD12	Internal disconnect	HP37
	HAD21	HD13	Internal disconnect	HP38
	HAD22	HD14	Internal disconnect	HP39
	HAD23	HD15	Internal disconnect	HP40
	HAD24	HD16	Internal disconnect	HP41
	HAD25	HD17	Internal disconnect	HP42
	HAD26	HD18	Internal disconnect	HP43
	HAD27	HD19	Internal disconnect	HP44
	HAD28	HD20	Internal disconnect	HP45
	HAD29	HD21	Internal disconnect	HP46
	HAD30	HD22	Internal disconnect	HP47
	HAD31	HD23	Internal disconnect	HP48
	HRST	HRST	Internal disconnect	HP49
1	HINTA	HINTA	Internal disconnect	HP50
	PVCL	Leave unconnected	Leave unconnected	PVCL

Note: HPxx is a reference only and is not a signal name. GPIO references formerly designated as HIOxx have been renamed PBxx for consistency with other Freescale DSPs.

Figure 1-2. Host Interface/Port B Detail Signal Diagram

1-3

1.1 Power

Table 1-2. Power Inputs

Power Name	Description
V _{CCP}	PLL Power Isolated power for the Phase Lock Loop (PLL). The voltage should be well-regulated and the input should be provided with an extremely low impedance path to the V _{CC} power rail.
Vccq	Quiet Power Isolated power for the internal processing logic. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
V _{CCA}	Address Bus Power Isolated power for sections of the address bus I/O drivers. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
V _{CCD}	Data Bus Power Isolated power for sections of the data bus I/O drivers. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
V _{CCN}	Bus Control Power Isolated power for the bus control I/O drivers. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
V _{ССН}	Host Power Isolated power for the HI32 I/O drivers. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
V _{ccs}	ESSI, SCI, and Timer Power Isolated power for the ESSI, SCI, and timer I/O drivers. This input must be tied externally to all other chip power inputs. The user must provide adequate external decoupling capacitors.
	lesignations are package-dependent. Some packages connect all V_{CC} inputs except V_{CCP} to each other internally. On ackages, all power input except V_{CCP} are labeled V_{CC} .

1.2 Ground

Table 1-3. Grounds

Ground Name	Description				
GND _P	PLL Ground Ground dedicated for PLL use. The connection should be provided with an extremely low-impedance path to ground. V_{CCP} should be bypassed to GND _P by a 0.47 μ F capacitor located as close as possible to the chip package.				
GND _{P1}	PLL Ground 1 Ground dedicated for PLL use. The connection should be provided with an extremely low-impedance path to ground.				
GND _Q	Quiet Ground Isolated ground for the internal processing logic. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				
GND _A	Address Bus Ground Isolated ground for sections of the address bus I/O drivers. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				
GND _D	Data Bus Ground Isolated ground for sections of the data bus I/O drivers. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				

DSP56301 Technical Data, Rev. 10

1-4 Freescale Semiconductor

Table 1-3. Grounds

Ground Name	Description				
GND _N	Bus Control Ground Isolated ground for the bus control I/O drivers. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				
GND _H	Host Ground Isolated ground for the HI32 I/O drivers. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				
GND _S	ESSI, SCI, and Timer Ground Isolated ground for the ESSI, SCI, and timer I/O drivers. This connection must be tied externally to all other chip ground connections. The user must provide adequate external decoupling capacitors.				
	Note: These designations are package-dependent. Some packages connect all GND inputs except GND _P and GND _{P1} to each other internally. On those packages, all ground connections except GND _P and GND _{P1} are labeled GND.				

1.3 Clock

Table 1-4. Clock Signals

Signal Name	Туре	State During Reset	Signal Description
EXTAL	Input	Input	External Clock/Crystal Input Interfaces the internal crystal oscillator input to an external crystal or an external clock.
XTAL	Output	Chip-driven	Crystal Output Connects the internal crystal oscillator output to an external crystal. If an external clock is used, leave XTAL unconnected.

1.4 Phase Lock Loop (PLL)

Table 1-5.Phase Lock Loop Signals

Signal Name	Туре	State During Reset	Signal Description
CLKOUT	Output	Chip-driven	Clock Output Provides an output clock synchronized to the internal core clock phase. If the PLL is enabled and both the multiplication and division factors equal one, then CLKOUT is also synchronized to EXTAL. If the PLL is disabled, the CLKOUT frequency is half the frequency of EXTAL.
PCAP	Input	Input	$ \begin{array}{c} \textbf{PLL Capacitor} \\ \textbf{Connects an off-chip capacitor to the PLL filter. Connect one capacitor terminal to PCAP and the other terminal to V_{CCP}. \\ \textbf{If the PLL is not used, PCAP can be tied to V_{CC}, GND, or left floating.} \end{array} $

 Table 1-5.
 Phase Lock Loop Signals (Continued)

Signal Name	Туре	State During Reset	Signal Description
PINIT/NMI	Input	Input	PLL Initial/Non-Maskable Interrupt During assertion of RESET, the value of PINIT/NMI is written into the PLL Enable (PEN) bit of the PLL control register, determining whether the PLL is enabled or disabled. After RESET deassertion and during normal instruction processing, the PINIT/NMI Schmitt-trigger input is a negative-edge-triggered Non-Maskable Interrupt (NMI) request internally synchronized to CLKOUT. PINIT/NMI can tolerate 5 V.

1.5 External Memory Expansion Port (Port A)

Note: When the DSP56301 enters a low-power stand-by mode (Stop or Wait), it releases bus mastership and tristates the relevant Port A signals: A[0–23], D[0–23], AA0/RAS0–AA3/RAS3, RD, WR, BB, CAS, BCLK, and BCLK. If hardware refresh of external DRAM is enabled, Port A exits the Wait mode to allow the refresh to occur and then returns to the Wait mode.

1.5.1 External Address Bus

Table 1-6. External Address Bus Signals

Signal Name	Туре	State During Reset	Signal Description
A[0-23]	Output	Tri-stated	Address Bus When the DSP is the bus master, A[0–23] specify the address for external program and data memory accesses. Otherwise, the signals are tri-stated. To minimize power dissipation, A[0–23] do not change state when external memory spaces are not being accessed.

1.5.2 External Data Bus

Table 1-7. External Data Bus Signals

Signal Name	Туре	State During Reset	Signal Description
D[0-23]	Input/Output	Tri-stated	Data Bus When the DSP is the bus master, D[0–23] provide the bidirectional data bus for external program and data memory accesses. Otherwise, D[0–23] are tristated.

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1.5.3 External Bus Control

 Table 1-8.
 External Bus Control Signals

Signal Name	Туре	State During Reset	Signal Description
AA0/RAS0- AA3/RAS3	Output	Tri-stated	Address Attribute or Row Address Strobe As AA, these signals function as chip selects or additional address lines. Unlike address lines, however, the AA lines do not hold their state after a read or write operation. As RAS, these signals can be used for Dynamic Random Access Memory (DRAM) interface. These signals have programmable polarity.
RD	Output	Tri-stated	Read Enable When the DSP is the bus master, RD is asserted to read external memory on the data bus (D[0–23]). Otherwise, RD is tri-stated.
WR	Output	Tri-stated	Write Enable When the DSP is the bus master, WR is asserted to write external memory on the data bus (D[0–23]). Otherwise, WR is tri-stated.
TĀ	Input	Ignored Input	Transfer Acknowledge If the DSP56301 is the bus master and there is no external bus activity, or the DSP56301 is not the bus master, the TA input is ignored. The TA input is a Data Transfer Acknowledge (DTACK) function that can extend an external bus cycle indefinitely. Any number of wait states (1, 2,, infinity) can be added to the wait states inserted by the BCR by keeping TA deasserted. In typical operation, TA is deasserted at the start of a bus cycle, asserted to enable completion of the bus cycle, and deasserted before the next bus cycle. The current bus cycle completes one clock period after TA is asserted synchronous to CLKOUT. The number of wait states is determined by the TA input or by the Bus Control Register (BCR), whichever is longer. The BCR can set the minimum number of wait states in external bus cycles. To use the TA functionality, the BCR must be programmed to at least one wait state. A zero wait state access cannot be extended by TA deassertion; otherwise improper operation may result. TA can operate synchronously or asynchronously, depending on the setting of the TAS bit in the Operating Mode Register (OMR). TA functionality cannot be used during DRAM-type accesses; otherwise
BR	Output	Output (deasserted)	Bus Request Asserted when the DSP requests bus mastership and deasserted when the DSP no longer needs the bus. \$\overline{BR}\$ can be asserted or deasserted independently of whether the DSP56301 is a bus master or a bus slave. Bus "parking" allows \$\overline{BR}\$ to be deasserted even though the DSP56301 is the bus master (see the description of bus "parking" in the \$\overline{BB}\$ signal description). The Bus Request Hole (BRH) bit in the BCR allows \$\overline{BR}\$ to be asserted under software control, even though the DSP does not need the bus. \$\overline{BR}\$ is typically sent to an external bus arbitrator that controls the priority, parking and tenure of each master on the same external bus. \$\overline{BR}\$ is affected only by DSP requests for the external bus, never for the internal bus. During hardware reset, \$\overline{BR}\$ is deasserted and the arbitration is reset to the bus slave state.
BG	Input	Ignored Input	Bus Grant Must be asserted/deasserted synchronous to CLKOUT for proper operation. An external bus arbitration circuit asserts \overline{BG} when the DSP56301 becomes the next bus master. When \overline{BG} is asserted, the DSP56301 must wait until \overline{BB} is deasserted before taking bus mastership. When \overline{BG} is deasserted, bus mastership is typically given up at the end of the current bus cycle. This may occur in the middle of an instruction that requires more than one external bus cycle for execution.

DSP56301 Technical Data, Rev. 10

Signals/Connections

 Table 1-8.
 External Bus Control Signals (Continued)

Signal Name	Туре	State During Reset	Signal Description
BB	Input/ Output	Input	Bus Busy Indicates that the bus is active and must be asserted and deasserted synchronous to CLKOUT. Only after BB is deasserted can the pending bus master become the bus master (and then assert the signal again). The bus master can keep BB asserted after ceasing bus activity, regardless of whether BR is asserted or deasserted. This is called "bus parking" and allows the current bus master to reuse the bus without re-arbitration until another device requires the bus. BB is deasserted by an "active pull-up" method (that is, BB is driven high and then released and held high by an external pull-up resistor). BB requires an external pull-up resistor.
BL	Output	Driven high (deasserted)	Bus Lock—BL is asserted at the start of an external divisible Read-Modify-Write (RMW) bus cycle, remains asserted between the read and write cycles, and is deasserted at the end of the write bus cycle. This provides an "early bus start" signal for the bus controller. BL may be used to "resource lock" an external multi-port memory for secure semaphore updates. Early deassertion provides an "early bus end" signal useful for external bus control. If the external bus is not used during an instruction cycle, BL remains deasserted until the next external indivisible RMW cycle. The only instructions that assert BL automatically are the BSET, CLR, and BCHG instructions when they are used to modify external memory. An operation can also assert BL by setting the BLH bit in the Bus Control Register.
CAS	Output	Tri-stated	Column Address Strobe When the DSP is the bus master, DRAM uses CAS to strobe the column address. Otherwise, if the Bus Mastership Enable (BME) bit in the DRAM Control Register is cleared, the signal is tri-stated.
BCLK	Output	Tri-stated	Bus Clock When the DSP is the bus master, BCLK is active when the OMR[ATE] is set. When BCLK is active and synchronized to CLKOUT by the internal PLL, BCLK precedes CLKOUT by one-fourth of a clock cycle.
BCLK	Output	Tri-stated	Bus Clock Not When the DSP is the bus master, BCLK is the inverse of the BCLK signal. Otherwise, the signal is tri-stated.

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1.6 Interrupt and Mode Control

The interrupt and mode control signals select the chip's operating mode as it comes out of hardware reset. After RESET is deasserted, these inputs are hardware interrupt request lines.

Table 1-9. Interrupt and Mode Control

Signal Name	Туре	State During Reset	Signal Description
MODA	Input	Input	Mode Select A Selects the initial chip operating mode during hardware reset and becomes a level-sensitive or negative-edge-triggered, maskable interrupt request input IRQA during normal instruction processing. MODA, MODB, MODC, and MODD select one of sixteen initial chip operating modes, latched into the OMR when the RESET signal is deasserted.
ĪRQĀ	Input		External Interrupt Request A Internally synchronized to CLKOUT. If IRQA is asserted synchronous to CLKOUT, multiple processors can be re-synchronized using the WAIT instruction and asserting IRQA to exit the Wait state. If the processor is in the Stop stand-by state and IRQA is asserted, the processor exits the Stop state. These inputs are 5 V tolerant.
MODB	Input	Input	Mode Select B Selects the initial chip operating mode during hardware reset and becomes a level-sensitive or negative-edge-triggered, maskable interrupt request input IRQB during normal instruction processing. MODA, MODB, MODC, and MODD select one of sixteen initial chip operating modes, latched into the OMR when the RESET signal is deasserted.
ĪRQB	Input		External Interrupt Request B Internally synchronized to CLKOUT. If IRQB is asserted synchronous to CLKOUT, multiple processors can be re-synchronized using the WAIT instruction and asserting IRQB to exit the Wait state. If the processor is in the Stop stand-by state and IRQC is asserted, the processor will exit the Stop state.
			These inputs are 5 V tolerant.
MODC	Input	Input	Mode Select C Selects the initial chip operating mode during hardware reset and becomes a level-sensitive or negative-edge-triggered, maskable interrupt request input IRQC during normal instruction processing. MODA, MODB, MODC, and MODD select one of sixteen initial chip operating modes, latched into the OMR when the RESET signal is deasserted.
ĪRQC	Input		External Interrupt Request C Internally synchronized to CLKOUT. If IRQC is asserted synchronous to CLKOUT, multiple processors can be re-synchronized using the WAIT instruction and asserting IRQC to exit the Wait state. If the processor is in the Stop stand-by state and IRQC is asserted, the processor exits the Stop state. These inputs are 5 V tolerant.

Table 1-9. Interrupt and Mode Control (Continued)

Signal Name	Туре	State During Reset	Signal Description
MODD	Input	Input	Mode Select D Selects the initial chip operating mode during hardware reset and becomes a level-sensitive or negative-edge-triggered, maskable interrupt request input IRQD during normal instruction processing. MODA, MODB, MODC, and MODD select one of sixteen initial chip operating modes, latched into the OMR when the RESET signal is deasserted.
ĪRQD	Input		External Interrupt Request D Internally synchronized to CLKOUT. If IRQD is asserted synchronous to CLKOUT, multiple processors can be re-synchronized using the WAIT instruction and asserting IRQD to exit the Wait state. If the processor is in the Stop stand-by state and IRQD is asserted, the processor exits the Stop state. These inputs are 5 V tolerant.
RESET	Input	Input	Reset Deassertion of RESET is internally synchronized to the clock out (CLKOUT). When asserted, the chip is placed in the Reset state and the internal phase generator is reset. The Schmitt-trigger input allows a slowly rising input (such as a capacitor charging) to reset the chip reliably. If RESET is deasserted synchronous to CLKOUT, exact start-up timing is guaranteed, allowing multiple processors to start synchronously and operate together in "lock-step." When the RESET signal is deasserted, the initial chip operating mode is latched from the MODA, MODB, MODC, and MODD inputs. The RESET signal must be asserted after power-up. This input is 5 V tolerant.

1.7 Host Interface (HI32)

The Host Interface (HI32) provides fast parallel data to a 32-bit port directly connected to the host bus. The HI32 supports a variety of standard buses and directly connects to a PCI bus and a number of industry-standard microcomputers, microprocessors, DSPs, and DMA hardware.

1.7.1 Host Port Usage Considerations

Careful synchronization is required when the system reads multiple-bit registers that are written by another asynchronous system. This is a common problem when two asynchronous systems are connected (as they are in the Host port). The considerations for proper operation are discussed in **Table 1-10**.

Table 1-10. Host Port Usage Considerations

Action	Description
Asynchronous read of receive byte registers	When reading the receive byte registers, Receive register High (RXH), Receive register Middle (RXM), or Receive register Low (RXL), use interrupts or poll the Receive register Data Full (RXDF) flag that indicates data is available. This assures that the data in the receive byte registers is valid.
Asynchronous write to transmit byte registers	Do not write to the transmit byte registers, Transmit register High (TXH), Transmit register Middle (TXM), or Transmit register Low (TXL), unless the Transmit register Data Empty (TXDE) bit is set, indicating that the transmit byte registers are empty. This guarantees that the transmit byte registers transfer valid data to the Host Receive (HRX) register.

DSP56301 Technical Data, Rev. 10

1-10 Freescale Semiconductor

Table 1-10. Host Port Usage Considerations (Continued)

Action	Description
Asynchronous write to host vector	Change the Host Vector (HV) register only when the Host Command bit (HC) is clear. This practice guarantees that the DSP interrupt control logic receives a stable vector.

1.7.2 Host Port Configuration

HI32 signal functions vary according to the programmed configuration of the interface as determined by the 24-bit DSP Control Register (DCTR). Refer to the DSP56301 User's Manual for details on HI32 configuration registers.

Table 1-11. Host Interface

Signal Name	Туре	State During Reset	Signal Description
HAD[0-7]	Input/Output	Tri-stated	Host Address/Data 0–7 When the HI32 is programmed to interface with a PCI bus and the HI function is selected, these signals are lines 0–7 of the Address/Data bus.
HA[3–10]	Input		Host Address 3–10 When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, these signals are lines 3–10 of the Address bus.
PB[0-7]	Input or Output		Port B 0–7 When the HI32 is configured as GPIO through the DCTR, these signals are individually programmed through the HI32 Data Direction Register (DIRH).
1			These inputs are 5 V tolerant.
HAD[8–15]	Input/Output	Tri-stated	Host Address/Data 8–15 When the HI32 is programmed to interface with a PCI bus and the HI function is selected, these signals are lines 8–15 of the Address/Data bus.
HD[0-7]	Input/Output		Host Data 0–7 When HI32 is programmed to interface with a universal non-PCI bus and the HI function is selected, these signals are lines 0–7 of the Data bus.
PB[8–15]	Input or Output		Port B 8–15 When the Hl32 is configured as GPIO through the DCTR, these signals are individually programmed through the Hl32 DIRH.
			These inputs are 5 V tolerant.
HC[0-3]/ HBE[0-3]	Input/Output	Tri-stated	Command 0-3/Byte Enable 0-3 When the HI32 is programmed to interface with a PCI bus and the HI function is selected, these signals are lines 0-7 of the Address/Data bus.
HA[0-2]	Input		Host Address 0–2 When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, these signals are lines 0–2 of the Address bus.
			The fourth signal in this set should connect to a pull-up resistor or directly to V_{CC} when a non-PCI bus is used.
PB[16–19]	Input or Output		Port B 16–19 When the Hl32 is configured as GPIO through the DCTR, these signals are individually programmed through the Hl32 DIRH.
			These inputs are 5 V tolerant.

Table 1-11. Host Interface (Continued)

Signal Name	Туре	State During Reset	Signal Description
HTRDY	Input/ Output	Tri-stated	Host Target Ready When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Target Ready signal.
HDBEN	Output		Host Data Bus Enable When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Data Bus Enable signal.
PB20	Input or Output		Port B 20 When the HI32 is configured as GPIO through the DCTR, this signal is individually programmed through the HI32 DIRH.
			This input is 5 V tolerant.
HIRDY	Input/ Output	Tri-stated	Host Initiator Ready When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Initiator Ready signal.
HDBDR	Output		Host Data Bus Direction When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Data Bus Direction signal.
PB21	Input or Output		Port B 21 When the HI32 is configured as GPIO through the DCTR, this signal is individually programmed through the HI32 DIRH.
			This input is 5 V tolerant.
HDEVSEL	Input/ Output	Tri-stated	Host Device Select When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Device Select signal.
HSAK	Output		Host Select Acknowledge When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Select Acknowledge signal.
PB22	Input or Output		Port B 22 When the HI32 is configured as GPIO through the DCTR, this signal is individually programmed through the HI32 DIRH.
			This input is 5 V tolerant.
HLOCK	Input	Tri-stated	Host Lock When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Lock signal.
HBS	Input		Host Bus Strobe When Hl32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Bus Strobe Schmitt-trigger signal.
PB23	Input or Output		Port B 23 When the Hl32 is configured as GPIO through the DCTR, this signal is individually programmed through the Hl32 DIRH.
			This input is 5 V tolerant.

1-12 Freescale Semiconductor

Table 1-11. Host Interface (Continued)

Signal Name	Туре	State During Reset	Signal Description
HPAR	Input/ Output	Tri-stated	Host Parity When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Parity signal.
HDAK	Input		Host DMA Acknowledge When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host DMA Acknowledge Schmitt-trigger signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HPERR	Input/ Output	Tri-stated	Host Parity Error When the Hl32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Parity Error signal.
HDRQ	Output		Host DMA Request When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host DMA Request output.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HGNT	Input	Input	Host Bus Grant When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Bus Grant signal.
HAEN	Input		Host Address Enable When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Address Enable output signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HREQ	Output	Tri-stated	Host Bus Request When the Hl32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Bus Request signal.
HTA	Output		Host Transfer Acknowledge—When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Data Bus Enable signal. HTA can be programmed as active high or active low.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.

Table 1-11. Host Interface (Continued)

Signal Name	Туре	State During Reset	Signal Description
HSERR	Output, open drain	Tri-stated	Host System Error When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host System Error signal.
HIRQ	Output, open drain		Host Interrupt Request When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Interrupt Request signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HSTOP	Input/ Output	Tri-stated	Host Stop When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Stop signal.
HWR/HRW	Input		Host Write/Host Read-Write When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Write/Host Read-Write Schmitt-trigger signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HIDSEL	Input	Input	Host Initialization Device Select When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Initialization Device Select signal.
HRD/HDS	Input		Host Read/Host Data Strobe When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Host Data Read/Host Data Strobe Schmitt-trigger signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HFRAME	Input/ Output	Tri-stated	Host Frame When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host cycle Frame signal.
			Non-PCI bus When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this signal must be connected to a pull-up resistor or directly to V _{CC} .
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.

DSP56301 Technical Data, Rev. 10

1-14 Freescale Semiconductor

Table 1-11. Host Interface (Continued)

Signal Name	Туре	State During Reset	Signal Description
HCLK	Input	Input	Host Clock When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Host Bus Clock input.
			Non-PCI bus When HI32 is programmed to interface a universal non-PCI bus and the HI function is selected, this signal must be connected to a pull-up resistor or directly to V _{CC} .
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HAD[16-31]	Input/Output	Tri-stated	Host Address/Data 16–31 When the HI32 is programmed to interface with a PCI bus and the HI function is selected, these signals are lines 16–31 of the Address/Data bus.
HD[8-23]	Input/Output		Host Data 8–23 When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, these signals are lines 8–23 of the Data bus.
			Port B When the HI32 is configured as GPIO through the DCTR, these signals are internally disconnected.
			These inputs are 5 V tolerant.
HRST	Input	Tri-stated	Hardware Reset When the HI32 is programmed to interface with a PCI bus and the HI function is selected, this is the Hardware Reset input.
HRST	Input		Hardware Reset When HI32 is programmed to interface with a universal, non-PCI bus and the HI function is selected, this is the Hardware Reset Schmitt-trigger signal.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
HINTA	Output, open drain	Tri-stated	Host Interrupt A When the HI function is selected, this signal is the Interrupt A open-drain output.
			Port B When the HI32 is configured as GPIO through the DCTR, this signal is internally disconnected.
			This input is 5 V tolerant.
PVCL	Input	Input	PCI Voltage Clamp When the HI32 is programmed to interface with a PCI bus and the HI function is selected and the PCI bus uses a 3 V signal environment, connect this pin to V_{CC} (3.3 V) to enable the high voltage clamping required by the PCI specifications. In all other cases, including a 5 V PCI signal environment, leave the input unconnected.

1.8 Enhanced Synchronous Serial Interface 0 (ESSI0)

Two synchronous serial interfaces (ESSI0 and ESSI1) provide a full-duplex serial port for serial communication with a variety of serial devices, including one or more industry-standard codecs, other DSPs, microprocessors, and peripherals that implement the Serial Peripheral Interface (SPI).

 Table 1-12.
 Enhanced Synchronous Serial Interface 0 (ESSI0)

Signal Name	Туре	State During Reset	Signal Description			
SC00	Input or Output	Input	Serial Control 0 Functions in either Synchronous or Asynchronous mode. For Asynchronous mode, this signal is the receive clock I/O (Schmitt-trigger input). For Synchronous mode, this signal is either for Transmitter 1 output or Serial I/O Flag 0.			
PC0			Port C 0 The default configuration following reset is GPIO. For PC0, signal direction is controlled through the Port Directions Register (PRR0). The signal can be configured as ESSI signal SC00 through the Port Control Register (PCR0). This input is 5 V tolerant.			
SC01	Input/Output	Input	Serial Control 1 Functions in either Synchronous or Asynchronous mode. For Asynchronous mode, this signal is the receiver frame sync I/O. For Synchronous mode, this signal is either Transmitter 2 output or Serial I/O Flag 1.			
PC1	Input or Output		Port C 1 The default configuration following reset is GPIO. For PC1, signal direction is controlled through PRR0. The signal can be configured as an ESSI signal SC01 through PCR0. This input is 5 V tolerant.			
SC02	Input/Output	Input	Serial Control Signal 2 The frame sync for both the transmitter and receiver in Synchronous mode, and for the transmitter only in Asynchronous mode. When configured as an output, this signal is the internally generated frame sync signal. When configured as an input, this signal receives an external frame sync signal for the transmitter (and the receiver in synchronous operation).			
PC2	Input or Output		Port C 2 The default configuration following reset is GPIO. For PC2, signal direction is controlled through PRR0. The signal can be configured as an ESSI signal SC02 through PCR0.			
			This input is 5 V tolerant.			

1-16 Freescale Semiconductor

Enhanced Synchronous Serial Interface 0 (ESSI0)

 Table 1-12.
 Enhanced Synchronous Serial Interface 0 (ESSI0) (Continued)

Signal Name	Туре	State During Reset	Signal Description
SCK0	Input/Output	Input	Serial Clock Provides the serial bit rate clock for the ESSI interface for both the transmitter and receiver in Synchronous modes, or the transmitter only in Asynchronous modes.
			Although an external serial clock can be independent of and asynchronous to the DSP system clock, it must exceed the minimum clock cycle time of 6 T (that is, the system clock frequency must be at least three times the external ESSI clock frequency). The ESSI needs at least three DSP phases inside each half of the serial clock.
PC3	Input or Output		Port C 3 The default configuration following reset is GPIO. For PC3, signal direction is controlled through PRR0. The signal can be configured as an ESSI signal SCK0 through PCR0.
			This input is 5 V tolerant.
SRD0	Input/Output	Input	Serial Receive Data Receives serial data and transfers the data to the ESSI receive shift register. SRD0 is an input when data is being received.
PC4	Input or Output		Port C 4 The default configuration following reset is GPIO. For PC4, signal direction is controlled through PRR0. The signal can be configured as an ESSI signal SRD0 through PCR0.
			This input is 5 V tolerant.
STD0	Input/Output	Input	Serial Transmit Data Transmits data from the serial transmit shift register. STD0 is an output when data is being transmitted.
PC5	Input or Output		Port C 5 The default configuration following reset is GPIO. For PC5, signal direction is controlled through PRR0. The signal can be configured as an ESSI signal STD0 through PCR0.
			This input is 5 V tolerant.

1.9 Enhanced Synchronous Serial Interface 1 (ESSI1)

Table 1-13. Enhanced Synchronous Serial Interface 1 (ESSI1)

Signal Name	Туре	State During Reset	Signal Description			
SC10	Input or Output	Input	Serial Control 0 Selection of Synchronous or Asynchronous mode determines function. For Asynchronous mode, this signal is the receive clock I/O (Schmitt-trigger input). For Synchronous mode, this signal is either Transmitter 1 output or Serial I/O Flag 0.			
PD0			Port D 0 The default configuration following reset is GPIO. For PD0, signal direction is controlled through the Port Directions Register (PRR1). The signal can be configured as an ESSI signal SC10 through the Port Control Register (PCR1).			
			This input is 5 V tolerant.			
SC11	Input/Output	Input	Serial Control 1 Selection of Synchronous or Asynchronous mode determines function. For Asynchronous mode, this signal is the receiver frame sync I/O. For Synchronous mode, this signal is either Transmitter 2 output or Serial I/O Flag 1.			
PD1	Input or Output		Port D 1 The default configuration following reset is GPIO. For PD1, signal direction is controlled through PRR1. The signal can be configured as an ESSI signal SC11 through PCR1.			
			This input is 5 V tolerant.			
SC12	Input/Output	Input	Serial Control Signal 2 Frame sync for both the transmitter and receiver in Synchronous mode, for the transmitter only in Asynchronous mode. When configured as an output, this signal is the internally generated frame sync signal. When configured as an input, this signal receives an external frame sync signal for the transmitter (and the receiver in Synchronous operation).			
PD2	Input or Output		Port D 2 The default configuration following reset is GPIO. For PD2, signal direction is controlled through PRR1. The signal can be configured as an ESSI signal SC12 through PCR1. This input is 5 V tolerant.			
SCK1	Input/Output	Input	Serial Clock Provides the serial bit rate clock for the ESSI interface. Clock input or output can be used by the transmitter and receiver in Synchronous modes, by the transmitter only in Asynchronous modes.			
			Although an external serial clock can be independent of and asynchronous to the DSP system clock, it must exceed the minimum clock cycle time of 6T (that is, the system clock frequency must be at least three times the external ESSI clock frequency). The ESSI needs at least three DSP phases inside each half of the serial clock.			
PD3	Input or Output		Port D 3 The default configuration following reset is GPIO. For PD3, signal direction is controlled through PRR1. The signal can be configured as an ESSI signal SCK1 through PCR1.			
			This input is 5 V tolerant.			

DSP56301 Technical Data, Rev. 10

1-18 Freescale Semiconductor

Table 1-13. Enhanced Synchronous Serial Interface 1 (ESSI1) (Continued)

Туре	State During Reset	Signal Description			
Input/Output	Input	Serial Receive Data Receives serial data and transfers it to the ESSI receive shift register. SRD1 is an input when data is being received.			
Input or Output		Port D 4 The default configuration following reset is GPIO. For PD4, signal direction is controlled through PRR1. The signal can be configured as an ESSI signal SRD1 through PCR1. This input is 5 V tolerant.			
Input/Output	Input	Serial Transmit Data Transmits data from the serial transmit shift register. STD1 is an output when data is being transmitted.			
Input or Output		Port D 5 The default configuration following reset is GPIO. For PD5, signal direction is controlled through PRR1. The signal can be configured as an ESSI signal STD1 through PCR1. This input is 5 V tolerant.			
	Input/Output Input or Output Input/Output	Input/Output Input Input or Output Input/Output Input			

1.10 Serial Communication Interface (SCI)

The Serial Communication interface (SCI) provides a full duplex port for serial communication with other DSPs, microprocessors, or peripherals such as modems.

Table 1-14. Serial Communication Interface (SCI)

Signal Name	Туре	State During Reset	Signal Description
RXD	Input	Input	Serial Receive Data Receives byte-oriented serial data and transfers it to the SCI receive shift register.
PE0	Input or Output		Port E 0 The default configuration following reset is GPIO. When configured as PEO, signal direction is controlled through the SCI Port Directions Register (PRR). The signal can be configured as an SCI signal RXD through the SCI Port Control Register (PCR). This input is 5 V tolerant.
TXD	Output	Input	Serial Transmit Data Transmits data from SCI transmit data register.
PE1	Input or Output		Port E 1 The default configuration following reset is GPIO. When configured as PE1, signal direction is controlled through the SCI PRR. The signal can be configured as an SCI signal TXD through the SCI PCR.
			This input is 5 V tolerant.

Table 1-14. Serial Communication Interface (SCI) (Continued)

Signal Name	Туре	State During Reset	Signal Description	
SCLK	Input/Output	Input	Serial Clock Provides the input or output clock used by the transmitter and/or the receiver.	
PE2	Input or Output		Port E 2 The default configuration following reset is GPIO. For PE2, signal direction is controlled through the SCI PRR. The signal can be configured as an SCI signal SCLK through the SCI PCR. This input is 5 V tolerant.	

1.11 Timers

The DSP56301 has three identical and independent timers. Each can use internal or external clocking, interrupt the DSP56301 after a specified number of events (clocks), or signal an external device after counting a specific number of internal events.

 Table 1-15.
 Triple Timer Signals

Signal Name	Туре	State During Reset	Signal Description
TIO0	Input or Output	Input	Timer 0 Schmitt-Trigger Input/Output As an external event counter or in Measurement mode, TIO0 is input. In Watchdog, Timer, or Pulse Modulation mode, TIO0 is output. The default mode after reset is GPIO input. This can be changed to output or configured as a Timer Input/Output through the Timer 0 Control/Status Register (TCSR0). This input is 5 V tolerant.
TIO1	Input or Output	Input	Timer 1 Schmitt-Trigger Input/Output As an external event counter or in Measurement mode, TIO1 is input. In Watchdog, Timer, or Pulse Modulation mode, TIO1 is output. The default mode after reset is GPIO input. This can be changed to output or configured as a Timer Input/Output through the Timer 1 Control/Status Register (TCSR1). This input is 5 V tolerant.
TIO2	Input or Output	Input	Timer 2 Schmitt-Trigger Input/Output As an external event counter or in Measurement mode, TIO2 is input. In Watchdog, Timer, or Pulse Modulation mode, TIO2 is output. The default mode after reset is GPIO input. This can be changed to output or configured as a Timer Input/Output through the Timer 2 Control/Status Register (TCSR2). This input is 5 V tolerant.

1-20 Freescale Semiconductor

1.12 JTAG/OnCE Interface

Table 1-16. JTAG/OnCE Interface

Signal Name	Туре	State During Reset	Signal Description				
TCK	Input	Input	Test Clock A test clock signal for synchronizing JTAG test logic. This input is 5 V tolerant.				
TDI	Input	Input	Test Data Input A test data serial signal for test instructions and data. TDI is sampled on the rising edge of TCK and has an internal pull-up resistor. This input is 5 V tolerant.				
TDO	Output	Tri-stated	Test Data Output A test data serial signal for test instructions and data. TDO can be tri-stated. The signal is actively driven in the shift-IR and shift-DR controller states and changes on the falling edge of TCK. This input is 5 V tolerant.				
TMS	Input	Input	Test Mode Select Sequences the test controller's state machine, is sampled on the rising edge of TCK, and has an internal pull-up resistor. This input is 5 V tolerant.				
TRST	Input	Input	Test Reset Asynchronously initializes the test controller, has an internal pull-up resistor, and must be asserted after power up. This input is 5 V tolerant.				
DE	Input/Output	Input	Debug Event Provides a way to enter Debug mode from an external command controller (as input) or to acknowledge that the chip has entered Debug mode (as output). When asserted as an input, DE causes the DSP56300 core to finish the current instruction, save the instruction pipeline information, enter Debug mode, and wait for commands from the debug serial input line. When a debug request or a breakpoint condition causes the chip to enter Debug mode, DE is asserted as an output for three clock cycles. DE has an internal pull-up resistor.				
			DE is not a standard part of the JTAG Test Access Port (TAP) Controller. It connects to the OnCE module to initiate Debug mode directly or to provide a direct external indication that the chip has entered the Debug mode. All other interface with the OnCE module must occur through the JTAG port.				
			This input is 5 V tolerant.				

Signals/Connections

1-22 Freescale Semiconductor

Specifications 2

The DSP56301 is fabricated in high-density CMOS with Transistor-Transistor Logic (TTL) compatible inputs and outputs.

2.1 Maximum Ratings

CAUTION

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, normal precautions should be taken to avoid exceeding maximum voltage ratings. Reliability is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{CC}).

Note: In the calculation of timing requirements, adding a maximum value of one specification to a minimum value of another specification does not yield a reasonable sum. A maximum specification is calculated using a worst case variation of process parameter values in one direction. The minimum specification is calculated using the worst case for the same parameters in the opposite direction. Therefore, a "maximum" value for a specification never occurs in the same device that has a "minimum" value for another specification; adding a maximum to a minimum represents a condition that can never exist.

2.2 Absolute Maximum Ratings

Table 2-1. Maximum Ratings

Rating ¹	Symbol	Value ^{1, 2}	Unit
Supply Voltage	V _{CC}	-0.3 to +4.0	V
All input voltages excluding "5 V tolerant" inputs ³	V _{IN}	GND – 0.3 to V _{CC} + 0.3	V
All "5 V tolerant" input voltages ³	V _{IN5}	GND – 0.3 to V _{CC} + 3.95	V
Current drain per pin excluding V _{CC} and GND	I	10	mA
Operating temperature range	TJ	-40 to +100	°C
Storage temperature	T _{STG}	-55 to +150	°C

Notes:

- 1. GND = 0 V, V_{CC} = 3.3 V ± 0.3 V, T_{J} = -40°C to +100°C, CL = 50 pF
- 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximum is not guaranteed. Stress beyond the maximum rating may affect device reliability or cause permanent damage to the device.
- 3. CAUTION: All "5 V Tolerant" input voltages cannot be more than 3.95 V greater than the supply voltage; this restriction applies to "power on," as well as during normal operation. In any case, the input voltages must not be higher than 5.75 V. "5 V Tolerant" inputs are inputs that tolerate 5 V.

2.3 Thermal Characteristics

Table 2-2. Thermal Characteristics

Characteristic	Symbol	TQFP Value	PBGA ³ Value	PBGA ⁴ Value	Unit
Junction-to-ambient thermal resistance ¹	$R_{\theta JA}$ or θ_{JA}	49.5	48.4	25.2	°C/W
Junction-to-case thermal resistance ²	$R_{\theta JC}$ or θ_{JC}	7.2	9	_	°C/W
Thermal characterization parameter	Ψ_{JT}	4.7	5	_	°C/W

Notes:

- Junction-to-ambient thermal resistance is based on measurements on a horizontal single-sided printed circuit board per JEDEC Specification JESD51-3.
- 2. Junction-to-case thermal resistance is based on measurements using a cold plate per SEMI G30-88, with the exception that the cold plate temperature is used for the case temperature.
- 3. These are simulated values. See note 1 for test board conditions.
- 4. These are simulated values. The test board has two 2-ounce signal layers and two 1-ounce solid ground planes internal to the test board.

2.4 DC Electrical Characteristics

Table 2-3. DC Electrical Characteristics⁶

Characteristics	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{CC}	3.0	3.3	3.6	V

DSP56301 Technical Data, Rev. 10

2-2 Freescale Semiconductor

Table 2-3. DC Electrical Characteristics⁶ (Continued)

Characteristics	Symbol	Min	Т	ур	Max	Unit						
Input high voltage • D[0–23], BG, BB, TA • MOD¹/IRQ¹, RESET, PINIT/NMI and all JTAG/ESSI/SCI/Timer/HI32 pins	V _{IH} V _{IHP}	2.0 2.0	_ _		_ _		_ _		_ _		V _{CC} 5.25	V V
• EXTAL ⁸	V_{IHX}	$0.8 \times V_{CC}$	-	_	V _{CC}	V						
Input low voltage • D[0–23], BG, BB, TA, MOD¹/IRQ¹, RESET, PINIT • All JTAG/ESSI/SCI/Timer/HI32 pins • EXTAL ⁸	V _{IL} V _{ILP} V _{ILX}	-0.3 -0.3 -0.3	- -		0.8 0.8 0.2 × V _{CC}	V V V						
Input leakage current	I _{IN}	-10	-	_	10	μΑ						
High impedance (off-state) input current (@ 2.4 V / 0.4 V)	I _{TSI}	-10	_		10	μΑ						
Output high voltage • TTL (I _{OH} = -0.4 mA) ^{5,7} • CMOS (I _{OH} = -10 μA) ⁵	V _{OH}	2.4 V _{CC} – 0.01	_ _		_ _	V V						
Output low voltage • TTL (I_{OL} = 1.6 mA, open-drain pins I_{OL} = 6.7 mA) ^{5,7} • CMOS (I_{OL} = 10 μ A) ⁵	V _{OL}		-	_ _ _		V V						
Internal supply current ² : In Normal mode In Wait mode ³ In Stop mode ⁴	I _{CCI} Iccw Iccs		80 MHz 100 MHz 102 127 6 7.5 100 100		_ _ _	mA mA μA						
PLL supply current		_	1		2.5	mA						
Input capacitance ⁵	C _{IN}	_	-	_		pF						

Notes:

- 1. Refers to MODA/IRQA, MODB/IRQB, MODC/IRQC, and MODD/IRQD pins.
- 2. Power Consumption Considerations on page 4-3 provides a formula to compute the estimated current requirements in Normal mode. To obtain these results, all inputs must be terminated (that is, not allowed to float). Measurements are based on synthetic intensive DSP benchmarks (see Appendix A). The power consumption numbers in this specification are 90 percent of the measured results of this benchmark. This reflects typical DSP applications. Typical internal supply current is measured with V_{CC} = 3.0 V at T_J = 100°C.
- 3. To obtain these results, all inputs must be terminated (that is, not allowed to float).
- 4. To obtain these results, all inputs that are not disconnected at Stop mode must be terminated (that is, not allowed to float). PLL and XTAL signals are disabled during Stop state.
- 5. Periodically sampled and not 100 percent tested.
- **6.** $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_{J} = -40 ^{\circ}\text{C}$ to +100 $^{\circ}\text{C}$, $C_{L} = 50 \text{ pF}$
- 7. This characteristic does not apply to XTAL and PCAP.
- 8. Driving EXTAL to the low V_{IHX} or the high V_{ILX} value may cause additional power consumption (DC current). To minimize power consumption, the minimum V_{IHX} should be no lower than $0.9 \times V_{CC}$ and the maximum V_{ILX} should be no higher than $0.1 \times V_{CC}$.

2.5 AC Electrical Characteristics

The timing waveforms shown in the AC electrical characteristics section are tested with a V_{IL} maximum of 0.3 V and a V_{IH} minimum of 2.4 V for all pins except EXTAL, which is tested using the input levels shown in Note 6 of **Table 2-3**. AC timing specifications, which are referenced to a device input signal, are measured in production with respect to the 50 percent point of the respective input signal's transition.

Note: Although the minimum value for the frequency of EXTAL is 0 MHz, the device AC test conditions are 15 MHz and rated speed.

All specifications for the high impedance state are guaranteed by design.

2.5.1 Internal Clocks

Table 2-4. Internal Clocks, CLKOUT

Characteristics	Symbol		2	
Gilaracteristics	Symbol	Min	Тур	Max
Internal operation frequency and CLKOUT with PLL enabled	f	_	$\begin{array}{c} (Ef \times MF) / \\ (PDF \times DF) \end{array}$	_
Internal operation frequency and CLKOUT with PLL disabled	f	_	Ef/2	_
Internal clock and CLKOUT high period • With PLL disabled • With PLL enabled and MF ≤ 4	T _H	 0.49 × ET _C × PDF × DF/MF	ET _C	 0.51 × ET _C × PDF × DF/MF
With PLL enabled and MF > 4		$0.47 \times \text{ET}_{\text{C}} \times \text{PDF} \times \text{DF/MF}$	_	$0.53 \times \text{ET}_{\text{C}} \times \text{PDF} \times \text{DF/MF}$
Internal clock and CLKOUT low period • With PLL disabled • With PLL enabled and MF ≤ 4	TL		ET _C	 0.51 × ET _C × PDF × DF/MF
With PLL enabled and MF > 4		$0.47 \times \text{ET}_{\text{C}} \times \text{PDF} \times \text{DF/MF}$	_	$0.53 \times \text{ET}_{\text{C}} \times \text{PDF} \times \text{DF/MF}$
Internal clock and CLKOUT cycle time with PLL enabled	T _C	_	ET _C × PDF × DF/MF	_
Internal clock and CLKOUT cycle time with PLL disabled	T _C	_	2 × ET _C	_
Instruction cycle time	I _{CYC}	_	T _C	_

Notes: 1. DF = Division Factor; Ef = External frequency; ET_C = External clock cycle = 1/Ef; MF = Multiplication Factor; PDF = Predivision Factor; T_C = Internal clock cycle

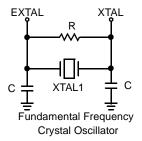
2. See the PLL and Clock Generator section in the DSP56300 Family Manual for details on the PLL.

2-4 Freescale Semiconductor

2-5

2.5.2 External Clock Operation

The DSP56301 system clock is derived from the on-chip oscillator or it is externally supplied. To use the on-chip oscillator, connect a crystal and associated resistor/capacitor components to EXTAL and XTAL; examples are shown in **Figure 2-1**.



Note: Make sure that in the PCTL Register:

- XTLD (bit 16) = 0
- If f_{OSC} > 200 kHz, XTLR (bit 15) = 0

Suggested Component Values:

$$\begin{split} &f_{OSC} = 4 \text{ MHz} \\ &R = 680 \text{ } k\Omega \pm 10\% \\ &C = 56 \text{ pF} \pm 20\% \end{split} \qquad \begin{aligned} &f_{OSC} = 20 \text{ MHz} \\ &R = 680 \text{ } k\Omega \pm 10\% \\ &C = 22 \text{ pF} \pm 20\% \end{aligned}$$

Calculations were done for a 4/20 MHz crystal with the following parameters:

- C_Lof 30/20 pF,
- C₀ of 7/6 pF,
- series resistance of 100/20 Ω , and
- drive level of 2 mW.

Figure 2-1. Crystal Oscillator Circuits

If an externally supplied square wave voltage source is used, disable the internal oscillator circuit during boot-up by setting XTLD (PCTL Register bit 16 = 1—see the *DSP56301 User's Manual*). The external square wave source connects to EXTAL; XTAL is not physically connected to the board or socket. **Figure 2-2** shows the relationship between the EXTAL input and the internal clock and CLKOUT.

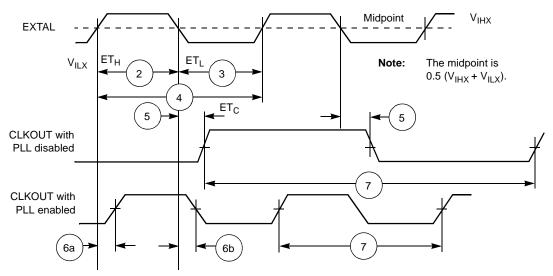


Figure 2-2. External Clock Timing

Table 2-5. Clock Operation

No.	Characteristics	Cumbal	80 MHz			100 MHz	
NO.	Characteristics	Symbol	Min	Max	Min	Max	
1	Frequency of EXTAL (EXTAL Pin Frequency) The rise and fall time of this external clock should be 3 ns maximum.	Ef	0	80.0 MHz	0	100.0 MHz	
2	 EXTAL input high^{1, 2} With PLL disabled (46.7%–53.3% duty cycle⁶) With PLL enabled (42.5%–57.5% duty cycle⁶) 	ET _H	5.84 ns 5.31 ns	∞ 157.0 μs	4.67 ns 4.25 ns	∞ 157.0 μs	
3	 EXTAL input low^{1, 2} With PLL disabled (46.7%–53.3% duty cycle⁶) With PLL enabled (42.5%–57.5% duty cycle⁶) 	ET _L	5.84 ns 5.31 ns	∞ 157.0 μs	4.67 ns 4.25 ns	∞ 157.0 μs	
4	EXTAL cycle time ² • With PLL disabled • With PLL enabled	ET _C	12.50 ns 12.50 ns	∞ 273.1 μs	10.00 ns 10.00 ns	∞ 273.1 μs	
5	CLKOUT change from EXTAL fall with PLL disabled		4.3 ns	11.0 ns	4.3 ns	11.0 ns	
6	a. CLKOUT rising edge from EXTAL rising edge with PLL enabled (MF = 1 or 2 or 4, PDF = 1, Ef > 15 MHz) 3,5		0.0 ns	1.8 ns	0.0 ns	1.8 ns	
	b. CLKOUT falling edge from EXTAL falling edge with PLL enabled (MF \leq 4, PDF \neq 1, Ef / PDF $>$ 15 MHz) 3,5		0.0 ns	1.8 ns	0.0 ns	1.8 ns	
7	Instruction cycle time = I _{CYC} = T _C ⁴ (see Table 2-4) (46.7%–53.3% duty cycle) • With PLL disabled		25.0 ns		20.0 ns		
	With PLL disabled With PLL enabled	Icyc	25.0 ns 12.50 ns	∞ 8.53 μs	20.0 ns 10.00 ns	_∞ 8.53 μs	

Notes:

- 1. Measured at 50 percent of the input transition
- 2. The maximum value for PLL enabled is given for minimum VCO frequency (see Table 2-6) and maximum MF.
- 3. Periodically sampled and not 100 percent tested
- 4. The maximum value for PLL enabled is given for minimum VCO frequency and maximum DF.
- 5. The skew is not guaranteed for any other MF value.
- 6. The indicated duty cycle is for the specified maximum frequency for which a part is rated. The minimum clock high or low time required for correction operation, however, remains the same at lower operating frequencies; therefore, when a lower clock frequency is used, the signal symmetry may vary from the specified duty cycle as long as the minimum high time and low time requirements are met.

2.5.3 Phase Lock Loop (PLL) Characteristics

Table 2-6. PLL Characteristics

Characteristics	1 08	ИНz	100 MHz			
Characteristics	Min Max Min Max		Max	Unit		
Voltage Controlled Oscillator (VCO) frequency when PLL enabled (MF \times E $_{\rm f} \times$ 2/PDF)	30	160	30	200	MHz	
PLL external capacitor (PCAP pin to V_{CCP}) (C_{PCAP}) • @ MF \leq 4	(MF × 580) – 100	(MF × 780) –	(MF × 580) – 100	(MF × 780) – 140	рF	
• @ MF > 4	MF × 830	MF × 1470	MF × 830	MF × 1470	pF	

Note: C_{PCAP} is the value of the PLL capacitor (connected between the PCAP pin and V_{CCP}). The recommended value in pF for C_{PCAP} can be computed from one of the following equations:

 $(680 \times MF) - 120$, for MF ≤ 4 , or $1100 \times MF$, for MF > 4.

2-6 Freescale Semiconductor

2.5.4 Reset, Stop, Mode Select, and Interrupt Timing

Table 2-7. Reset, Stop, Mode Select, and Interrupt Timing⁶

NI-	Oh ava ataviatia	F	80	MHz	100	MHz	1114
No.	Characteristics	Expression	Min	Max	Min	Max	Unit
8	Delay from RESET assertion to all pins at reset value ³	_	_	26.0	_	26.0	ns
9	Required RESET duration ⁴ Power on, external clock generator, PLL disabled Power on, external clock generator, PLL enabled Power on, internal oscillator During STOP, XTAL disabled (PCTL Bit 16 = 0) During STOP, XTAL enabled (PCTL Bit 16 = 1) During normal operation	$50 \times \text{ET}_{\text{C}} \\ 1000 \times \text{ET}_{\text{C}} \\ 75000 \times \text{ET}_{\text{C}} \\ 75000 \times \text{ET}_{\text{C}} \\ 2.5 \times \text{T}_{\text{C}} \\ 2.5 \times \text{T}_{\text{C}}$	625.0 12.5 1.0 1.0 31.3 31.3	_ _ _ _ _	500.0 10.0 0.75 0.75 25.0 25.0	_ _ _ _	ns µs ms ms ns ns
10	Delay from asynchronous RESET deassertion to first external address output (internal reset deassertion) ⁵ • Minimum • Maximum	3.25 × T _C + 2.0 20.25 T _C + 10.0	42.6 —	 263.1	34.5 —	 212.5	ns ns
11	Synchronous reset setup time from RESET deassertion to CLKOUT Transition 1 Minimum Maximum	T _C	7.4 —	 12.5	5.9 —	— 10.0	ns ns
12	Synchronous reset deasserted, delay time from the CLKOUT Transition 1 to the first external address output Minimum Maximum	3.25 × T _C + 1.0 20.25 × T _C + 1.0	41.6 —	 258.1	33.5 —	 207.5	ns ns
13	Mode select setup time		30.0	_	30.0	_	ns
14	Mode select hold time		0.0	_	0.0	_	ns
15	Minimum edge-triggered interrupt request assertion width		8.25	_	6.6	_	ns
16	Minimum edge-triggered interrupt request deassertion width		8.25	_	7.1	_	ns
17	Delay from IRQA, IRQB, IRQC, IRQD, NMI assertion to external memory access address out valid Caused by first interrupt instruction fetch Caused by first interrupt instruction execution	$4.25 \times T_{C} + 2.0$ $7.25 \times T_{C} + 2.0$	55.1 92.6		44.5 74.5		ns ns
18	Delay from IRQA, IRQB, IRQC, IRQD, NMI assertion to general-purpose transfer output valid caused by first interrupt instruction execution	10 × T _C + 5.0	130.0	_	105.0	_	ns
19	Delay from address output valid caused by first interrupt instruction execute to interrupt request deassertion for level sensitive fast interrupts ¹		_	Note 8	_	Note 8	ns ns
20	Delay from RD assertion to interrupt request deassertion for level sensitive fast interrupts ¹	80 MHz: $3.25 \times T_C + WS \times T_C - 12.4$ 100 MHz: $3.25 \times T_C + WS \times T_C - 10.94$	_	Note 8	_	Note 8	ns ns

 Table 2-7.
 Reset, Stop, Mode Select, and Interrupt Timing⁶ (Continued)

Na	Oh ava stavistica	Funnasian	1 08	ИHz	100	MHz	l l mit
No.	Characteristics	Expression	Min	Max	Min	Max	Unit
21	Delay from WR assertion to interrupt request deassertion for level sensitive fast interrupts ¹ • DRAM for all WS ⁷	80 MHz : (WS + 3.5) × T _C – 12.4 100 MHz :	_	Note 8		Note 8	ns
	• SRAM WS = 1	$(WS + 3.5) \times T_C - 10.94$ 80 MHz : $(WS + 3.5) \times T_C - 12.4$ 100 MHz :	_	Note 8		Note 8	ns ns ns
	• SRAM WS = 2, 3	(WS + 3.5) × T _C - 10.94 80 MHz : (WS + 3) × T _C - 12.4 100 MHz :	_	Note 8	_	Note 8	ns
	• SRAM WS ≥ 4	$ \begin{array}{c} (\text{WS} + 3) \times \text{T}_{\text{C}} - 10.94 \\ \textbf{80 MHz} \\ (\text{WS} + 2.5) \times \text{T}_{\text{C}} - 12.4 \\ \textbf{100 MHz} \\ \end{array} $	_	Note 8	-	Note 8	ns ns
22	Synchronous interrupt setup time from IRQA, IRQB, IRQC, IRQD, NMI assertion to the CLKOUT Transition 2	(WS + 2.5) × T _C – 10.94	7.4	T _C	5.9	T _C	ns
23	Synchronous interrupt delay time from the CLKOUT Transition 2 to the first external address output valid caused by the first instruction fetch after coming out of Wait Processing state Minimum Maximum	$8.25 \times T_{C} + 1.0$ $24.75 \times T_{C} + 5.0$	116.6 —	 314.4	83.5	 252.5	ns ns
24	Duration for IRQA assertion to recover from Stop state		7.4	_	5.9	_	ns
25	Delay from IRQA assertion to fetch of first instruction (when exiting Stop) ^{2, 3} • PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is enabled (Operating Mode Register Bit 6 = 0)	$PLC \times ET_{C} \times PDF + (128 \text{ K} - PLC/2) \times T_{C}$	1.6	17.0	1.3	13.6	ms
	 PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is not enabled (Operating Mode Register Bit 6 = 1) 	PLC × ET _C × PDF + $(23.75 \pm 0.5) \times$ T _C $(9.25 \pm 0.5) \times$ TC	290.6 ns 109.4	15.4 ms 121.9	232.5 ns 87.5	12.3 ms 97.5	ns
	 PLL is active during Stop (PCTL Bit 17 = 1) (Implies No Stop Delay) 						
26	Duration of level sensitive IRQA assertion to ensure interrupt service (when exiting Stop) ^{2, 3} PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is enabled (Operating Mode Register Bit 6 = 0)	$\begin{array}{c} PLC \times ET_{C} \times PDF + (128K - \\ PLC/2) \times T_{C} \end{array}$	17.0		13.6	_	ms
	 PLL is not active during Stop (PCTL Bit 17 = 0) and Stop delay is not enabled (Operating Mode Register Bit 6 = 1) 	PLC × ET _C × PDF + $(20.5 \pm 0.5) \times T_C$ $5.5 \times T_C$	15.4 68.8	_	12.3 55.0	_	ms ns
	 PLL is active during Stop (PCTL Bit 17 = 1) (implies no Stop delay) 						
27	Interrupt Request Rate HI32, ESSI, SCI, Timer DMA IRQ, NMI (edge trigger) IRQ, NMI (level trigger)	$12 \times T_{C}$ $8 \times T_{C}$ $8 \times T_{C}$ $12 \times T_{C}$		150.0 100.0 100.0 150.0	_ _ _ _	120.0 80.0 80.0 120.0	ns ns ns

DSP56301 Technical Data, Rev. 10

2-8 Freescale Semiconductor

Table 2-7. Reset, Stop, Mode Select, and Interrupt Timing⁶ (Continued)

No.	Characteristics	Francoica	80 MHz		100 MHz		Unit
	Characteristics	Expression	Min	Max	Min	Max	Onit
28	DMA Request Rate Data read from HI32, ESSI, SCI Data write to HI32, ESSI, SCI Timer RQ, NMI (edge trigger)	6 × T _C 7 × T _C 2 × T _C 3 × T _C	 - - -	75.0 87.5 25.0 37.5	_ _ _ _	60.0 70.0 20.0 30.0	ns ns ns
29	Delay from IRQA, IRQB, IRQC, IRQD, NMI assertion to external memory (DMA source) access address out valid	$4.25 \times T_{C} + 2.0$	55.1	_	44.5	_	ns

Notes:

- . When using fast interrupts and IRQA, IRQB, IRQC, and IRQD are defined as level-sensitive, timings 19 through 21 apply to prevent multiple interrupt service. To avoid these timing restrictions, the deasserted Edge-triggered mode is recommended when using fast interrupts. Long interrupts are recommended when using Level-sensitive mode.
- **2.** This timing depends on several settings:
 - For PLL disable, using internal oscillator (PLL Control Register (PCTL) Bit 16 = 0) and oscillator disabled during Stop (PCTL Bit 17 = 0), a stabilization delay is required to assure that the oscillator is stable before programs are executed. Resetting the Stop delay (Operating Mode Register Bit 6 = 0) provides the proper delay. While Operating Mode Register Bit 6 = 1 can be set, it is not recommended, and these specifications do not guarantee timings for that case.
 - For PLL disable, using internal oscillator (PCTL Bit 16 = 0) and oscillator enabled during Stop (PCTL Bit 17=1), no stabilization delay is required and recovery is minimal (Operating Mode Register Bit 6 setting is ignored).
 - For PLL disable, using external clock (PCTL Bit 16 = 1), no stabilization delay is required and recovery time is defined by the PCTL Bit 17 and Operating Mode Register Bit 6 settings.
 - For PLL enable, if PCTL Bit 17 is 0, the PLL is shutdown during Stop. Recovering from Stop requires the PLL to get locked. The PLL lock procedure duration, PLL Lock Cycles (PLC), may be in the range of 0 to 1000 cycles. This procedure occurs in parallel with the stop delay counter, and stop recovery ends when the last of these two events occurs. The stop delay counter completes count or PLL lock procedure completion.
 - PLC value for PLL disable is 0.
 - The maximum value for ET_C is 4096 (maximum MF) divided by the desired internal frequency (that is, for 66 MHz it is 4096/66 MHz = 62 μs). During the stabilization period, T_C, T_H, and T_L is not constant, and their width may vary, so timing may vary as well.
- 3. Periodically sampled and not 100 percent tested.
- 4. Value depends on clock source:
 - For an external clock generator, RESET duration is measured while RESET is asserted, V_{CC} is valid, and the EXTAL input is active and valid.
 - For an internal oscillator, RESET duration is measured while RESET is asserted and V_{CC} is valid. The specified timing reflects the crystal oscillator stabilization time after power-up. This number is affected both by the specifications of the crystal and other components connected to the oscillator and reflects worst case conditions.
 - When the V_{CC} is valid, but the other "required RESET duration" conditions (as specified above) have not been yet met, the device circuitry is in an uninitialized state that can result in significant power consumption and heat-up. Designs should minimize this state to the shortest possible duration.
- 5. If PLL does not lose lock.
- **6.** $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_{J} = -40 ^{\circ}\text{C}$ to $+100 ^{\circ}\text{C}$, $C_{L} = 50 \text{ pF}$.
- 7. WS = number of wait states (measured in clock cycles, number of T_C).
- 8. Use the expression to compute a maximum value.

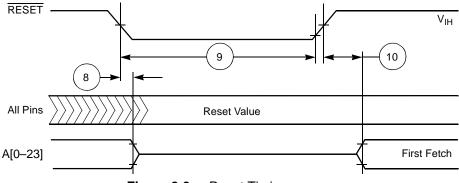


Figure 2-3. Reset Timing

DSP56301 Technical Data, Rev. 10

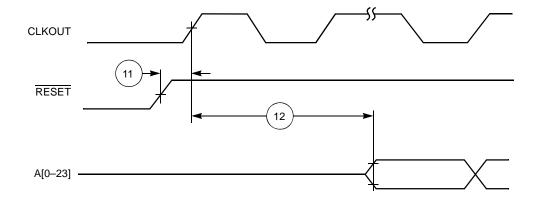
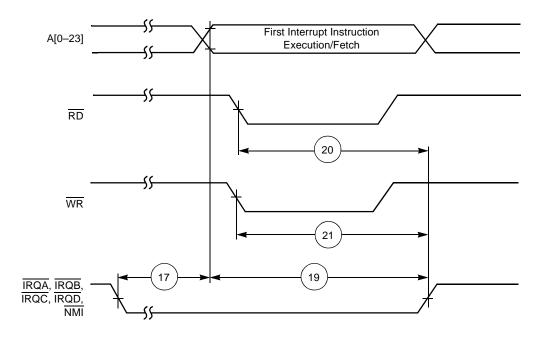
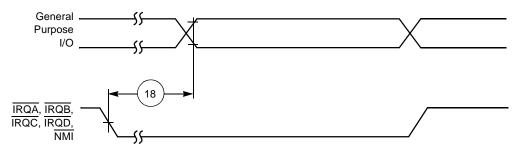


Figure 2-4. Synchronous Reset Timing



a) First Interrupt Instruction Execution



b) General-Purpose I/O

Figure 2-5. External Fast Interrupt Timing

DSP56301 Technical Data, Rev. 10

2-10 Freescale Semiconductor

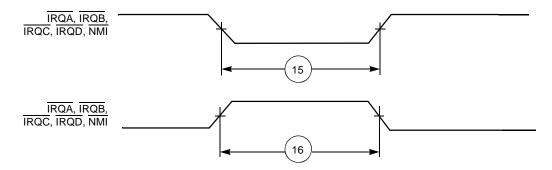


Figure 2-6. External Interrupt Timing (Negative Edge-Triggered)

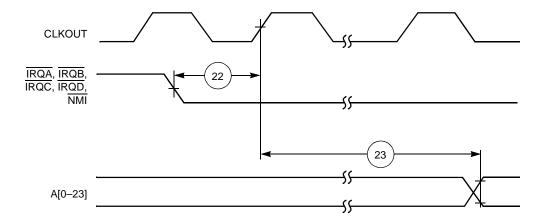


Figure 2-7. Synchronous Interrupt from Wait State Timing

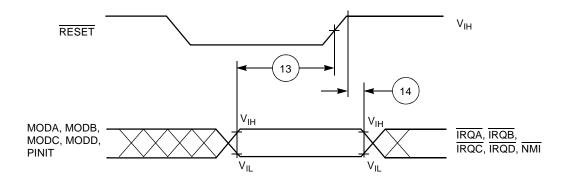


Figure 2-8. Operating Mode Select Timing

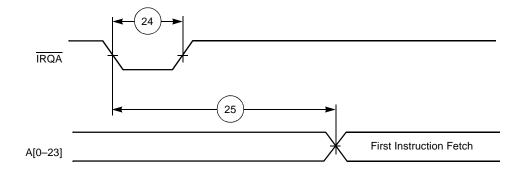


Figure 2-9. Recovery from Stop State Using IRQA

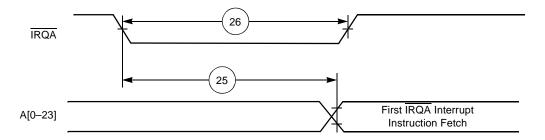


Figure 2-10. Recovery from Stop State Using IRQA Interrupt Service

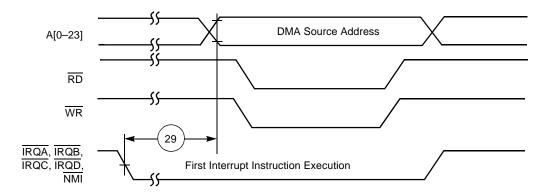


Figure 2-11. External Memory Access (DMA Source) Timing

2.5.5 External Memory Expansion Port (Port A)

2-12 Freescale Semiconductor

2.5.5.1 SRAM Timing

Table 2-8. SRAM Read and Write Accesses^{3,6}

NI	Oh annat a tation	0	F 1	80 1	ИНz	100	MHz	1124
No.	Characteristics	Symbol	Expression ¹	Min	Max	Min	Max	Unit
100	Address valid and AA assertion pulse width ²	t _{RC} , t _{WC}	$ \begin{array}{c} (\text{WS} + 1) \times \text{T}_{\text{C}} - 4.0 \ [1 \leq \text{WS} \leq 3] \\ (\text{WS} + 2) \times \text{T}_{\text{C}} - 4.0 \ [4 \leq \text{WS} \leq 7] \\ (\text{WS} + 3) \times \text{T}_{\text{C}} - 4.0 \ [\text{WS} \geq 8] \end{array} $	21.0 71.0 133.5	_ _ _	16.0 56.0 106.0	_ _ _	ns ns ns
101	Address and AA valid to WR assertion	t _{AS}	$\begin{array}{c} 0.25 \times T_{C} - 2.0 \; [WS = 1] \\ 0.75 \times T_{C} - 2.0 \; [2 \leq WS \leq 3] \\ 1.25 \times T_{C} - 2.0 \; [WS \geq 4] \end{array}$	1.1 7.4 13.6	 _ _	0.5 5.5 10.5	_ _ _	ns ns ns
102	WR assertion pulse width	t _{WP}	$\begin{array}{c} 1.5 \times T_{C} - 4.0 \; [WS = 1] \\ WS \times T_{C} - 4.0 \; [2 \leq WS \leq 3] \\ (WS - 0.5) \times T_{C} - 4.0 \; [WS \geq 4] \end{array}$	14.8 21.0 39.8	_ _ _	11.0 16.0 31.0	_ _ _	ns ns ns
103	WR deassertion to address not valid	t _{WR}	$\begin{array}{c} 0.25 \times T_{C} - 2.0 \; [1 \leq WS \leq 3] \\ 1.25 \times T_{C} - 4.0 \; [4 \leq WS \leq 7] \\ 2.25 \times T_{C} - 4.0 \; [WS \geq 8] \end{array}$	1.1 11.6 24.1	_ _ _	0.5 8.5 18.5	_ _ _	ns ns ns
104	Address and AA valid to input data valid	t _{AA} , t _{AC}	$(WS + 0.75) \times T_C - 5.0 [WS \ge 1]$	_	16.9	_	12.5	ns
105	RD assertion to input data valid	t _{OE}	$(WS + 0.25) \times T_{C} - 5.0 \ [WS \ge 1]$	_	10.6	_	7.5	ns
106	RD deassertion to data not valid (data hold time)	t _{OHZ}		0.0	_	0.0	_	ns
107	Address valid to WR deassertion ²	t _{AW}	$(WS + 0.75) \times T_C - 4.0 \ [WS \ge 1]$	17.9	_	13.5	_	ns
108	Data valid to WR deassertion (data setup time)	t _{DS} (t _{DW})	$(WS - 0.25) \times T_C - 3.0 \ [WS \ge 1]$	6.4	_	4.5	_	ns
109	Data hold time from WR deassertion	t _{DH}	$\begin{array}{c} 0.25 \times T_{C} - 2.0 \; [1 \leq WS \leq 3] \\ 1.25 \times T_{C} - 2.0 \; [4 \leq WS \leq 7] \\ 2.25 \times T_{C} - 2.0 \; [WS \geq 8] \end{array}$	1.1 13.6 26.1	_ _ _	0.5 10.5 20.5	_ _ _	ns ns ns
110	WR assertion to data active		$\begin{array}{c} 0.75 \times T_{C} - 3.7 \; [WS = 1] \\ 0.25 \times T_{C} - 3.7 \; [2 \leq WS \leq 3] \\ -0.25 \times T_{C} - 3.7 \; [WS \geq 4] \end{array}$	5.7 -0.6 -6.8	_ _ _	3.8 -1.2 -6.2	_ _ _	ns ns ns
111	WR deassertion to data high impedance		$\begin{array}{c} 0.25 \times T_{C} + 0.2 \; [1 \leq WS \leq 3] \\ 1.25 \times T_{C} + 0.2 \; [4 \leq WS \leq 7] \\ 2.25 \times T_{C} + 0.2 \; [WS \geq 8] \end{array}$	_ _ _	3.3 15.8 28.3	_ _ _	2.7 12.7 22.7	ns ns ns
112	Previous RD deassertion to data active (write)		$\begin{array}{l} 1.25 \times T_{C} - 4.0 \; [1 \leq WS \leq 3] \\ 2.25 \times T_{C} - 4.0 \; [4 \leq WS \leq 7] \\ 3.25 \times T_{C} - 4.0 \; [WS \geq 8] \end{array}$	11.6 24.1 36.6	_ _ _	8.5 18.5 28.5	_ _ _	ns ns ns
113	RD deassertion time		$\begin{array}{c} 0.75 \times T_C - 4.0 \; [1 \leq WS \leq 3] \\ 1.75 \times T_C - 4.0 \; [4 \leq WS \leq 7] \\ 2.75 \times T_C - 4.0 \; [WS \geq 8] \end{array}$	5.4 17.9 30.4	_ _ _	3.5 13.5 23.5	_ _ _	ns ns ns
114	WR deassertion time		$0.5 \times T_{C} - 4.0 \text{ [WS = 1]}$ $T_{C} - 4.0 \text{ [2 \le WS \le 3]}$ $2.5 \times T_{C} - 4.0 \text{ [4 \le WS \le 7]}$ $3.5 \times T_{C} - 4.0 \text{ [WS \ge 8]}$	2.3 8.5 27.3 39.8	_ _ _ _	1.0 6.0 21.0 31.0	_ _ _ _	ns ns ns

DSP56301 Technical Data, Rev. 10

Table 2-8. SRAM Read and Write Accesses^{3,6} (Continued)

No.	Characteristics	Symbol	Expression ¹	1 08	80 MHz		100 MHz		
140.	Onaracteristics	Oymboi	Expression	Min	Max	Min	Max	Unit	
115	Address valid to RD assertion		0.5 × T _C – 4.0	2.3	_	1.0	_	ns	
116	RD assertion pulse width		$(WS + 0.25) \times T_C - 4.0$	11.6	_	8.5	_	ns	
117	RD deassertion to address not valid		$\begin{array}{c} 0.25 \times T_{C} - 2.0 \ [1 \leq WS \leq 3] \\ 1.25 \times T_{C} - 2.0 \ [4 \leq WS \leq 7] \\ 2.25 \times T_{C} - 2.0 \ [WS \geq 8] \end{array}$	1.1 13.6 26.1	_ _ _	0.5 10.5 20.5	_ _ _	ns ns ns	
118	TA setup before RD or WR deassertion ⁴		$0.25 \times T_{C} + 2.0$	5.1	_	4.5	_	ns	
119	TA hold after RD or WR deassertion			0	_	0	_	ns	

- 1. WS is the number of wait states specified in the BCR.
- 2. Timings 100, 107 are guaranteed by design, not tested.
- 3. All timings for 100 MHz are measured from 0.5 · Vcc to 0.5 · Vcc
- **4.** Timing 118 is relative to the deassertion edge of \overline{RD} or \overline{WR} even if \overline{TA} remains active.
- 5. Timings 110, 111, and 112, are not helpful and are not specified for 100 MHz.
- **6.** $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_{J} = -40^{\circ}\text{C}$ to $+100^{\circ}\text{C}$, $C_{L} = 50 \text{ pF}$

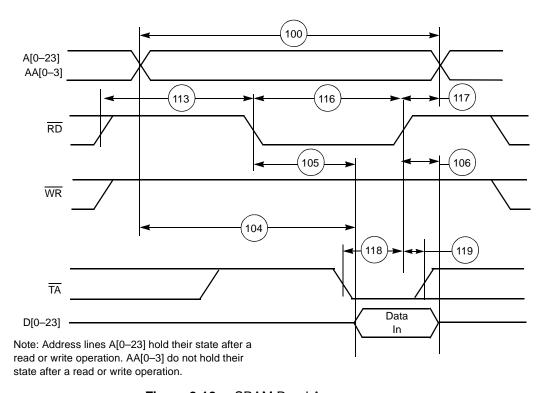
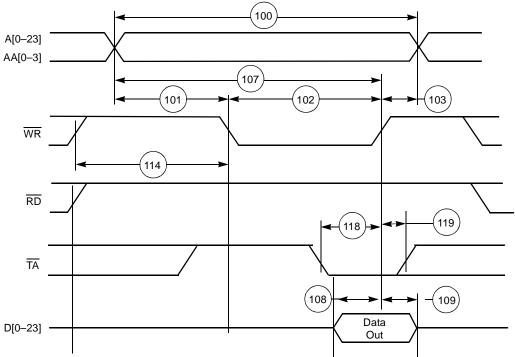


Figure 2-12. SRAM Read Access



Note: Address lines A[0–23] hold their state after a read or write operation. AA[0–3] do not hold their state after a read or write operation.

Figure 2-13. SRAM Write Access

2.5.5.2 DRAM Timing

The selection guides in **Figure 2-14** and **Figure 2-17** are for primary selection only. Final selection should be based on the timing in the following tables. For example, the selection guide suggests that four wait states must be used for 100 MHz operation in Page Mode DRAM. However, using the information in the appropriate table, a designer could choose to evaluate whether fewer wait states might be used by determining which timing prevents operation at 100 MHz, by running the chip at a slightly lower frequency (for example, 95 MHz), by using faster DRAM (if it becomes available), and by manipulating control factors such as capacitive and resistive load to improve overall system performance.

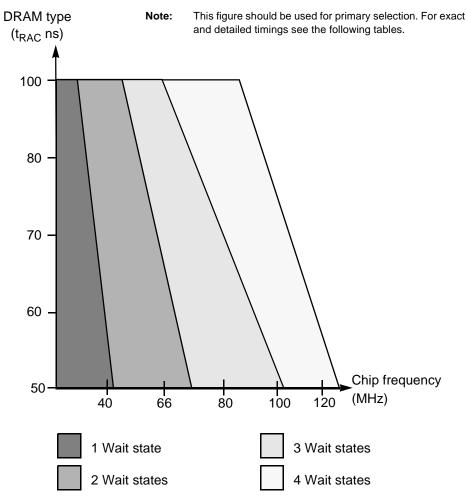


Figure 2-14. DRAM Page Mode Wait States Selection Guide

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Table 2-9. DRAM Page Mode Timings, Two Wait States^{1, 2, 3, 7}

NI-	Oh arrantariation	O	F	80 1	MHz	1111
No.	Characteristics	Symbol	Expression	Min	Max	Unit
131	Page mode cycle time for two consecutive accesses of the same direction		3×T _C	37.5	_	ns
	Page mode cycle time for mixed (read and write) accesses	t _{PC}	$2.75 \times T_{C}$	34.4	_	ns
132	CAS assertion to data valid (read)	t _{CAC}	$1.5 \times T_{C} - 6.5$	_	12.3	ns
133	Column address valid to data valid (read)	t _{AA}	$2.5 \times T_{C} - 6.5$	_	24.8	ns
134	CAS deassertion to data not valid (read hold time)	t _{OFF}		0.0	_	ns
135	Last CAS assertion to RAS deassertion	t _{RSH}	$1.75 \times T_{C} - 4.0$	17.9	_	ns
136	Previous CAS deassertion to RAS deassertion	t _{RHCP}	$3.25 \times T_{C} - 4.0$	36.6	_	ns
137	CAS assertion pulse width	t _{CAS}	$1.5 \times T_{C} - 4.0$	14.8	_	ns
138	Last $\overline{\text{CAS}}$ deassertion to $\overline{\text{RAS}}$ deassertion ⁵ BRW[1-0] = 00 BRW[1-0] = 01 BRW[1-0] = 10 BRW[1-0] = 11	t _{CRP}	Not supported $3.5 \times T_C - 6.0$ $4.5 \times T_C - 6.0$ $6.5 \times T_C - 6.0$	— 37.8 50.3 75.3	 - - -	ns ns ns
139	CAS deassertion pulse width	t _{CP}	$1.25 \times T_{C} - 4.0$	11.6	_	ns
140	Column address valid to CAS assertion	t _{ASC}	T _C – 4.0	8.5	_	ns
141	CAS assertion to column address not valid	t _{CAH}	$1.75 \times T_{C} - 4.0$	17.9	_	ns
142	Last column address valid to RAS deassertion	t _{RAL}	$3 \times T_C - 4.0$	33.5	_	ns
143	WR deassertion to CAS assertion	t _{RCS}	$1.25\times T_C-4$	11.6	_	ns
144	CAS deassertion to WR assertion	t _{RCH}	$0.5 \times T_C - 3.7$	2.6	_	ns
145	CAS assertion to WR deassertion	t _{WCH}	$1.5 \times T_C - 4.2$	14.6	_	ns
146	WR assertion pulse width	t _{WP}	$2.5\times T_C-4.5$	26.8	_	ns
147	Last WR assertion to RAS deassertion	t _{RWL}	$2.75\times T_C-4.3$	30.1	_	ns
148	WR assertion to CAS deassertion	t _{CWL}	$2.5\times T_C-4.3$	27.0	_	ns
149	Data valid to CAS assertion (write)	t _{DS}	$0.25\times T_C-3.0$	0.1	_	ns
150	CAS assertion to data not valid (write)	t _{DH}	$1.75\times T_C-4.0$	17.9	_	ns
151	WR assertion to CAS assertion	t _{WCS}	$T_C - 4.3$	8.2	_	ns
152	Last RD assertion to RAS deassertion	t _{ROH}	$2.5\times T_C-4.0$	27.3	_	ns
153	RD assertion to data valid	t _{GA}	$1.75 \times T_{C} - 6.5$	_	15.4	ns
154	RD deassertion to data not valid ⁶	t _{GZ}		0.0	_	ns
155	WR assertion to data active		$0.75 \times T_{C} - 1.5$	7.9	_	ns
156	WR deassertion to data high impedance		$0.25 \times T_{C}$	_	3.1	ns
153 154 155	RD assertion to data valid RD deassertion to data not valid WR assertion to data active	t _{GA}	$1.75 \times T_{C} - 6.5$ $0.75 \times T_{C} - 1.5$	0.0		

- 1. The number of wait states for Page mode access is specified in the DCR.
- 2. The refresh period is specified in the DCR.
- 3. The asynchronous delays specified in the expressions are valid for the DSP56301.
- 4. All the timings are calculated for the worst case. Some of the timings are better for specific cases (for example, t_{PC} equals $3 \times T_{C}$ for read-after-read or write-after-write sequences).
- 5. BRW[1–0] (DRAM Control Register bits) defines the number of wait states that should be inserted in each DRAM out-of-page access.
- **6.** RD deassertion always occurs after $\overline{\text{CAS}}$ deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ} .
- 7. At this time, there are no DRAMs fast enough to fit with two wait states Page mode @ 100MHz (see **Table 2-14**). However, DRAM speeds are approaching two-wait-state compatibility.

Table 2-10. DRAM Page Mode Timings, Three Wait States^{1, 2, 3}

NI-	Oh ann at a risting	0	F	80 1	MHz	100	MHz	11!6
No.	Characteristics	Symbol	Expression	Min	Max	Min	Max	Unit
131	Page mode cycle time for two consecutive accesses of the same direction		4×T _C	50.0	_	40.0	_	ns
	Page mode cycle time for mixed (read and write) accesses	t _{PC}	$3.5\times T_{\hbox{\scriptsize C}}$	43.7	_	35.0	_	ns
132	CAS assertion to data valid (read)	t _{CAC}	$2 \times T_C - 5.7$	_	19.3	_	14.3	ns
133	Column address valid to data valid (read)	t _{AA}	$3 \times T_C - 5.7$	_	31.8	_	24.3	ns
134	CAS deassertion to data not valid (read hold time)	t _{OFF}		0.0	_	0.0	_	ns
135	Last CAS assertion to RAS deassertion	t _{RSH}	$2.5\times T_C-4.0$	27.3	_	21.0	_	ns
136	Previous CAS deassertion to RAS deassertion	t _{RHCP}	$4.5 \times T_C - 4.0$	52.3	_	41.0	_	ns
137	CAS assertion pulse width	t _{CAS}	2 × T _C - 4.0	21.0	_	16.0	_	ns
138	Last CAS deassertion to RAS assertion ⁵ BRW[1-0] = 00 BRW[1-0] = 01 BRW[1-0] = 10 BRW[1-0] = 11	^t CRP	Not supported $3.75 \times T_{C} - 6.0$ $4.75 \times T_{C} - 6.0$ $6.75 \times T_{C} - 6.0$	40.9 53.4 78.4		31.5 41.5 61.5	 - - -	ns ns ns
139	CAS deassertion pulse width	t _{CP}	$1.5 \times T_{C} - 4.0$	14.8	_	11.0	_	ns
140	Column address valid to CAS assertion	t _{ASC}	T _C – 4.0	8.5	_	6.0	_	ns
141	CAS assertion to column address not valid	t _{CAH}	$2.5 \times T_{C} - 4.0$	27.3	_	21.0	_	ns
142	Last column address valid to RAS deassertion	t _{RAL}	$4 \times T_C - 4.0$	46.0	_	36.0	_	ns
143	WR deassertion to CAS assertion	t _{RCS}	$1.25 \times T_{C} - 4.0$	11.6	_	8.5	_	ns
144	CAS deassertion to WR assertion	t _{RCH}	0.75 × TC - 4.0	5.4	_	3.5	_	ns
145	CAS assertion to WR deassertion	t _{WCH}	2.25 × T _C – 4.2	23.9	_	18.3	_	ns
146	WR assertion pulse width	t _{WP}	$3.5 \times T_C - 4.5$	39.3	_	30.5	_	ns
147	Last WR assertion to RAS deassertion	t _{RWL}	$3.75 \times T_{C} - 4.3$	42.6	_	33.2	_	ns
148	WR assertion to CAS deassertion	t _{CWL}	$3.25 \times T_{C} - 4.3$	36.3	_	28.2	_	ns
149	Data valid to CAS assertion (write)	t _{DS}	$0.5 \times T_{C} - 4.8$	2.0	_	0.2	_	ns
150	CAS assertion to data not valid (write)	t _{DH}	$2.5 \times T_{C} - 4.0$	27.3	_	21.0	_	ns
151	WR assertion to CAS assertion	t _{WCS}	$1.25\times T_C-4.3$	11.3	_	8.2	_	ns
152	Last RD assertion to RAS deassertion	t _{ROH}	$3.5 \times T_C - 4.0$	39.8	_	31.0	_	ns
153	RD assertion to data valid	t _{GA}	$2.5 \times T_C - 5.7$	_	25.6	_	19.3	ns
154	RD deassertion to data not valid ⁶	t _{GZ}		0.0	_	0.0	_	ns
155	WR assertion to data active		$0.75 \times T_{C} - 1.5$	7.9	_	6.0	_	ns
156	WR deassertion to data high impedance		$0.25 \times T_{\hbox{\scriptsize C}}$	_	3.1	_	2.5	ns

- 1. The number of wait states for Page mode access is specified in the DCR.
- 2. The refresh period is specified in the DCR.
- 3. The asynchronous delays specified in the expressions are valid for DSP56301.
- 4. All the timings are calculated for the worst case. Some of the timings are better for specific cases (for example, t_{PC} equals 4 × T_C for read-after-read or write-after-write sequences).
- 5. BRW[1–0] (DRAM control register bits) defines the number of wait states that should be inserted in each DRAM out-of page-access.
- **6.** $\overline{\text{RD}}$ deassertion always occurs after $\overline{\text{CAS}}$ deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ} .

DRAM Page Mode Timings, Four Wait States^{1, 2, 3} Table 2-11.

			-	80 1	ИНz	100	MHz	
No.	Characteristics	Symbol	Expression	Min	Max	Min	Max	Unit
131	Page mode cycle time for two consecutive accesses of the same direction		5×T _C	62.5	_	50.0	_	ns
	Page mode cycle time for mixed (read and write) accesses	t _{PC}	$4.5 \times T_{C}$	56.2	_	45.0	_	ns
132	CAS assertion to data valid (read)	t _{CAC}	$2.75\times T_C-5.7$	_	28.7	_	21.8	ns
133	Column address valid to data valid (read)	t _{AA}	$3.75\times T_C-5.7$	_	41.2	_	31.8	ns
134	CAS deassertion to data not valid (read hold time)	t _{OFF}		0.0	_	0.0	_	ns
135	Last CAS assertion to RAS deassertion	t _{RSH}	$3.5 \times T_C - 4.0$	39.8	_	31.0	_	ns
136	Previous CAS deassertion to RAS deassertion	t _{RHCP}	$6 \times T_C - 4.0$	71.0	_	56.0	_	ns
137	CAS assertion pulse width	t _{CAS}	$2.5 \times T_C - 4.0$	27.3	_	21.0	_	ns
138	Last CAS deassertion to RAS assertion ⁵ BRW[1-0] = 00 BRW[1-0] = 01 BRW[1-0] = 10 BRW[1-0] = 11	^t CRP	Not supported $4.25 \times T_C - 6.0$ $5.25 \times T_C - 6.0$ $7.25 \times T_C - 6.0$	47.2 59.6 84.6	 - -	— 36.5 46.5 66.5	 - -	ns ns ns
139	CAS deassertion pulse width	t _{CP}	2 × T _C - 4.0	21.0	_	16.0	_	ns
140	Column address valid to CAS assertion	t _{ASC}	T _C – 4.0	8.5	_	6.0	_	ns
141	CAS assertion to column address not valid	t _{CAH}	$3.5 \times T_C - 4.0$	39.8	_	31.0	_	ns
142	Last column address valid to RAS deassertion	t _{RAL}	$5 \times T_C - 4.0$	58.5	_	46.0	_	ns
143	WR deassertion to CAS assertion	t _{RCS}	$1.25\times T_C-4.0$	11.8	_	8.5	_	ns
144	CAS deassertion to WR assertion	t _{RCH}	$1.25\times T_C-3.7$	11.9	_	8.8	_	ns
145	CAS assertion to WR deassertion	t _{WCH}	$3.25 \times T_C - 4.2$	36.4	_	28.3	_	ns
146	WR assertion pulse width	t _{WP}	$4.5\times T_C-4.5$	51.8	_	40.5	_	ns
147	Last WR assertion to RAS deassertion	t _{RWL}	$4.75\times T_C-4.3$	55.1	_	43.2	_	ns
148	WR assertion to CAS deassertion	t _{CWL}	$3.75\times T_{C}-4.3$	42.6	_	33.2	_	ns
149	Data valid to CAS assertion (write)	t _{DS}	$0.5 \times T_C - 4.8$	1.5	_	0.2	_	ns
150	CAS assertion to data not valid (write)	t _{DH}	$3.5\times T_C-4.0$	39.8	_	31.0	_	ns
151	WR assertion to CAS assertion	t _{WCS}	$1.25 \times T_{C} - 4.3$	11.3	_	8.2	_	ns
152	Last RD assertion to RAS deassertion	t _{ROH}	$4.5\times T_C-4.0$	52.3	_	41.0	_	ns
153	RD assertion to data valid	t _{GA}	$3.25 \times T_C - 5.7$	_	34.9	_	26.8	ns
154	RD deassertion to data not valid ⁶	t _{GZ}		0.0	_	0.0		ns
155	WR assertion to data active		$0.75 \times T_{C} - 1.5$	7.9	_	6.0	_	ns
156	WR deassertion to data high impedance		$0.25\times T_{\hbox{\scriptsize C}}$	-	3.1	_	2.5	ns

- Notes: 1. The number of wait states for Page mode access is specified in the DCR.
 - 2. The refresh period is specified in the DCR.
 - The asynchronous delays specified in the expressions are valid for DSP56301.
 - All the timings are calculated for the worst case. Some of the timings are better for specific cases (for example, t_{PC} equals $3 \times T_C$ for read-after-read or write-after-write sequences).
 - BRW[1-0] (DRAM control register bits) defines the number of wait states that should be inserted in each DRAM out-of-page access. N/A = does not apply because 100 MHz requires a minimum of three wait states.
 - RD deassertion always occurs after CAS deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ}.

2-19 Freescale Semiconductor

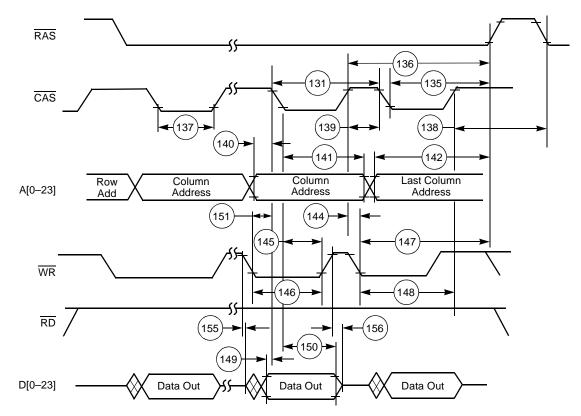


Figure 2-15. DRAM Page Mode Write Accesses

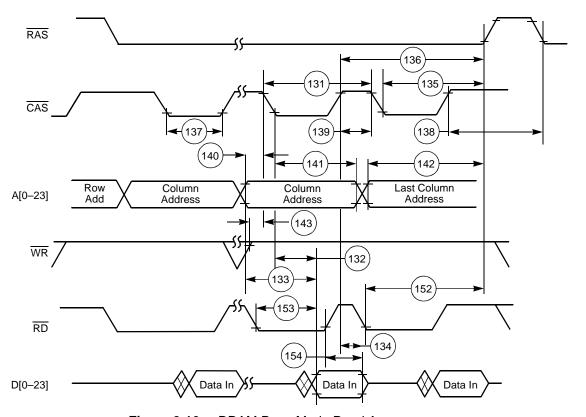


Figure 2-16. DRAM Page Mode Read Accesses

DSP56301 Technical Data, Rev. 10

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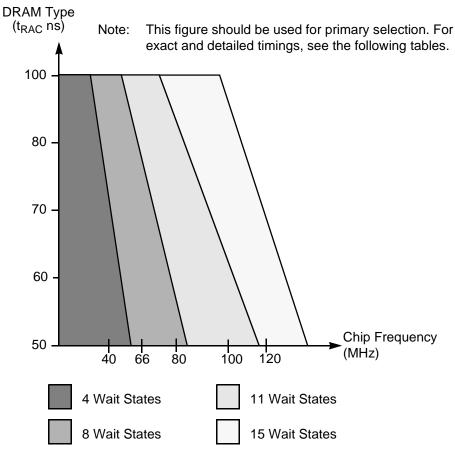


Figure 2-17. DRAM Out-of-Page Wait States Selection Guide

Table 2-12. DRAM Out-of-Page and Refresh Timings, Eight Wait States^{1, 2}

Na		Cumbal	Funnasian	1 08	ИНz	l l m i t
No.	Characteristics ³	Symbol	Expression	Min	Max	Unit
157	Random read or write cycle time	t _{RC}	9×T _C	112.5	_	ns
158	RAS assertion to data valid (read)	t _{RAC}	$4.75 \times T_{C} - 6.5$	_	52.9	ns
159	CAS assertion to data valid (read)	t _{CAC}	$2.25\times T_C-6.5$	_	21.6	ns
160	Column address valid to data valid (read)	t _{AA}	$3 \times T_C - 6.5$	_	31.0	ns
161	CAS deassertion to data not valid (read hold time)	t _{OFF}		0.0	_	ns
162	RAS deassertion to RAS assertion	t _{RP}	$3.25\times T_C-4.0$	36.6	_	ns
163	RAS assertion pulse width	t _{RAS}	$5.75\times T_C-4.0$	67.9	_	ns
164	CAS assertion to RAS deassertion	t _{RSH}	$3.25\times T_{C}-4.0$	36.6	_	ns
165	RAS assertion to CAS deassertion	t _{CSH}	$4.75\times T_C-4.0$	55.4	_	ns
166	CAS assertion pulse width	t _{CAS}	$2.25\times T_C-4.0$	24.1	_	ns
167	RAS assertion to CAS assertion	t _{RCD}	$2.5 \times T_C \pm 2$	29.3	33.3	ns
168	RAS assertion to column address valid	t _{RAD}	$1.75\times T_{C}\pm 2$	19.9	23.9	ns
169	CAS deassertion to RAS assertion	t _{CRP}	$4.25\times T_C-4.0$	49.1	_	ns
170	CAS deassertion pulse width	t _{CP}	$2.75\times T_{C}-6.0$	28.4		ns
171	Row address valid to RAS assertion	t _{ASR}	$3.25 \times T_{C} - 4.0$	36.6		ns

DSP56301 Technical Data, Rev. 10

Specifications

DRAM Out-of-Page and Refresh Timings, Eight Wait States^{1, 2} (Continued) Table 2-12.

Na		Comple al	Fygge	80 1	ИНz	l lm!t
No.	Characteristics ³	Symbol	Expression	Min	Max	Unit
172	RAS assertion to row address not valid	t _{RAH}	$1.75 \times T_{C} - 4.0$	17.9	_	ns
173	Column address valid to CAS assertion	t _{ASC}	$0.75 \times T_{C} - 4.0$	5.4	_	ns
174	CAS assertion to column address not valid	t _{CAH}	$3.25\times T_C-4.0$	36.6	_	ns
175	RAS assertion to column address not valid	t _{AR}	$5.75\times T_C-4.0$	67.9	_	ns
176	Column address valid to RAS deassertion	t _{RAL}	$4 \times T_C - 4.0$	46.0	_	ns
177	WR deassertion to CAS assertion	t _{RCS}	$2 \times T_C - 3.8$	21.2	_	ns
178	$\overline{\text{CAS}}$ deassertion to $\overline{\text{WR}}^4$ assertion	t _{RCH}	$1.25\times T_C-3.7$	11.9	_	ns
179	RAS deassertion to WR ⁴ assertion	t _{RRH}	$0.25\times T_C-2.6$	0.5	_	ns
180	CAS assertion to WR deassertion	t _{WCH}	$3 \times T_C - 4.2$	33.3	_	ns
181	RAS assertion to WR deassertion	t _{WCR}	$5.5 \times T_C - 4.2$	64.6	_	ns
182	WR assertion pulse width	t _{WP}	$8.5\times T_C-4.5$	101.8	_	ns
183	WR assertion to RAS deassertion	t _{RWL}	$8.75\times T_C-4.3$	105.1	_	ns
184	WR assertion to CAS deassertion	t _{CWL}	$7.75\times T_C-4.3$	92.6	_	ns
185	Data valid to CAS assertion (write)	t _{DS}	$4.75 \times T_{C} - 4.0$	55.4	_	ns
186	CAS assertion to data not valid (write)	t _{DH}	$3.25\times T_C-4.0$	36.6	_	ns
187	RAS assertion to data not valid (write)	t _{DHR}	$5.75\times T_C-4.0$	67.9	_	ns
188	WR assertion to CAS assertion	t _{WCS}	$5.5 \times T_C - 4.3$	64.5	_	ns
189	CAS assertion to RAS assertion (refresh)	t _{CSR}	$1.5\times T_{\text{C}}-4.0$	14.8	_	ns
190	RAS deassertion to CAS assertion (refresh)	t _{RPC}	$1.75 \times T_{C} - 4.0$	17.9	_	ns
191	RD assertion to RAS deassertion	t _{ROH}	$8.5 \times T_C - 4.0$	102.3	_	ns
192	RD assertion to data valid	t _{GA}	$7.5 \times T_{C} - 6.5$	_	87.3	ns
193	RD deassertion to data not valid ³	t _{GZ}		0.0	_	ns
194	WR assertion to data active		$0.75 \times T_{C} - 1.5$	7.9	_	ns
195	WR deassertion to data high impedance		$0.25 \times T_{C}$	_	3.1	ns

Notes:

- The number of wait states for an out-of-page access is specified in the DCR. $\underline{\text{The}} \text{ refresh period is specified in the } \underline{\text{DCR}}.$ 1.
- $\overline{\text{RD}}$ deassertion always occurs after $\overline{\text{CAS}}$ deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ} .
- Either t_{RCH} or t_{RRH} must be satisfied for read cycles.

2-22 Freescale Semiconductor

 Table 2-13.
 DRAM Out-of-Page and Refresh Timings, Eleven Wait States^{1, 2}

	21 3			80 1	ИНz	100	MHz	
No.	Characteristics ³	Symbol	Expression	Min	Max	Min	Max	Unit
157	Random read or write cycle time	t _{RC}	12 × T _C	150.0	_	120.0	_	ns
158	RAS assertion to data valid (read)	t _{RAC}		_	71.6	_	_ 55.5	ns ns
159	CAS assertion to data valid (read)	t _{CAC}	$80 \text{ MHz}: \\ 3.75 \times T_{\text{C}} - 6.5 \\ \textbf{100 MHz}: \\ 3.75 \times T_{\text{C}} - 7.0$	_	40.4	_	_ 30.5	ns ns
160	Column address valid to data valid (read)	t _{AA}	80 MHz: $4.5 \times T_{C} - 6.5$ 100 MHz: $4.5 \times T_{C} - 7.0$	_ 	49.8	_	_ 38.0	ns
161	CAS deassertion to data not valid (read hold time)	t _{OFF}		0.0	_	0.0	_	ns
162	RAS deassertion to RAS assertion	t _{RP}	$4.25 \times T_{C} - 4.0$	49.1	_	38.5	_	ns
163	RAS assertion pulse width	t _{RAS}	$7.75 \times T_{C} - 4.0$	92.9	_	73.5	_	ns
164	CAS assertion to RAS deassertion	t _{RSH}	5.25 × T _C – 4.0	61.6	_	48.5	_	ns
165	RAS assertion to CAS deassertion	t _{CSH}	$6.25 \times T_{C} - 4.0$	74.1	_	58.5	_	ns
166	CAS assertion pulse width	t _{CAS}	$3.75 \times T_{C} - 4.0$	42.9	_	33.5	_	ns
167	RAS assertion to CAS assertion	t _{RCD}	$2.5 \times T_C \pm 4.0$	27.3	35.3	21.0	29.0	ns
168	RAS assertion to column address valid	t _{RAD}	$1.75 \times T_{C} \pm 4.0$	17.9	25.9	13.5	21.5	ns
169	CAS deassertion to RAS assertion	t _{CRP}	5.75 × T _C – 4.0	67.9	_	53.5	_	ns
170	CAS deassertion pulse width	t _{CP}	$4.25 \times T_{C} - 6.0$	49.1	_	36.5	_	ns
171	Row address valid to RAS assertion	t _{ASR}	$4.25 \times T_{C} - 4.0$	49.1	_	38.5	_	ns
172	RAS assertion to row address not valid	t _{RAH}	1.75 × T _C – 4.0	17.9	_	13.5	_	ns
173	Column address valid to CAS assertion	t _{ASC}	$0.75\times T_C-4.0$	5.4	_	3.5		ns
174	CAS assertion to column address not valid	t _{CAH}	$5.25\times T_{C}-4.0$	61.6	_	48.5		ns
175	RAS assertion to column address not valid	t _{AR}	$7.75\times T_C-4.0$	92.9	_	73.5		ns
176	Column address valid to RAS deassertion	t _{RAL}	$6 \times T_C - 4.0$	71.0	_	56.0	_	ns
177	WR deassertion to CAS assertion	t _{RCS}	$3.0\times T_{C}-4.0$	33.5	_	26.0	_	ns
178	CAS deassertion to WR ⁴ assertion	t _{RCH}	$1.75\times T_C-3.7$	17.9	_	13.8	_	ns
179	RAS deassertion to WR ⁴ assertion	t _{RRH}	$\begin{array}{c} \textbf{80 MHz}:\\ 0.25\times T_{C}-2.6\\ \textbf{100 MHz}:\\ 0.25\times T_{C}-2.0 \end{array}$	0.5	_	0.5	_	ns ns
180	CAS assertion to WR deassertion	t _{WCH}	$5 \times T_{C} - 4.2$	58.3		45.8		ns
181	RAS assertion to WR deassertion	t _{WCR}	$7.5 \times T_{C} - 4.2$	89.6	_	70.8	_	ns
182	WR assertion pulse width	t _{WP}	$11.5 \times T_{C} - 4.5$	139.3		110.5	_	ns
183	WR assertion to RAS deassertion	t _{RWL}	11.75 × T _C – 4.3	142.7	_	113.2	_	ns
184	WR assertion to CAS deassertion	t _{CWL}	$10.25 \times T_{C} - 4.3$	123.8	_	98.2	_	ns
185	Data valid to CAS assertion (write)	t _{DS}	5.75 × T _C – 4.0	67.9	_	53.5	_	ns
186	CAS assertion to data not valid (write)	t _{DH}	5.25 × T _C – 4.0	61.6	_	48.5	_	ns

Table 2-13. DRAM Out-of-Page and Refresh Timings, Eleven Wait States^{1, 2} (Continued)

N.a.	Characteristics ³	Comple of	Fygge	1 08	ИНz	100	MHz	l lm!t
No.	Characteristics	Symbol	Expression	Min	Max	Min	Max	Unit
187	RAS assertion to data not valid (write)	t _{DHR}	$7.75 \times T_{C} - 4.0$	92.9	_	73.5	_	ns
188	WR assertion to CAS assertion	t _{WCS}	$6.5 \times T_C - 4.3$	77.0	_	60.7	_	ns
189	CAS assertion to RAS assertion (refresh)	t _{CSR}	$1.5 \times T_C - 4.0$	14.8	_	11.0	_	ns
190	RAS deassertion to CAS assertion (refresh)	t _{RPC}	$2.75\times T_C-4.0$	30.4	_	23.5	_	ns
191	RD assertion to RAS deassertion	t _{ROH}	11.5 × T _C – 4.0	139.8	_	111.0	_	ns
192	RD assertion to data valid	t _{GA}	80 MHz : $10 \times T_C - 6.5$ 100 MHz : $10 \times T_C - 7.0$	_	118.5	_	93.0	ns ns
193	RD deassertion to data not valid ³	t _{GZ}	10 % 10 7.0	0.0	_	0.0	_	ns
194	WR assertion to data active		$0.75 \times T_{C} - 1.5$	9.1	_	6.0	_	ns
195	WR deassertion to data high impedance		0.25 × T _C	_	3.1	_	2.5	ns

- 1. The number of wait states for an out-of-page access is specified in the DCR.
- 2. The refresh period is specified in the DCR.
- 3. \overline{RD} deassertion always occurs after \overline{CAS} deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ} .
- 4. Either t_{RCH} or t_{RRH} must be satisfied for read cycles.

Table 2-14. DRAM Out-of-Page and Refresh Timings, Fifteen Wait States^{1, 2}

No.	Characteristics ³	Symbol	Everencies	80 1	ИHz	100	MHz	Unit
NO.	Characteristics	Symbol	Expression	Min	Max	Min	Max	Unit
157	Random read or write cycle time	t _{RC}	16 × T _C	200.0	_	160.0	_	ns
158	RAS assertion to data valid (read)	t _{RAC}	80 MHz : $8.25 \times T_C - 6.5$ 100 MHz : $0.25 \times T_C = 5.7$	_	96.6		_	ns
	<u> </u>		$8.25 \times T_{C} - 5.7$	_	_	_	76.8	ns
159	CAS assertion to data valid (read)	t _{CAC}	80 MHz : 4.75 × T _C – 6.5 100 MHz :	_	52.9	_	_	ns
			$4.75 \times T_{C} - 5.7$	_	_	_	41.8	ns
160	Column address valid to data valid (read)	t _{AA}	80 MHz : 5.5 × T _C – 6.5 100 MHz :	_	62.3	_	_	ns
			$5.5 \times T_C - 5.7$	_	_	_	49.3	ns
161	CAS deassertion to data not valid (read hold time)	t _{OFF}	0.0	0.0		0.0	_	ns
162	RAS deassertion to RAS assertion	t _{RP}	$6.25\times T_C-4.0$	74.1	_	58.5	_	ns
163	RAS assertion pulse width	t _{RAS}	$9.75\times T_C-4.0$	117.9	_	93.5	_	ns
164	CAS assertion to RAS deassertion	t _{RSH}	$6.25\times T_C-4.0$	74.1	1	58.5	_	ns
165	RAS assertion to CAS deassertion	t _{CSH}	$8.25\times T_{\text{C}}-4.0$	99.1	1	78.5	_	ns
166	CAS assertion pulse width	t _{CAS}	$4.75 \times T_{C} - 4.0$	55.4	1	43.5	_	ns
167	RAS assertion to CAS assertion	t _{RCD}	$3.5 \times T_C \pm 2$	41.8	45.8	33.0	37.0	ns
168	RAS assertion to column address valid	t _{RAD}	$2.75 \times T_{\text{C}} \pm 2.0$	32.4	36.4	25.5	29.5	ns
169	CAS deassertion to RAS assertion	t _{CRP}	$7.75 \times T_{C} - 4.0$	92.9	_	73.5	_	ns

DSP56301 Technical Data, Rev. 10

2-24 Freescale Semiconductor

DRAM Out-of-Page and Refresh Timings, Fifteen Wait States^{1, 2} (Continued) Table 2-14.

	OL		-	80 1	ИHz	100	MHz	
No.	Characteristics ³	Symbol	Expression	Min	Max	Min	Max	Unit
170	CAS deassertion pulse width	t _{CP}	$6.25 \times T_{C} - 6.0$	74.1	_	56.5	_	ns
171	Row address valid to RAS assertion	t _{ASR}	$6.25 \times T_{C} - 4.0$	74.1	_	58.5	_	ns
172	RAS assertion to row address not valid	t _{RAH}	$2.75 \times T_{C} - 4.0$	30.4	_	23.5	_	ns
173	Column address valid to CAS assertion	t _{ASC}	$0.75 \times T_{C} - 4.0$	5.4	_	3.5	_	ns
174	CAS assertion to column address not valid	t _{CAH}	$6.25 \times T_{C} - 4.0$	74.1	_	58.5	_	ns
175	RAS assertion to column address not valid	t _{AR}	$9.75 \times T_{C} - 4.0$	117.9	_	93.5	_	ns
176	Column address valid to RAS deassertion	t _{RAL}	$7 \times T_C - 4.0$	83.5	_	66.0	_	ns
177	WR deassertion to CAS assertion	t _{RCS}	5 × T _C – 3.8	58.7	_	46.2	_	ns
178	$\overline{\text{CAS}}$ deassertion to $\overline{\text{WR}}^4$ assertion	t _{RCH}	$1.75 \times T_{C} - 3.7$	18.2	_	13.8	_	ns
179	RAS deassertion to WR ⁴ assertion	^t RRH	80 MHz : $0.25 \times T_C - 2.6$ 100 MHz : $0.25 \times T_C - 2.0$	0.5		— 0.5	_	ns ns
180	CAS assertion to WR deassertion	t _{WCH}	$6 \times T_C - 4.2$	70.8	_	55.8	_	ns
181	RAS assertion to WR deassertion	t _{WCR}	$9.5 \times T_{C} - 4.2$	114.6	_	90.8	_	ns
182	WR assertion pulse width	t _{WP}	15.5 × T _C – 4.5	189.3	_	150.5	_	ns
183	WR assertion to RAS deassertion	t _{RWL}	15.75 × T _C – 4.3	192.6	_	153.2	_	ns
184	WR assertion to CAS deassertion	t _{CWL}	14.25 × T _C – 4.3	173.8	_	138.2	_	ns
185	Data valid to CAS assertion (write)	t _{DS}	$8.75 \times T_{C} - 4.0$	105.4	_	83.5	_	ns
186	CAS assertion to data not valid (write)	t _{DH}	$6.25 \times T_{C} - 4.0$	74.1	_	58.5	_	ns
187	RAS assertion to data not valid (write)	t _{DHR}	9.75 × T _C – 4.0	117.9	_	93.5	_	ns
188	WR assertion to CAS assertion	t _{WCS}	$9.5 \times T_C - 4.3$	114.5	_	90.7	_	ns
189	CAS assertion to RAS assertion (refresh)	t _{CSR}	1.5 × T _C – 4.0	14.8	_	11.0	_	ns
190	RAS deassertion to CAS assertion (refresh)	t _{RPC}	$4.75 \times T_{C} - 4.0$	55.4	_	43.5	_	ns
191	RD assertion to RAS deassertion	t _{ROH}	15.5 × T _C – 4.0	189.8	_	151.0	_	ns
192	RD assertion to data valid	t _{GA}	80 MHz: $14 \times T_C - 6.5$ 100 MHz:	_	168.5	_	_	ns
			$14 \times T_C - 5.7$		_	_	134.3	ns
193	RD deassertion to data not valid ³	t _{GZ}		0.0	_	0.0	_	ns
194	WR assertion to data active		$0.75 \times T_{C} - 1.5$	9.1	_	6.0	_	ns
195	WR deassertion to data high impedance		$0.25 \times T_{C}$	_	3.1	_	2.5	ns

- The number of wait states for an out-of-page access is specified in the DCR.
- The refresh period is specified in the DCR.
- \overline{RD} deassertion always occurs after \overline{CAS} deassertion; therefore, the restricted timing is t_{OFF} and not t_{GZ} .
- Either t_{RCH} or t_{RRH} must be satisfied for read cycles.

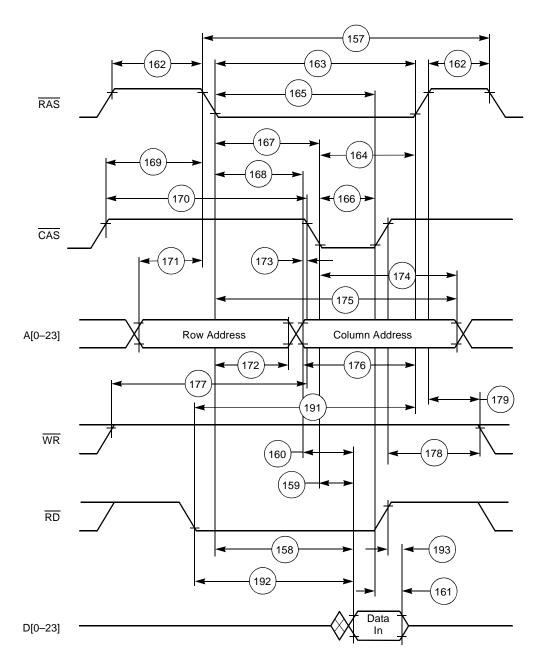


Figure 2-18. DRAM Out-of-Page Read Access

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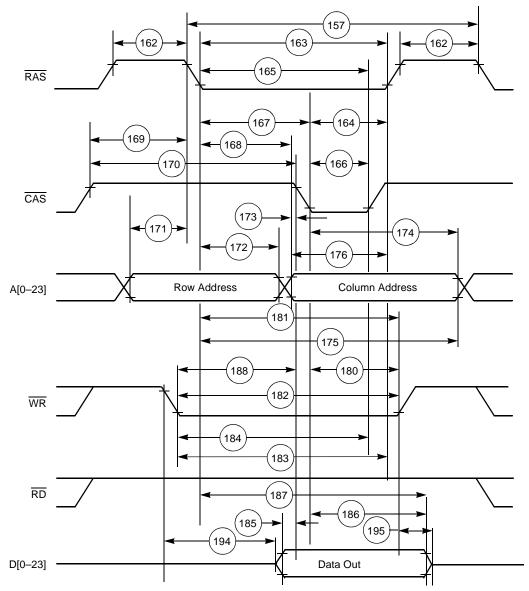


Figure 2-19. DRAM Out-of-Page Write Access

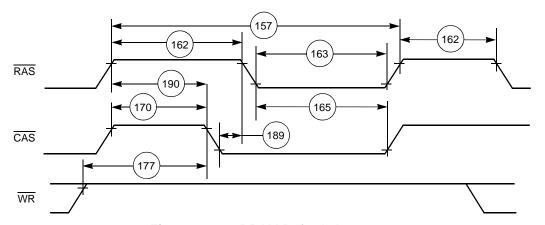


Figure 2-20. DRAM Refresh Access

2.5.5.3 Synchronous Timings (SRAM)

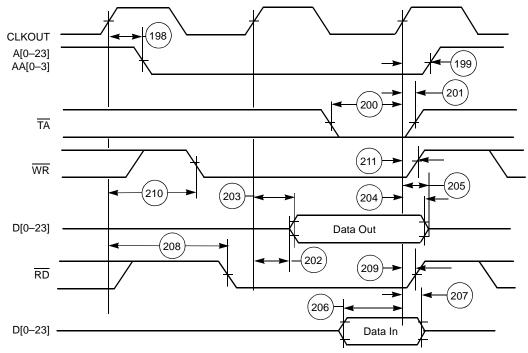
Table 2-15. External Bus Synchronous Timings (SRAM Access)³

NI -	Oh avantavintina	F	80 1	MHz	100	MHz	Unit	
No.	Characteristics	Expression ^{1,2}	Min	Max	Min	Max	Unit	
196	CLKOUT high to BS assertion	$0.25 \times T_{C} + 5.2 / -0.5$	2.6	8.3	2.0	7.7	ns	
197	CLKOUT high to BS deassertion	$0.75 \times T_{C} + 4.2 / -1.0$	8.4	13.6	6.5	11.7	ns	
198	CLKOUT high to address, and AA valid ⁴	$0.25 \times T_{C} + 2.5$	_	5.6	_	5.0	ns	
199	CLKOUT high to address, and AA invalid ⁴	$0.25 \times T_{C} - 0.7$	2.4	_	1.8	_	ns	
200	TA valid to CLKOUT high (setup time)		5.8	_	4.0	_	ns	
201	CLKOUT high to TA invalid (hold time)		0.0	_	0.0	_	ns	
202	CLKOUT high to data out active	0.25 × T _C	3.1	_	2.5	_	ns	
203	CLKOUT high to data out valid			7.6 —	_	— 6.5	ns ns	
204	CLKOUT high to data out invalid	0.25 × T _C	3.1	_	2.5	_	ns	
205	CLKOUT high to data out high impedance	$\begin{array}{c} \textbf{80 MHz:} \\ 0.25 \times T_{\text{C}} + 0.5 \\ \textbf{100 MHz:} \\ 0.25 \times T_{\text{C}} \end{array}$	 - -	3.6	_	_ 2.5	ns ns	
206	Data in valid to CLKOUT high (setup)		5.0	_	4.0	_	ns	
207	CLKOUT high to data in invalid (hold)		0.0	_	0.0	_	ns	
208	CLKOUT high to RD assertion	maximum: 0.75 × T _C + 2.5	10.4	11.9	6.7	10.0	ns ns	
209	CLKOUT high to RD deassertion		0.0	4.5	0.0	4.0	ns	
210	CLKOUT high to WR assertion ²	$0.5 \times T_C + 4.3$ [WS = 1 or WS \geq 4] [2 \leq WS \leq 3]	7.6 1.3	10.6 4.8	4.5 0.0	9.3 4.3	ns ns	
211	CLKOUT high to WR deassertion	[2 2 440 2 0]	0.0	4.3	0.0	3.8	ns	

Notes:

- 1. WS is the number of wait states specified in the BCR.
- 2. If WS > 1, $\overline{\text{WR}}$ assertion refers to the next rising edge of CLKOUT.
- 3. External bus synchronous timings should be used only for reference to the clock and *not* for relative timings.
- 4. T198 and T199 are valid for Address Trace mode if the ATE bit in the Operating Mode Register is set. Use the status of BR (See T212) to determine whether the access referenced by A[0–23] is internal or external in this mode.

2-28 Freescale Semiconductor



Note: Address lines A[0–23] hold their state after a read or write operation. AA[0–3] do not hold their state after a read or write operation.

CLKOUT A[0-23] **_**199 AA[0-3] 201 201 200 TA 211 WR 205 203 204 D[0-23] Data Out 202 208 (209 RD (207 (206 Data In D[0-23]

Figure 2-21. Synchronous Bus Timings 1 WS (BCR Controlled)

Note: Address lines A[0–23] hold their state after a read or write operation. AA[0–3] do not hold their state after a read or write operation.

Figure 2-22. Synchronous Bus Timings 2 WS (TA Controlled)

DSP56301 Technical Data, Rev. 10

2.5.5.4 Arbitration Timings

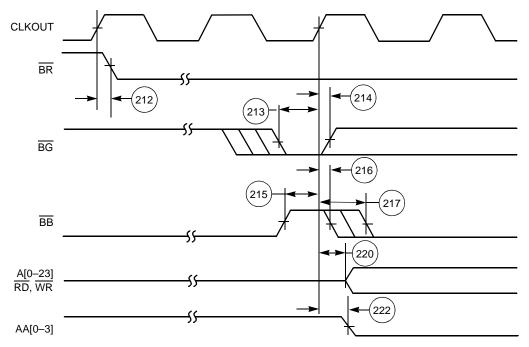
Table 2-16. Arbitration Bus Timings¹.

No.	Characteristics	Expression ²	80 1	MHz	100	MHz	Unit
NO.	Characteristics	Expression	Min	Max	Min	Max	Offic
212	CLKOUT high to BR assertion/deassertion ³		1.0	4.5	0.0	4.0	ns
213	BG asserted/deasserted to CLKOUT high (setup)		5.0	_	4.0	_	ns
214	CLKOUT high to \overline{BG} deasserted/asserted (hold)		0.0	_	0.0	_	ns
215	BB deassertion to CLKOUT high (input setup)		5.0	_	4.0	_	ns
216	CLKOUT high to BB assertion (input hold)		0.0	_	0.0	_	ns
217	CLKOUT high to BB assertion (output)		1.0	4.5	0.0	4.0	ns
218	CLKOUT high to BB deassertion (output)		1.0	4.5	0.0	4.0	ns
219	BB high to BB high impedance (output)		_	5.6	_	4.5	ns
220	CLKOUT high to address and controls active	0.25 × T _C	3.1	_	2.5	_	ns
221	CLKOUT high to address and controls high impedance	0.75 × T _C	_	9.4	_	7.5	ns
222	CLKOUT high to AA active	0.25 × T _C	3.1	_	2.5	_	ns
223	CLKOUT high to AA deassertion	maximum: $0.25 \times T_C + 4.0$	4.1	7.1	2.0	6.5	ns
224	CLKOUT high to AA high impedance	$0.75 \times T_{\mathbb{C}}$		9.4	_	7.5	ns

Notes:

- 1. Synchronous Bus Arbitration is not recommended. Use Asynchronous mode whenever possible.
- 2. An expression is used to compute the maximum or minimum value listed, as appropriate. For timing 223, the minimum is an absolute value.
- 3. T212 is valid for Address Trace mode when the ATE bit in the Operating Mode Register is set. BR is deasserted for internal accesses and asserted for external accesses.

2-30 Freescale Semiconductor



Note: Address lines A[0–23] hold their state after a read or write operation. AA[0–3] do not hold their state after a read or write operation.

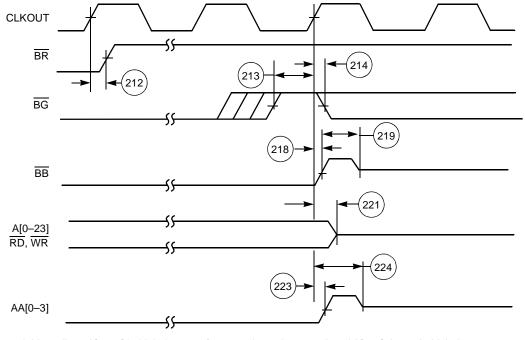
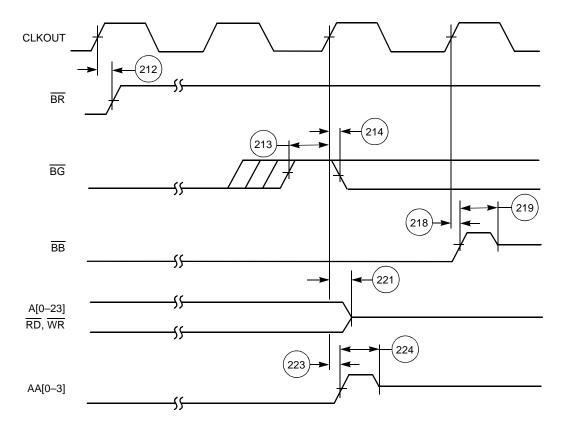


Figure 2-23. Bus Acquisition Timings

Note: Address lines A[0-23] hold their state after a read or write operation. AA[0-3] do not hold their state after a read or write operation.

Figure 2-24. Bus Release Timings Case 1 (BRT Bit in Operating Mode Register Cleared)



Note: Address lines A[0–23] hold their state after a read or write operation. AA[0–3] do not hold their state after a read or write operation.

Figure 2-25. Bus Release Timings Case 2 (BRT Bit in Operating Mode Register Set)

2.5.5.5 Asynchronous Bus Arbitrations Timings

Table 2-17. Asynchronous Bus Arbitration Timing^{1,3}

No. Characteristics	Characteristics	Expression	80 MHz		100 I	Unit	
	Onaraciensiles	Expression	Min	Max	Min	Max	Onic
250	BB assertion window from BG input deassertion ⁴	2.5 × Tc + 5	_	25		30	ns
251	Delay from BB assertion to BG assertion ⁴	2 × Tc + 5	25	_	25	_	ns

Notes:

- 1. Bit 13 in the Operating Mode Register must be set to enter Asynchronous Arbitration mode.
- 2. Asynchronous Arbitration mode is recommended for operation at 100 MHz.
- 3. If Asynchronous Arbitration mode is active, none of the timings in **Table 2-16** is required.
- 4. In order to guarantee timings 250, and 251, $\overline{\text{BG}}$ inputs must be asserted to different DSP56300 devices on the same bus in the non-overlap manner shown in **Figure 2-26**.

2-32 Freescale Semiconductor

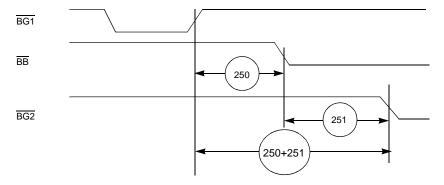


Figure 2-26. Asynchronous Bus Arbitration Timing

The asynchronous bus arbitration is enabled by internal \overline{BB} inputs and synchronization circuits on \overline{BG} . These synchronization circuits add delay from the external signal until it is exposed to internal logic. As a result of this delay, a DSP56300 part can assume mastership and assert \overline{BB} , for some time after \overline{BG} is deasserted. Timing 250 defines when \overline{BB} can be asserted.

Once \overline{BB} is asserted, there is a synchronization delay from \overline{BB} assertion to the time this assertion is exposed to other DSP56300 components which are potential masters on the same bus. If \overline{BG} input is asserted before that time, a situation of \overline{BG} asserted, and \overline{BB} deasserted, can cause another DSP56300 component to assume mastership at the same time. Therefore, a non-overlap period between one \overline{BG} input active to another \overline{BG} input active is required. Timing 251 ensures that such a situation is avoided.

2.5.6 Host Interface Timing

Table 2-18.	Universal E	Bus Mode	I iming I	-arameters
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	Observatoristis	Farmanasian	80 1	ИНz	100	MHz	11!6
No.	Characteristic	Expression	Min	Max	Min	Max	Unit
300	Access Cycle Time	3×T _C	37.5	_	30.0		ns
301	HA[10–0], HAEN Setup to Data Strobe Assertion ¹		5.8	_	4.6	I	ns
302	HA[10–0], HAEN Valid Hold from Data Strobe Deassertion ¹		0.0	_	0.0	I	ns
303	HRW Setup to HDS Assertion ²		5.8	_	4.6	_	ns
304	HRW Valid Hold from HDS Deassertion ²		0.0	_	0.0	I	ns
305	Data Strobe Deasserted Width ¹		4.1	_	3.3	_	ns
306	Data Strobe Asserted Pulse Width ¹	80 MHz: 2.5 × T _C + 1.7 100 MHz: 2.5 × T _C + 1.3	32.9	_	26.3	_	ns ns
307	HBS Asserted Pulse Width		2.5	_	2.0	_	ns
308	HBS Assertion to Data Strobe Assertion ¹	80 MHz: T _C – 4.9 100 MHz: T _C – 4.0	_	7.6	_	6.0	ns ns
309	HBS Assertion to Data Strobe Deassertion ¹	80 MHz: 2.5 × T _C + 2.9 100 MHz: 2.5 × T _C + 2.3	34.1	_	27.3	_	ns ns
310	HBS Deassertion to Data Strobe Deassertion ¹	80 MHz: 1.5 × T _C + 3.3 100 MHz: 1.5 × T _C + 2.6	22.1	_	17.6	_	ns ns
311	Data Out Valid to TA Assertion ($\overline{\rm HBS}$ Not Used—Tied to $\rm V_{CC})^2$	80 MHz: 2 × T _C - 11.6 100 MHz: 2 × T _C - 9.2	13.4	_	10.8		ns ns
312	Data Out Active from Read Data Strobe Assertion ³		1.7	_	1.3	_	ns

DSP56301 Technical Data, Rev. 10

 Table 2-18.
 Universal Bus Mode Timing Parameters (Continued)

No.	Characteristic	Fyggesien	80 1	ИНz	100	MHz	Unit
NO.	Characteristic	Expression	Min	Max	Min	Max	Unit
313	Data Out Valid from Read <u>Data</u> Strobe Assertion (No Wait States Inserted—HTA Asserted) ³		_	18.9	_	16.9	ns
314	Data Out Valid Hold from Read Data Strobe Deassertion ₃		1.7	_	1.3	_	ns
315	Data Out High Impedance from Read Data Strobe Deassertion ³		_	12.0	_	9.6	ns
316	Data In Valid Setup to Write Data Strobe Deassertion ⁴		8.3	_	6.6	_	ns
317	Data In Valid Hold from Write Data Strobe Deassertion ⁴		0.0	_	0.0	_	ns
318	HSAK Assertion from Data Strobe Assertion ¹		_	30.0	_	30.0	ns
319	HSAK Asserted Hold from Data Strobe Deassertion ¹		2.0	_	2.0	_	ns
320	HTA Active from Data Strobe Assertion ^{1,2,5}		3.1	_	2.5	_	ns
321	HTA Assertion from Data Strobe Assertion (HBS Not Used—Tied to V _{CC}) ^{1,2,5}	80 MHz: 2.0 × T _C + 13.0 100 MHz: 2.0 × T _C + 12.2	38.0	_	32.2	_	ns ns
322	HTA Assertion from HBS Assertion ^{2,5}	80 MHz: 2.0 × T _C + 13.0 100 MHz: 2.0 × T _C + 12.2	38.0	_	32.2	_	ns ns
323	HTA Deasserted from Data Strobe Assertion ^{1,2,5}		_	17.1	_	15.0	ns
324	HTA Assertion to Data Strobe Deassertion ^{1,2}		0.0	_	0.0	_	ns
325	HTA High Impedance from Data Strobe Deassertion ^{1,2}		_	15.3	_	12.2	ns
326	HIRQ Asserted Pulse Width (HIRH = 0, HIRD = 1)	$(LT + 1) \times T_C - 6.0^7$	19.0	_	14.0	_	ns
327	Data Strobe Deasserted Hold from HIRQ Deassertion (HIRH = 0) ¹		0.0	_	0.0	_	ns
328	HIRQ Asserted Hold from Data Strobe Assertion (HIRH = 1) ¹	1.5 × T _C	18.8	_	15.0	_	ns
329	HIRQ Deassertion from Data Strobe Assertion (HIRH = 1, HIRD = 1) ¹	80 MHz: 2.5 × T _C + 24.7 100 MHz: 2.5 × T _C + 21.5	_	55.9	_	46.5	ns ns
330	HIRQ High Impedance from Data Strobe Assertion (HIRH = 1, HIRD = 0) ^{1,6}	80 MHz: 2.5 × T _C + 24.7 100 MHz: 2.5 × T _C + 21.5	_	55.9	_	46.5	ns ns
331	HIRQ Active from Data Strobe Deassertion (HIRH = 1, HIRD = 0) ¹	2.5 × T _C	31.3	_	25.0	_	ns
332	HIRQ Deasserted Hold from Data Strobe Deassertion ¹	2.5 × T _C	31.3	_	25.0	_	ns
333	HDRQ ² Asserted Hold from Data Strobe Assertion ¹	1.5 × T _C	18.8	_	15.0	_	ns
334	HDRQ ² Deassertion from Data Strobe Assertion ¹	80 MHz: 2.5 × T _C + 24.7 100 MHz: 2.5 × T _C + 21.5	_	55.9	_	46.5	ns ns
335	HDRQ ² Deasserted Hold from Data Strobe Deassertion ¹	80 MHz: 2.5 × T _C + 3.7 100 MHz: 2.5 × T _C + 3.0	35.0	_	28.0	_	ns ns
336	HDAK Assertion to Data Strobe Assertion ¹		5.8	_	4.6	_	ns
337	HDAK Asserted Hold from Data Strobe Deassertion ¹		0.0	_	0.0	_	ns
338	HDBEN Deasserted Hold from Data Strobe Assertion ¹		2.5	_	2.0	_	ns
339	HDBEN Assertion from Data Strobe Assertion ¹		_	22.2	_	19.6	ns
340	HDBEN Asserted Hold from Data Strobe Deassertion ¹		2.5	_	2.0	_	ns
341	HDBEN Deassertion from Data Strobe Deassertion ¹		_	22.2	_	19.6	ns
342	HDBDR High Hold from Read Data Strobe Assertion ³		2.5	_	2.0	_	ns
343	HDBDR Low from Read Data Strobe Assertion ³		_	22.2	_	19.6	ns
344	HDBDR Low Hold from Read Data Strobe Deassertion ³		2.5	_	2.0	_	ns

DSP56301 Technical Data, Rev. 10

2-34 Freescale Semiconductor

Table 2-18. Universal Bus Mode Timing Parameters (Continued)

No. Characteristic	Characteristic	Expression	80 MHz Expression		100	Unit	
	Expression	Min	Max	Min	Max	Ollit	
345	HDBDR High from Read Data Strobe Deassertion ³			22.2	_	19.6	ns
346	HRST Assertion to Host Port Pins High Impedance ²		1	22.2	_	19.6	ns

- 1. The Data Strobe is $\overline{\text{HRD}}$ or $\overline{\text{HWR}}$ in the Dual Data Strobe mode and $\overline{\text{HDS}}$ in the Single Data Strobe mode.
- 2. HTA, HDRQ, and HRST may be programmed as active-high or active-low. In the example timing diagrams, HDRQ and HRST are shown as active-high and HTA is shown as active low.
- 3. The Read Data Strobe is HRD in the Dual Data Strobe mode and HDS in the Single Data Strobe mode.
- 4. The Write Data Strobe is \overline{HWR} in the Dual Data Strobe mode and \overline{HDS} in the Single Data Strobe mode.
- 5. HTA requires an external pull-down resistor if programmed as active high (HTAP = 0); or an external pull-up resistor if programmed as active low (HTAP = 1). The resistor value should be consistent with the DC specifications.
- **6.** HIRQ requires an external pull-up resistor if programmed as open drain (HIRD = 0). The resistor value should be consistent with the DC specifications.
- 7. "LT" is the value of the latency timer register (CLAT) as programmed by the user during self configuration. $LT \ge 1$.
- **8.** Values are valid for $V_{CC} = 3.3 \pm 0.3 V$

Table 2-19. Universal Bus Mode, Synchronous Port A Type Host Timing

	01		80 I	MHz	100	MHz	
No.	Characteristic	Expression	Min	Max	Min	Max	Unit
300	Access Cycle Time	$3 \times T_{C}$	37.5	_	30.0	_	ns
301	HA[10-0], HAEN Setup to Data Strobe Assertion ¹		5.8	_	4.6	_	ns
302	HA[10–0], HAEN Valid Hold from Data Strobe Deassertion ¹		0.0	_	0.0	_	ns
305	Data Strobe Deasserted Width ¹		4.1	_	3.3	_	ns
307	HBS Asserted Pulse Width		2.5	_	2.0	_	ns
308	HBS Assertion to Data Strobe Assertion ¹	80 MHz: T _C – 4.9 100 MHz: T _C – 4.0	_	7.6	_	6.0	ns ns
309	HBS Assertion to Data Strobe Deassertion ¹	80 MHz: 2.5 × T _C + 2.9 100 MHz: 2.5 × T _C + 2.3	34.1	_	27.3	_	ns ns
310	HBS Deassertion to Data Strobe Deassertion ¹	80 MHz: 1.5 × T _C + 3.3 100 MHz: 1.5 × T _C + 2.6	22.1	_	17.6	_	ns ns
312	Data Out Active from Read Data Strobe Assertion ³		1.7	_	1.3	_	ns
313	Data Out Valid from Read <u>Data</u> Strobe Assertion (No Wait States Inserted—HTA Asserted) ³		_	18.9	_	16.9	ns
314	Data Out Valid Hold from Read Data Strobe Deassertion ₃		1.7	_	1.3	_	ns
315	Data Out High Impedance from Read Data Strobe Deassertion ³		_	12.0	_	9.6	ns
316	Data In Valid Setup to Write Data Strobe Deassertion ⁴		8.3	_	6.6	_	ns
317	Data In Valid Hold from Write Data Strobe Deassertion ⁴		0.0	_	0.0	_	ns
324	HTA Assertion to Data Strobe Deassertion ^{1,2}		0.0	_	0.0	_	ns
325	HTA High Impedance from Data Strobe Deassertion ^{1,2}		_	15.3	_	12.2	ns
326	HIRQ Asserted Pulse Width (HIRH = 0, HIRD = 1)	$(LT + 1) \times T_C - 6.0^7$	6.5	_	4.0	_	ns
327	Data Strobe Deasserted Hold from HIRQ Deassertion (HIRH = 0) ¹		0.0	_	0.0	_	ns
328	HIRQ Asserted Hold from Data Strobe Assertion (HIRH = 1) ¹	1.5 × T _C	18.8	_	15.0	_	ns
329	HIRQ Deassertion from Data Strobe Assertion (HIRH = 1, HIRD = 1) ¹	80 MHz: 2.5 × T _C + 24.7 100 MHz: 2.5 × T _C + 21.5		55.9		46.5	ns ns

Table 2-19. Universal Bus Mode, Synchronous Port A Type Host Timing (Continued)

No.	Characteristic	Evaracian	80 MHz		100	MHz	Unit
NO.	Characteristic	Expression	Min	Max	Min	Max	Unit
330	HIRQ High Impedance from Data Strobe Assertion (HIRH = 1, HIRD = 0) ^{1,6}	80 MHz: 2.5 × T _C + 24.7 100 MHz: 2.5 × T _C + 21.5		55.9	_	46.5	ns ns
331	HIRQ Active from Data Strobe Deassertion (HIRH = 1, HIRD = 0) ¹	2.5 × T _C	31.3	_	25.0	_	ns
332	HIRQ Deasserted Hold from Data Strobe Deassertion ¹	2.5 × T _C	31.3	_	25.0	_	ns
346	HRST Assertion to Host Port Pins High Impedance ²		_	22.2	_	19.6	ns
347	HBS Assertion to CLKOUT Rising Edge		4.3	_	3.4	_	ns
348	Data Strobe Deassertion to CLKOUT Rising Edge ¹		7.4	_	5.9	_	ns

- 1. The Data Strobe is HRD or HWR in the Dual Data Strobe mode and HDS in the Single Data Strobe mode.
- 2. HTA, HDRQ, and HRST may be programmed as active-high or active-low. In the example timing diagrams, HDRQ and HRST are shown as active-high and HTA is shown as active low.
- 3. The Read Data Strobe is $\overline{\text{HRD}}$ in the Dual Data Strobe mode and $\overline{\text{HDS}}$ in the Single Data Strobe mode.
- 4. The Write Data Strobe is $\overline{\text{HWR}}$ in the Dual Data Strobe mode and $\overline{\text{HDS}}$ in the Single Data Strobe mode.
- 5. HTA requires an external pull-down resistor if programmed as active high (HTAP = 0); or an external pull-up resistor if programmed as active low (HTAP = 1). The resistor value should be consistent with the DC specifications.
- **6.** HIRQ requires an external pull-up resistor if programmed as open drain (HIRD = 0). The resistor value should be consistent with the DC specifications.
- 7. "LT" is the value of the latency timer register (CLAT) as programmed by the user during self configuration.
- **8.** Values are valid for $V_{CC} = 3.3 \pm 0.3 V$

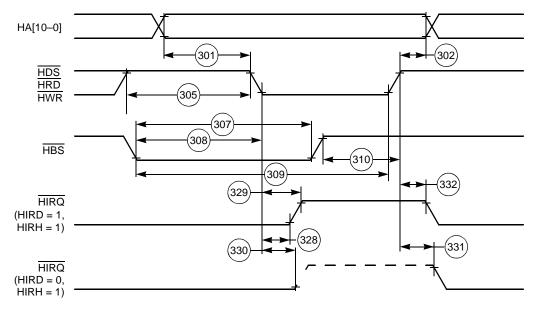


Figure 2-27. Universal Bus Mode I/O Access Timing

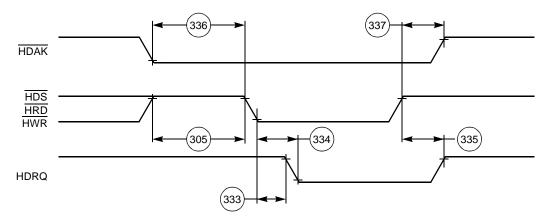


Figure 2-28. Universal Bus Mode DMA Access Timing

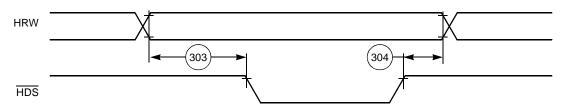


Figure 2-29. HRW to HDS Timing

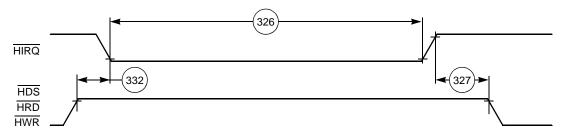


Figure 2-30. \overline{HIRQ} Pulse Width (HIRH = 0)

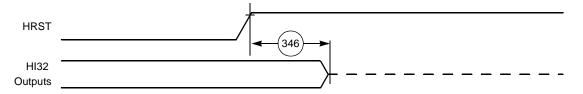


Figure 2-31. HRST Timing

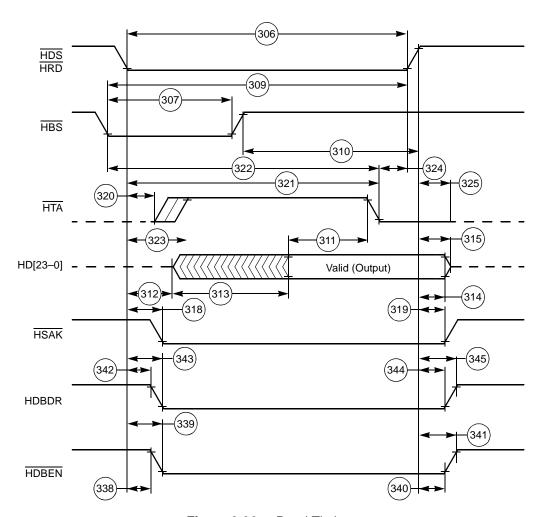


Figure 2-32. Read Timing

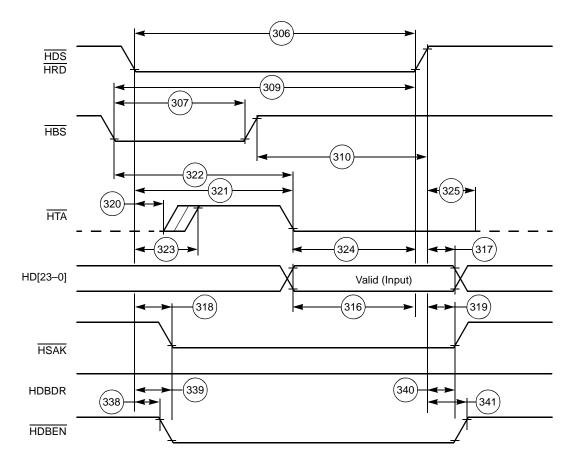


Figure 2-33. Write Timing

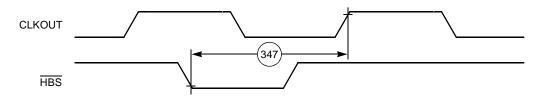


Figure 2-34. HBS Synchronous Timing

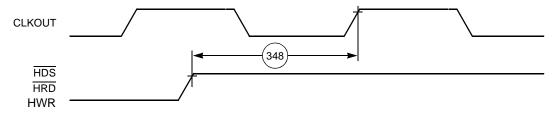


Figure 2-35. Data Strobe Synchronous Timing

Table 2-20. PCI Mode Timing Parameters¹

NI -	Observation 10	0	80 N	ИHz	100	100 MHz	
No.	Characteristic ¹⁰	Symbol	Min	Max	Min	Max	Unit
349	HCLK to Signal Valid Delay—Bussed Signals	t _{VAL}	2.0	11.0	2.0	11.0	ns
350	HCLK to Signal Valid Delay—Point to Point	t _{VAL(ptp)}	2.0	12.0	2.0	12.0	ns
351	Float to Active Delay	t _{ON}	2.0	_	2.0	_	ns
352	Active to Float Delay	t _{OFF}	_	28.0	_	28.0	ns
353	Input Set Up Time to HCLK—Bussed Signals	t _{SU}	7.0	_	7.0	_	ns
354	Input Set Up Time to HCLK—Point to Point	t _{SU(ptp)}	10.0, 12.0	_	10.0, 12.0	_	ns
355	Input Hold Time from HCLK	t _H	0.0	_	0.0	_	ns
356	Reset Active Time After Power Stable	t _{RST}	1.0	_	1.0	_	ms
357	Reset Active Time After HCLK Stable	t _{RST-CLK}	100.0		100.0	_	μs
358	Reset Active to Output Float Delay	t _{RST-OFF}	_	40.0	_	40.0	ns
359	HCLK Cycle Time	t _{CYC}	30.0	_	30.0	_	ns
360	HCLK High Time	t _{HIGH}	11.0	_	11.0	_	ns
361	HCLK Low Time	t _{LOW}	11.0	_	11.0	_	ns

- 1. For standard PCI timing, see the PCI Local Bus Specification, Rev. 2.0, especially Chapters 3 and 4.
- 2. The HI32 supports these timings for a PCI bus operating at 33 MHz for a DSP clock frequency of 56 MHz and above. The DSP core operating frequency should be greater than 5/3 of the PCI bus frequency to maintain proper PCI operation.
- 3. HGNT has a setup time of 10 ns. HREQ has a setup time of 12 ns.

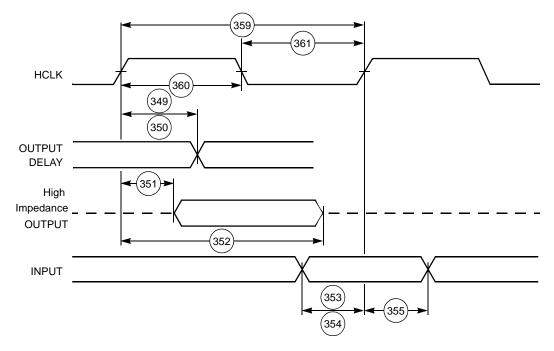


Figure 2-36. PCI Timing

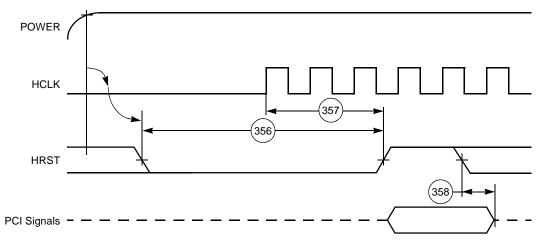


Figure 2-37. PCI Reset Timing

2.5.7 SCI Timing

Table 2-21. SCI Timing

				1 08	ИНz	100	MHz	
No.	Characteristics ¹	Symbol	Expression	Min	Max	Min	Max	Unit
400	Synchronous clock cycle	t _{SCC} ²	8×T _C	100.0	_	80.0	_	ns
401	Clock low period		t _{SCC} /2 – 10.0	40.0	_	30.0	_	ns
402	Clock high period		t _{SCC} /2 - 10.0	40.0	_	30.0	_	ns
403	Output data setup to clock falling edge (internal clock)		$t_{SCC}/4 + 0.5 \times T_C - 17.0$	14.3	_	8.0	_	ns
404	Output data hold after clock rising edge (internal clock)		$t_{SCC}/4 - 0.5 \times T_{C}$	18.8	_	15.0	_	ns
405	Input data setup time before clock rising edge (internal clock)		$t_{SCC}/4 + 0.5 \times T_C + 25.0$	56.3	_	50.0	_	ns
406	Input data not valid before clock rising edge (internal clock)		$t_{SCC}/4 + 0.5 \times T_C - 5.5$	_	25.8	_	19.5	ns
407	Clock falling edge to output data valid (external clock)			_	32.0	_	32.0	ns
408	Output data hold after clock rising edge (external clock)		T _C + 8.0	20.5	_	18.0	_	ns
409	Input data setup time before clock rising edge (external clock)			0.0	_	0.0	_	ns
410	Input data hold time after clock rising edge (external clock)			9.0	_	9.0	_	ns
411	Asynchronous clock cycle	t _{ACC} 3	64 × T _C	800.0	_	640.0	_	ns
412	Clock low period		t _{ACC} /2 - 10.0	390.0	_	310.0	_	ns
413	Clock high period		t _{ACC} /2 - 10.0	390.0	_	310.0	_	ns
414	Output data setup to clock rising edge (internal clock)		t _{ACC} /2 - 30.0	370.0	_	290.0	_	ns
415	Output data hold after clock rising edge (internal clock)		t _{ACC} /2 - 30.0	370.0	_	290.0	_	ns

Table 2-21. SCI Timing (Continued)

No	01111	Characteristics ¹ Symbol Expression	Evarencies	80 I	ИНz	100	I Init	
No.	Characteristics		Min	Max	Min	Max	Unit	
Notes	1. $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_J = -40^{\circ}\text{C}$ to +100 °C,	$C_1 = 50 pF$						

- - t_{SCC} = synchronous clock cycle time (For internal clock, t_{SCC} is determined by the SCI clock control register and t_{CC}) t_{ACC} = asynchronous clock cycle time; value given for 1X Clock mode (For internal clock, t_{ACC} is determined by the SCI clock control register and T_C)

400

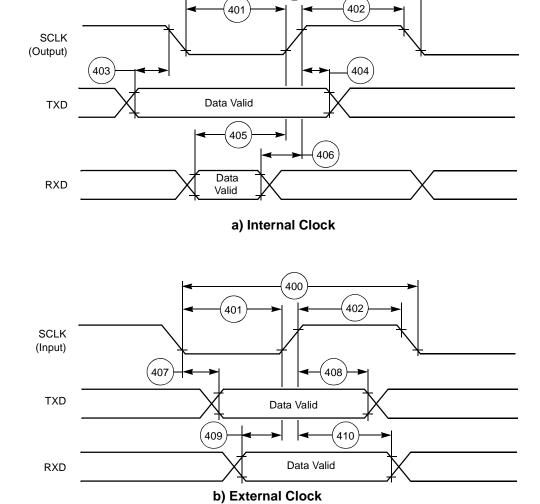


Figure 2-38. SCI Synchronous Mode Timing

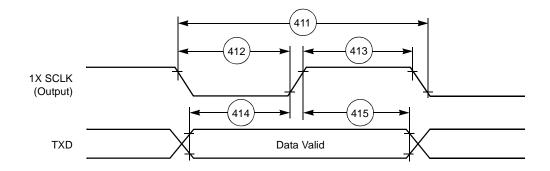


Figure 2-39. SCI Asynchronous Mode Timing

2.5.8 ESSI0/ESSI1 Timing

Table 2-22. ESSI Timings

	0 457			80 1	ИНz	100	MHz	Cond-	
No.	Characteristics ^{4, 5, 7}	Symbol	Expression	Min	Max	Min	Max	ition ⁶	Unit
430	Clock cycle ¹	t _{SSICC}	$\begin{array}{c} 3\times T_C \\ 4\times T_C \end{array}$	50.0 37.5	_ _	30.0 40.0	_ _	x ck i ck	ns
431	Clock high period For internal clock For external clock		$2 \times T_{C} - 10.0$ $1.5 \times T_{C}$	15.0 18.8	_	10.0 15.0	_		ns ns
432	Clock low period For internal clock For external clock		2 × T _C - 10.0 1.5 × T _C	15.0 18.8	_	10.0 15.0	_		ns ns
433	RXC rising edge to FSR out (bl) high			_ _	37.0 22.0	_	37.0 22.0	x ck i ck a	ns
434	RXC rising edge to FSR out (bl) low			_	37.0 22.0	_	37.0 22.0	x ck i ck a	ns
435	RXC rising edge to FSR out (wr) high ²			_	39.0 24.0	_	39.0 24.0	x ck i ck a	ns
436	RXC rising edge to FSR out (wr) low ²			_	39.0 24.0	_	39.0 24.0	x ck i ck a	ns
437	RXC rising edge to FSR out (wl) high			_ _	36.0 21.0	_	36.0 21.0	x ck i ck a	ns
438	RXC rising edge to FSR out (wl) low			_	37.0 22.0	_	37.0 22.0	x ck i ck a	ns
439	Data in setup time before RXC (SCK in Synchronous mode) falling edge			10.0 19.0	_	10.0 19.0	_	x ck i ck	ns
440	Data in hold time after RXC falling edge			5.0 3.0	_	5.0 3.0	_	x ck i ck	ns
441	FSR input (bl, wr) high before RXC falling edge ²			1.0 23.0	_	1.0 23.0	_	x ck i ck a	ns
442	FSR input (wl) high before RXC falling edge			3.5 23.0	_	3.5 23.0	_	x ck i ck a	ns
443	FSR input hold time after RXC falling edge			3.0 0.0	_	3.0 0.0		x ck i ck a	ns
444	Flags input setup before RXC falling edge			5.5 19.0		5.5 19.0		x ck i ck s	ns

Table 2-22. ESSI Timings (Continued)

No.	Characteristics ^{4, 5, 7}	Symbol	Expression	80 MHz		100 MHz		Cond-	
				Min	Max	Min	Max	ition ⁶	Unit
445	Flags input hold time after RXC falling edge			6.0 0.0	_	6.0 0.0	_	x ck i ck s	ns
446	TXC rising edge to FST out (bl) high				29.0 15.0	_	29.0 15.0	x ck i ck	ns
447	TXC rising edge to FST out (bl) low			_	31.0 17.0	_	31.0 17.0	x ck i ck	ns
448	TXC rising edge to FST out (wr) high ²			_	31.0 17.0	_	31.0 17.0	x ck i ck	ns
449	TXC rising edge to FST out (wr) low ²			_	33.0 19.0	_	33.0 19.0	x ck i ck	ns
450	TXC rising edge to FST out (wl) high			_	30.0 16.0	_	30.0 16.0	x ck i ck	ns
451	TXC rising edge to FST out (wl) low			_	31.0 17.0	_	31.0 17.0	x ck i ck	ns
452	TXC rising edge to data out enable from high impedance			_	31.0 17.0	_	31.0 17.0	x ck i ck	ns
453	TXC rising edge to Transmitter #0 drive enable assertion			_	34.0 20.0	_	34.0 20.0	x ck i ck	ns
454	TXC rising edge to data out valid ⁸			_	20.0 10.0	_	20.0 10.0	x ck i ck	ns
455	TXC rising edge to data out high impedance ³			_	31.0 16.0	_	31.0 16.0	x ck i ck	ns
456	TXC rising edge to Transmitter #0 drive enable deassertion ³				34.0 20.0	_	34.0 20.0	x ck i ck	ns
457	FST input (bl, wr) setup time before TXC falling edge ²			2.0 21.0	_	2.0 21.0	<u>-</u>	x ck i ck	ns
458	FST input (wl) to data out enable from high impedance			_	27.0	_	27.0	_	ns
459	FST input (wl) to Transmitter #0 drive enable assertion			_	31.0	_	31.0	_	ns
460	FST input (wl) setup time before TXC falling edge			2.5 21.0	_	2.5 21.0	_	x ck i ck	ns
461	FST input hold time after TXC falling edge			4.0 0.0	_	4.0 0.0		x ck i ck	ns
462	Flag output valid after TXC rising edge			_	32.0 18.0	_	32.0 18.0	x ck i ck	ns

2-44 Freescale Semiconductor

Table 2-22. ESSI Timings (Continued)

No.	Characteristics ^{4, 5, 7}	Symbol	Expression	80 MHz		100 MHz		Cond-	1111
				Min	Max	Min	Max	ition ⁶	Unit

Notes:

- For the internal clock, the external clock cycle is defined by the instruction cycle time (timing 7 in **Table 2-5** on page 2-6) and the ESSI control register.
- 2. The word-relative frame sync signal waveform relative to the clock operates the same way as the bit-length frame sync signal waveform, but spreads from one serial clock before the first bit clock (same as Bit Length Frame Sync signal), until the one before the last bit clock of the first word in frame.
- 3. Periodically sampled and not 100 percent tested
- **4.** $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_J = -40 ^{\circ}\text{C}$ to +100 $^{\circ}\text{C}$, $C_L = 50 \text{ pF}$
- 5. TXC (SCK Pin) = Transmit Clock RXC (SC0 or SCK Pin) = Receive Clock

FST (SC2 Pin) = Transmit Frame Sync

FSR (SC1 or SC2 Pin) Receive Frame Sync

6. i ck = Internal Clock

x ck = External Clock

i ck a = Internal Clock, Asynchronous Mode

(Asynchronous implies that TXC and RXC are two different clocks)

i ck s = Internal Clock, Synchronous Mode

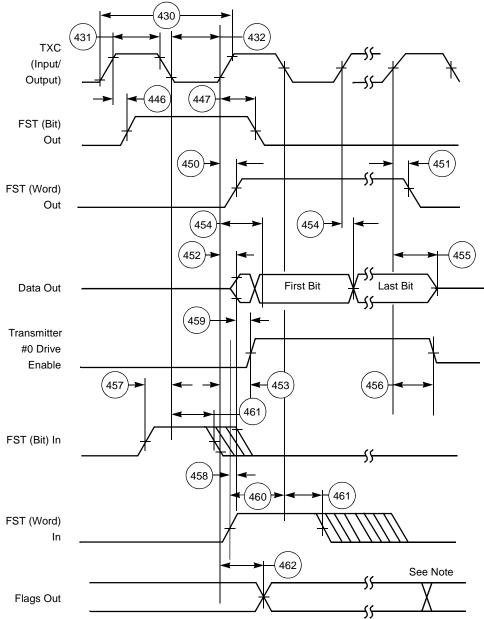
(Synchronous implies that TXC and RXC are the same clock)

7. bl = bit length

wl = word length

wr = word length relative

If the DSP core writes to the transmit register during the last cycle before causing an underrun error, the delay is 20 ns + (0.5 × T_C).



Note: In Network mode, output flag transitions can occur at the start of each time slot within the frame. In Normal mode, the output flag state is asserted for the entire frame period.

Figure 2-40. ESSI Transmitter Timing

2-46 Freescale Semiconductor

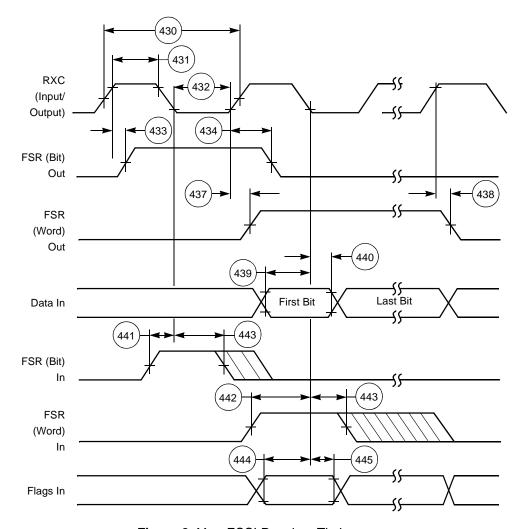


Figure 2-41. ESSI Receiver Timing

2.5.9 Timer Timing

Table 2-23. Timer Timing

N.	Characteristics	F	1 08	ИНz	100 MHz		11-26
No.	Cnaracteristics	Expression	Min	Max	Min	Max	Unit
480	TIO Low	2 × T _C + 2.0	27.0	_	22.0		ns
481	TIO High	2 × T _C + 2.0	27.0	_	22.0		ns
482	Timer setup time from TIO (Input) assertion to CLKOUT rising edge		9.0	12.5	9.0	10.0	ns
483	Synchronous timer delay time from CLKOUT rising edge to the external memory access address out valid caused by first interrupt instruction execution	$10.25 \times T_{C} + 1.0$	129.1	_	103.5	_	ns
484	CLKOUT rising edge to TIO (Output) assertion Minimum Maximum	$0.5 \times T_{C} + 0.5$ $0.5 \times T_{C} + 19.8$	9.8 —	 26.1	5.5 —	 24.8	ns ns

DSP56301 Technical Data, Rev. 10

Table 2-23. Timer Timing (Continued)

No.	Characteristics	Everession	80 MHz		100 MHz		Unit
		Expression	Min	Max	Min	Max	
485	CLKOUT rising edge to TIO (Output) deassertion Minimum Maximum	$0.5 \times T_{C} + 0.5$ $0.5 \times T_{C} + 19.8$	9.8 —	 26.1	5.5 —	 24.8	ns ns
Note:	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}; T_{J} = -40 ^{\circ}\text{C to } +100 ^{\circ}\text{C}, C_{L} = 50 \text{ pF}$						

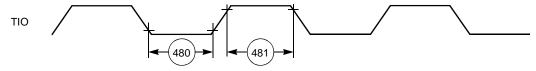


Figure 2-42. TIO Timer Event Input Restrictions

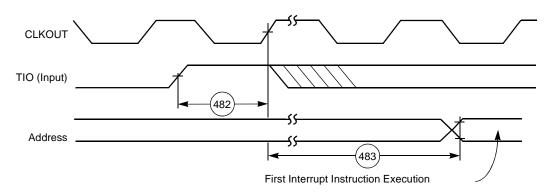


Figure 2-43. Timer Interrupt Generation

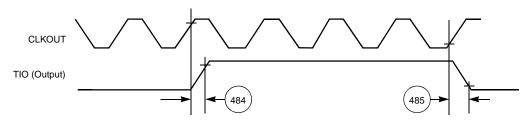


Figure 2-44. External Pulse Generation

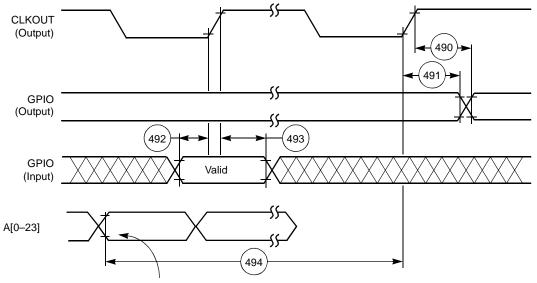
2.5.10 GPIO Timing

Table 2-24. GPIO Timing

No.	Characteristics	Evarossion	80 MHz		100 MHz		Unit
NO.	Cridiacteristics	Expression	Min	Max	Min	Max	Ullit
490	CLKOUT edge to GPIO out valid (GPIO out delay time)		_	31.0	_	8.5	ns
491	CLKOUT edge to GPIO out not valid (GPIO out hold time)		0.0	_	0.0	_	ns
492	GPIO In valid to CLKOUT edge (GPIO in set-up time)		8.5	_	8.5	_	ns
493	CLKOUT edge to GPIO in not valid (GPIO in hold time)		0.0	_	0.0	_	ns
494	Fetch to CLKOUT edge before GPIO change	$6.75 \times T_C$	84.4	_	67.5	_	ns
Note:	vite: $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_J = -40 ^{\circ}\text{C}$ to +100 $^{\circ}\text{C}$, $C_L = 50 \text{ pF}$						

DSP56301 Technical Data, Rev. 10

2-48 Freescale Semiconductor



Fetch the instruction MOVE X0,X:(R0); X0 contains the new value of GPIO and R0 contains the address of GPIO data register.

Figure 2-45. GPIO Timing

2.5.11 JTAG Timing

Table 2-25. JTAG Timing

Observatorists 12	All freq	Unit	
Characteristics	Min	Max	Unit
TCK frequency of operation (1/(T _C × 3); maximum 22 MHz)	0.0	22.0	MHz
TCK cycle time in Crystal mode	45.0	_	ns
TCK clock pulse width measured at 1.5 V	20.0	_	ns
TCK rise and fall times	0.0	3.0	ns
Boundary scan input data setup time	5.0	_	ns
Boundary scan input data hold time	24.0	_	ns
TCK low to output data valid	0.0	40.0	ns
TCK low to output high impedance	0.0	40.0	ns
TMS, TDI data setup time	5.0	_	ns
TMS, TDI data hold time	25.0	_	ns
TCK low to TDO data valid	0.0	44.0	ns
TCK low to TDO high impedance	0.0	44.0	ns
TRST assert time	100.0	_	ns
TRST setup time to TCK low	40.0	_	ns
	TCK cycle time in Crystal mode TCK clock pulse width measured at 1.5 V TCK rise and fall times Boundary scan input data setup time Boundary scan input data hold time TCK low to output data valid TCK low to output high impedance TMS, TDI data setup time TMS, TDI data hold time TCK low to TDO data valid TCK low to TDO high impedance	Characteristics 1,2 Min TCK frequency of operation (1/(T _C × 3); maximum 22 MHz) 0.0 TCK cycle time in Crystal mode 45.0 TCK clock pulse width measured at 1.5 V 20.0 TCK rise and fall times 0.0 Boundary scan input data setup time 5.0 Boundary scan input data hold time 24.0 TCK low to output data valid 0.0 TCK low to output high impedance 0.0 TMS, TDI data setup time 5.0 TMS, TDI data hold time 25.0 TCK low to TDO data valid 0.0 TCK low to TDO high impedance 0.0 TCK low to TDO high impedance 0.0 TRST assert time 100.0 TRST setup time to TCK low 40.0	Min Max TCK frequency of operation (1/(T _C × 3); maximum 22 MHz) 0.0 22.0 TCK cycle time in Crystal mode 45.0 — TCK clock pulse width measured at 1.5 V 20.0 — TCK rise and fall times 0.0 3.0 Boundary scan input data setup time 5.0 — Boundary scan input data hold time 24.0 — TCK low to output data valid 0.0 40.0 TCK low to output high impedance 0.0 40.0 TMS, TDI data setup time 5.0 — TCK low to TDO data valid 0.0 44.0 TCK low to TDO high impedance 0.0 44.0 TCK low to TDO high impedance 0.0 44.0 TRST assert time 100.0 — TRST setup time to TCK low 40.0 —

Notes: 1. $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$; $T_J = -40 ^{\circ}\text{C}$ to +100 $^{\circ}\text{C}$, $C_L = 50 \text{ pF}$

2. All timings apply to OnCE module data transfers because it uses the JTAG port as an interface.

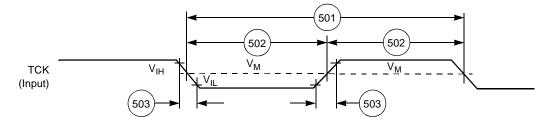


Figure 2-46. Test Clock Input Timing Diagram

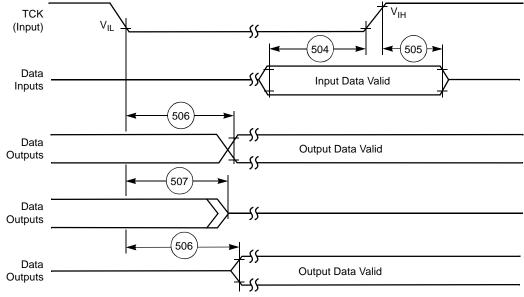


Figure 2-47. Boundary Scan (JTAG) Timing Diagram

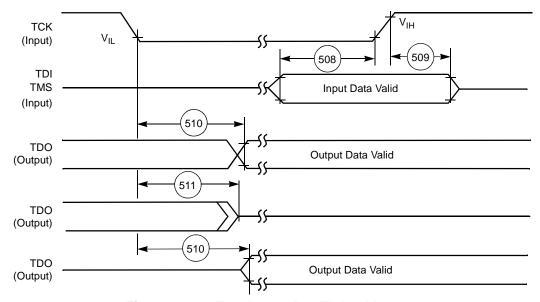


Figure 2-48. Test Access Port Timing Diagram

DSP56301 Technical Data, Rev. 10

2-50 Freescale Semiconductor

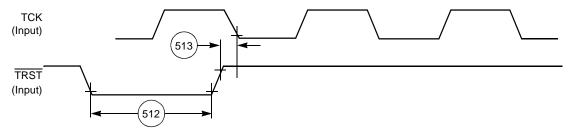


Figure 2-49. TRST Timing Diagram

2.5.12 OnCE Module TimIng

Table 2-26. OnCE Module Timing

No.	Characteristics	5	80 MHz		100	11!	
NO.	Characteristics	Expression	Min	Max	Min	Max	Unit
500	TCK frequency of operation	1/(T _C × 3), max: 22.0 MHz	0.0	22.0	0.0	22.0	MHz
514	DE assertion time in order to enter Debug mode	$1.5 \times T_{C} + 10.0$	28.8	_	25.0	_	ns
515	Response time when DSP56301 is executing NOP instructions from internal memory	$5.5 \times T_{C} + 30.0$	_	98.8	_	85.0	ns
516	Debug acknowledge assertion time	$3 \times T_C - 5.0$	47.5	_	25.0	_	ns
Note:	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}; T_J = -40 ^{\circ}\text{C to } +100 ^{\circ}\text{C}, C_L = 50 \text{ pF}$						



Figure 2-50. OnCE—Debug Request

Specifications

DSP56301 Technical Data, Rev. 10

2-52 Freescale Semiconductor

This section provides information on the available packages for the DSP56301, including diagrams of the package pinouts and tables showing how the signals discussed in **Section 1** are allocated for each package. The DSP56301 is available in two package types:

- 208-pin Thin Quad Flat Pack (TQFP)
- 252-pin Molded Array Process-Ball Grid Array (MAP-BGA)

Note: Both packages are available in lead-bearing and lead-free versions. Switching a design from a lead-bearing package device to a lead-free package device may require a change in the board manufacturing process. The lead-free package requires a higher solder flow temperature than the lead-bearing device. Refer to *Lead-Free BGA Solder Joint Assembly Evaluation* (EB635) for manufacturing considerations when incorporating lead-free package devices into a design.

3.1 TQFP Package Description

Top and bottom views of the TQFP package are shown in Figure 3-1 and Figure 3-2 with their pin-outs.

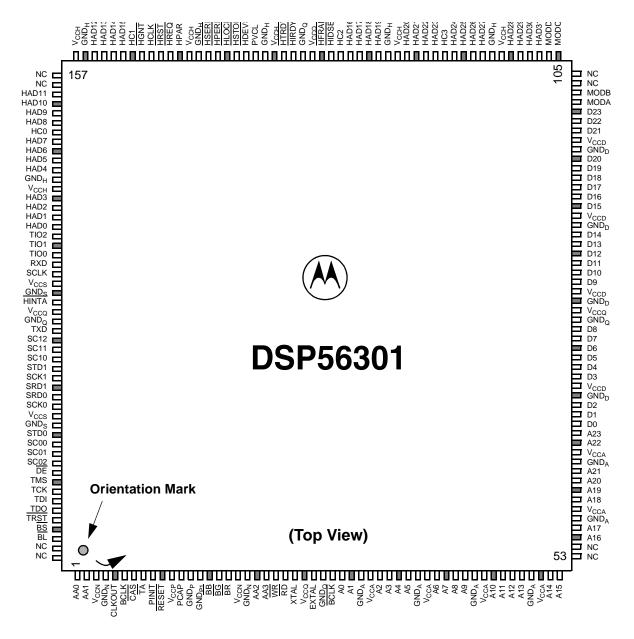


Figure 3-1. DSP56301 Thin Quad Flat Pack (TQFP), Top View

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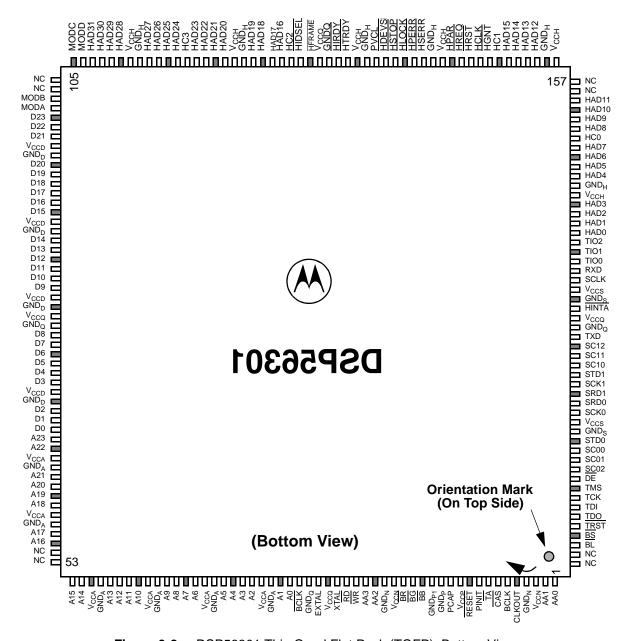


Figure 3-2. DSP56301 Thin Quad Flat Pack (TQFP), Bottom View

 Table 3-1.
 DSP56301 TQFP Signal Identification by Pin Number

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
1	AA0/RAS0	26	EXTAL	51	A14
2	AA1/RAS1	27	GND_Q	52	A15
3	V _{CCN}	28	BCLK	53	NC
4	GND_N	29	A0	54	NC
5	CLKOUT	30	A1	55	A16
6	BCLK	31	GND _A	56	A17
7	CAS	32	V _{CCA}	57	GND _A
8	TA	33	A2	58	V _{CCA}
9	PINIT/NMI	34	A3	59	A18
10	RESET	35	A4	60	A19
11	V _{CCP}	36	A5	61	A20
12	PCAP	37	GND _A	62	A21
13	GND _P	38	V _{CCA}	63	GND _A
14	GND _{P1}	39	A6	64	V _{CCA}
15	BB	40	A7	65	A22
16	BG	41	A8	66	A23
17	BR	42	А9	67	D0
18	V _{CCN}	43	GND _A	68	D1
19	GND_N	44	V _{CCA}	69	D2
20	AA2/RAS2	45	A10	70	GND _D
21	AA3/RAS3	46	A11	71	V _{CCD}
22	WR	47	A12	72	D3
23	RD	48	A13	73	D4
24	XTAL	49	GND _A	74	D5
25	V _{CCQ}	50	V _{CCA}	75	D6

3-4 Freescale Semiconductor

 Table 3-1.
 DSP56301 TQFP Signal Identification by Pin Number (Continued)

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
76	D7	101	MODA/IRQA	126	HAD17 or HD9
77	D8	102	MODB/IRQB	127	HAD16 or HD8
78	GND_Q	103	NC	128	HC2/HBE2, HA2, or PB18
79	V _{CCQ}	104	NC	129	HIDSEL or HRD/HDS
80	GND _D	105	MODC/IRQC	130	HFRAME
81	V _{CCD}	106	MODD/IRQD	131	V _{CCQ}
82	D9	107	HAD31 or HD23	132	GND _Q
83	D10	108	HAD30 or HD22	133	HIRDY, HDBDR, or PB21
84	D11	109	HAD29 or HD21	134	HTRDY, HDBEN, or PB20
85	D12	110	HAD28 or HD20	135	V _{CCH}
86	D13	111	V _{CCH}	136	GND _H
87	D14	112	GND _H	137	PVCL
88	GND _D	113	HAD27 or HD19	138	HDEVSEL, HSAK, or PB22
89	V _{CCD}	114	HAD26 or HD18	139	HSTOP or HWR/HRW
90	D15	115	HAD25 or HD17	140	HLOCK, HBS, or PB23
91	D16	116	HAD24 or HD16	141	HPERR or HDRQ
92	D17	117	HC3/HBE3 or PB19	142	HSERR or HIRQ
93	D18	118	HAD23 or HD15	143	GND _H
94	D19	119	HAD22 or HD14	144	V _{CCH}
95	D20	120	HAD21 or HD13	145	HPAR or HDAK
96	GND _D	121	HAD20 or HD12	146	HREQ or HTA
97	V _{CCD}	122	V _{CCH}	147	HRST or HRST
98	D21	123	GND _H	148	HCLK
99	D22	124	HAD19 or HD11	149	HGNT or HAEN
100	D23	125	HAD18 or HD10	150	HC1/HBE1, HA1, or PB17

Table 3-1. DSP56301 TQFP Signal Identification by Pin Number (Continued)

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
151	HAD15, HD7, or PB15	171	HAD2, HA5, or PB2	191	SRD0 or PC4
152	HAD14, HD6, or PB14	172	HAD1, HA4, or PB1	192	SCK0 or PC3
153	HAD13, HD5, or PB13	173	HAD0, HA3, or PB0	193	V _{CCS}
154	HAD12, HD4, or PB12	174	TIO2	194	GND _S
155	GND _H	175	TIO1	195	STD0 or PC5
156	V _{CCH}	176	TIO0	196	SC00 or PC0
157	NC	177	RXD or PE0	197	SC01 or PC1
158	NC	178	SCLK or PE2	198	SC02 or PC2
159	HAD11, HD3, or PB11	179	V _{CCS}	199	DE
160	HAD10, HD2, or PB10	180	GND _S	200	TMS
161	HAD9, HD1, or PB9	181	HINTA	201	TCK
162	HAD8, HD0, or PB8	182	V _{CCQ}	202	TDI
163	HC0/HBE0, HA0, or PB16	183	GND_Q	203	TDO
164	HAD7, HA10, or PB7	184	TXD or PE1	204	TRST
165	HAD6, HA9, or PB6	185	SC12 or PD2	205	BS
166	HAD5, HA8, or PB5	186	SC11 or PD1	206	BL
167	HAD4, HA7, or PB4	187	SC10 or PD0	207	NC
168	GND _H	188	STD1 or PD5	208	NC
169	V _{CCH}	189	SCK1 or PD3		
170	HAD3, HA6, or PB3	190	SRD1 or PD4	1	

Notes:

3-6 Freescale Semiconductor

^{1.} Signal names are based on configured functionality. Most pins supply a single signal. Some pins provide a signal with dual functionality, such as the MODx/IRQx pins that select an operating mode after RESET is deasserted, but act as interrupt lines during operation. Some pins have two or more configurable functions; names assigned to these pins indicate the function for a specific configuration. For example, Pin 165 is address/data line HAD6 in PCI bus mode, address line HA9 in non-PCI bus mode, or GPIO line PB6 when the GPIO function is enabled for this pin.

^{2.} NC stands for Not Connected. These pins are reserved for future development. Do not connect any line, component, trace, or via to these pins.

 Table 3-2.
 DSP56301 TQFP Signal Identification by Name

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
A0	29	AA3	21	D3	72
A1	30	BB	15	D4	73
A10	45	BCLK	6	D5	74
A11	46	BCLK	28	D6	75
A12	47	BG	16	D7	76
A13	48	BL	206	D8	77
A14	51	BR	17	D9	82
A15	52	BS	205	DE	199
A16	55	CAS	7	EXTAL	26
A17	56	CLKOUT	5	GND _{P1}	14
A18	59	D0	67	GND _A	31
A19	60	D1	68	GND _A	37
A2	33	D10	83	GND _A	43
A20	61	D11	84	GND _A	49
A21	62	D12	85	GND _A	57
A22	65	D13	86	GND _A	63
A23	66	D14	87	GND _D	70
A3	34	D15	90	GND _D	80
A4	35	D16	91	GND _D	88
A5	36	D17	92	GND _D	96
A6	39	D18	93	GND _H	112
A7	40	D19	94	GND _H	123
A8	41	D2	69	GND _H	136
A9	42	D20	95	GND _H	143
AA0	1	D21	98	GND _H	155
AA1	2	D22	99	GND _H	168
AA2	20	D23	100	GND _N	4

 Table 3-2.
 DSP56301 TQFP Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
GND _N	19	HAD14	152	HAEN	149
GND _P	13	HAD15	151	HBE0	163
GND_Q	27	HAD16	127	HBE1	150
GND_Q	78	HAD17	126	HBE2	128
GND_Q	132	HAD18	125	HBE3	117
GND_Q	183	HAD19	124	HBS	140
GND_Q	183	HAD2	171	HC0	163
GND _S	180	HAD20	121	HC1	150
GND _S	194	HAD21	120	HC2	128
HA0	163	HAD22	119	HC3	117
HA1	150	HAD23	118	HCLK	148
HA10	164	HAD24	116	HD0	162
HA2	128	HAD25	115	HD1	161
HA3	173	HAD26	114	HD10	125
HA4	172	HAD27	113	HD11	124
HA5	171	HAD28	110	HD12	121
HA6	170	HAD29	109	HD13	120
HA7	167	HAD3	170	HD14	119
HA8	166	HAD30	108	HD15	118
HA9	165	HAD31	107	HD16	116
HAD0	173	HAD4	167	HD17	115
HAD1	172	HAD5	166	HD18	114
HAD10	160	HAD6	165	HD19	113
HAD11	159	HAD7	164	HD2	160
HAD12	154	HAD8	162	HD20	110
HAD13	153	HAD9	161	HD21	109

3-8 Freescale Semiconductor

 Table 3-2.
 DSP56301 TQFP Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
HD22	108	HRST/HRST	147	PB0	173
HD23	107	HRW	139	PB1	172
HD3	159	HSAK	138	PB10	160
HD4	154	HSERR	142	PB11	159
HD5	153	HSTOP	139	PB12	154
HD6	152	HTA	146	PB13	153
HD7	151	HTRDY	134	PB14	152
HD8	127	HWR	139	PB15	151
HD9	126	ĪRQĀ	101	PB16	163
HDAK	145	ĪRQB	102	PB17	150
HDBDR	133	ĪRQC	105	PB18	128
HDBEN	134	ĪRQD	106	PB19	117
HDEVSEL	138	MODA	101	PB2	171
HDRQ	141	MODB	102	PB20	134
HDS	129	MODC	105	PB21	133
HFRAME	130	MODD	106	PB22	138
HGNT	149	NC	28	PB23	140
HIDSEL	129	NC	53	PB3	170
HINTA	181	NC	54	PB4	167
HIRDY	133	NC	103	PB5	166
HIRQ	142	NC	104	PB6	165
HLOCK	140	NC	157	PB7	164
HPAR	145	NC	158	PB8	162
HPERR	141	NC	207	PB9	161
HRD	129	NC	208	PC0	196
HREQ	146	NMI	9	PC1	197

Table 3-2. DSP56301 TQFP Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
PC2	198	SC02	198	V _{CCA}	58
PC3	192	SC10	187	V _{CCA}	64
PC4	191	SC11	186	V _{CCD}	71
PC5	195	SC12	185	V _{CCD}	81
PCAP	12	SCK0	192	V _{CCD}	89
PD0	187	SCK1	189	V _{CCD}	97
PD1	186	SCLK	178	V _{CCH}	111
PD2	185	SRD0	191	V _{CCH}	122
PD3	189	SRD1	190	V _{CCH}	135
PD4	190	STD0	195	V _{CCH}	144
PD5	188	STD1	188	V _{CCH}	156
PE0	177	TA	8	V _{CCH}	169
PE1	184	TCK	201	V _{CCN}	3
PE2	178	TDI	202	V _{CCN}	18
PINIT	9	TDO	203	V _{CCP}	11
PVCL	137	TIO0	176	V _{CCQ}	25
RAS0	1	TIO1	175	V _{CCQ}	79
RAS1	2	TIO2	174	V _{CCQ}	131
RAS2	20	TMS	200	V _{CCQ}	182
RAS3	21	TRST	204	V _{CCS}	179
RD	23	TXD	184	V _{CCS}	193
RESET	10	V _{CCA}	32	WR	22
RXD	177	V _{CCA}	38	XTAL	24
SC00	196	V _{CCA}	44		
SC01	197	V _{CCA}	50		

Note: NC stands for Not Connected. These pins are reserved for future development. Do not connect any line, component, or trace to these pins.

3.2 TQFP Package Mechanical Drawing

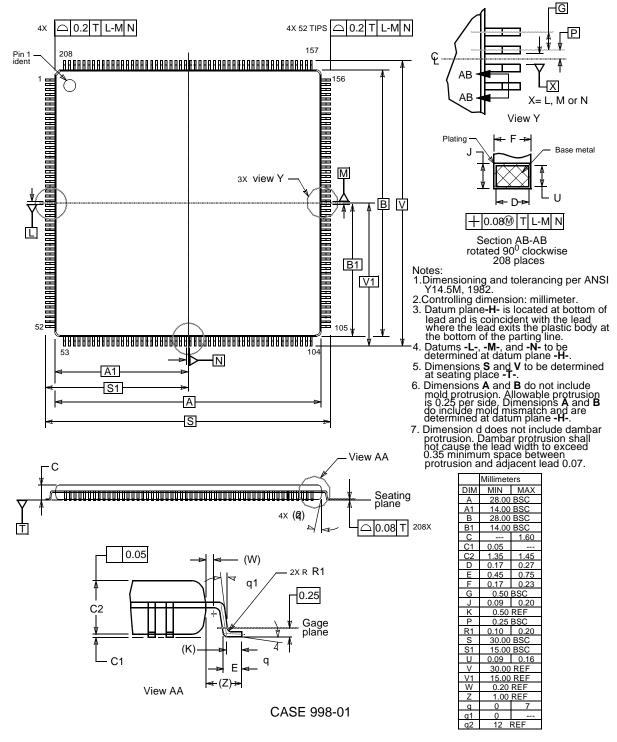


Figure 3-3. DSP56301 Mechanical Information, 208-pin TQFP Package

3.3 MAP-BGA Package Description

Top and bottom views of the MAP-BGA package are shown in Figure 3-4 and Figure 3-5 with their pin-outs.

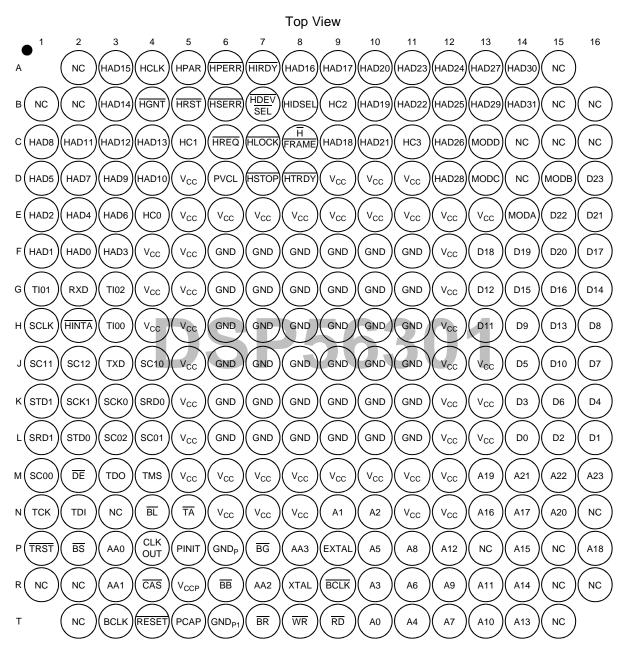


Figure 3-4. DSP56301 Molded Array Process-Ball Grid Array (MAP-BGA), Top View

DSP56301 Technical Data, Rev. 10

3-12 Freescale Semiconductor

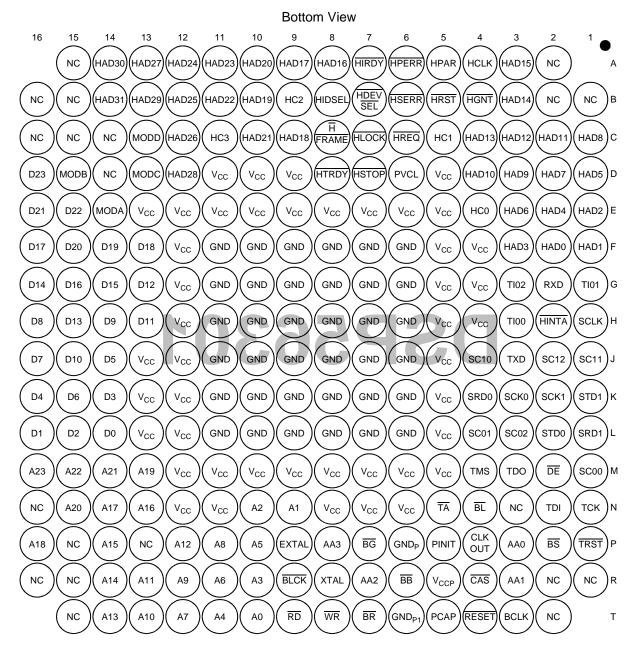


Figure 3-5. DSP56301 Molded Array Process-Ball Grid Array (MAP-BGA), Bottom View

 Table 3-3.
 DSP56301 MAP-BGA Signal Identification by Pin Number

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
A2	NC	B12	HAD25 or HD17	D5	V _{CC}
А3	HAD15, HD7, or PB15	B13	HAD29 or HD21	D6	PVCL
A4	HCLK	B14	HAD31 or HD23	D7	HSTOP or HWR/HRW
A5	HPAR or HDAK	B15	NC	D8	HTRDY, HDBEN, or PB20
A6	HPERR or HDRQ	B16	NC	D9	V _{CC}
A7	HIRDY, HDBDR, or PB21	C1	HAD8, HD0, or PB8	D10	V _{CC}
A8	HAD16 or HD8	C2	HAD11, HD3, or PB11	D11	V _{CC}
A9	HAD17 or HD9	C3	HAD12, HD4, or PB12	D12	HAD28 or HD20
A10	HAD20 or HD12	C4	HAD13, HD5, or PB13	D13	MODC/IRQC
A11	HAD23 or HD15	C5	HC1/HBE1, HA1, or PB17	D14	NC
A12	HAD24 or HD16	C6	HREQ or HTA	D15	MODB/IRQB
A13	HAD27 or HD19	C7	HLOCK, HBS, or PB23	D16	D23
A14	HAD30 or HD22	C8	HFRAME	E1	HAD2, HA5, or PB2
A15	NC	C9	HAD18 or HD10	E2	HAD4, HA7, or PB4
B1	NC	C10	HAD21 or HD13	E3	HAD6, HA9, or PB6
B2	NC	C11	HC3/HBE3 or PB19	E4	HC0/HBE0, HA0, or PB16
В3	HAD14, HD6, or PB14	C12	HAD26 or HD18	E5	V _{CC}
B4	HGNT or HAEN	C13	MODD/IRQD	E6	V _{CC}
B5	HRST/HRST	C14	NC	E7	V _{CC}
В6	HSERR or HIRQ	C15	NC	E8	V _{CC}
B7	HDEVSEL, HSAK, or PB22	C16	NC	E9	V _{CC}
B8	HIDSEL or HRD/HDS	D1	HAD5, HA8, or PB5	E10	V _{CC}
В9	HC2/HBE2, HA2, or PB18	D2	HAD7, HA10, or PB7	E11	V _{CC}
B10	HAD19 or HD11	D3	HAD9, HD1, or PB9	E12	V _{CC}
B11	HAD22 or HD14	D4	HAD10, HD2, or PB10	E13	V _{CC}

3-14 Freescale Semiconductor

 Table 3-3.
 DSP56301 MAP-BGA Signal Identification by Pin Number (Continued)

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
E14	MODA/IRQA	G7	GND	H16	D8
E15	D22	G8	GND	J1	SC11 or PD1
E16	D21	G9	GND	J2	SC12 or PD2
F1	HAD1, HA4, or PB1	G10	GND	J3	TXD or PE1
F2	HAD0, HA3, or PB0	G11	GND	J4	SC10 or PD0
F3	HAD3, HA6, or PB3	G12	V _{CC}	J5	V _{CC}
F4	V _{CC}	G13	D12	J6	GND
F5	V _{CC}	G14	D15	J7	GND
F6	GND	G15	D16	J8	GND
F7	GND	G16	D14	J9	GND
F8	GND	H1	SCLK or PE2	J10	GND
F9	GND	H2	HINTA	J11	GND
F10	GND	Н3	TIO0	J12	V _{CC}
F11	GND	H4	V _{CC}	J13	V _{CC}
F12	V _{CC}	H5	V _{CC}	J14	D5
F13	D18	H6	GND	J15	D10
F14	D19	H7	GND	J16	D7
F15	D20	H8	GND	K1	STD1 or PD5
F16	D17	Н9	GND	K2	SCK1 or PD3
G1	TIO1	H10	GND	К3	SCK0 or PC3
G2	RXD or PE0	H11	GND	K4	SRD0 or PC4
G3	TIO2	H12	V _{CC}	K5	V _{CC}
G4	V _{CC}	H13	D11	K6	GND
G5	V _{CC}	H14	D9	K7	GND
G6	GND	H15	D13	K8	GND

 Table 3-3.
 DSP56301 MAP-BGA Signal Identification by Pin Number (Continued)

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
K9	GND	M2	DE	N11	V _{CC}
K10	GND	M3	TDO	N12	V _{CC}
K11	GND	M4	TMS	N13	A16
K12	V _{CC}	M5	V _{CC}	N14	A17
K13	V _{CC}	M6	V _{CC}	N15	A20
K14	D3	M7	V _{CC}	N16	NC
K15	D6	M8	V _{CC}	P1	TRST
K16	D4	M9	V _{CC}	P2	BS
L1	SRD1 or PD4	M10	V _{CC}	P3	AA0/RAS0
L2	STD0 or PC5	M11	V _{CC}	P4	CLKOUT
L3	SC02 or PC2	M12	V _{CC}	P5	PINIT/NMI
L4	SC01 or PC1	M13	A19	P6	GND _P
L5	V _{CC}	M14	A21	P7	BG
L6	GND	M15	A22	P8	AA3/RAS3
L7	GND	M16	A23	P9	EXTAL
L8	GND	N1	TCK	P10	A5
L9	GND	N2	TDI	P11	A8
L10	GND	N3	NC	P12	A12
L11	GND	N4	BL	P13	NC
L12	V _{CC}	N5	TA	P14	A15
L13	V _{CC}	N6	V _{CC}	P15	NC
L14	D0	N7	V _{CC}	P16	A18
L15	D2	N8	V _{CC}	R1	NC
L16	D1	N9	A1	R2	NC
M1	SC00 or PC0	N10	A2	R3	AA1/RAS1

3-16 Freescale Semiconductor

3-17

Table 3-3. DSP56301 MAP-BGA Signal Identification by Pin Number (Continued)

Pin No.	Signal Name	Pin No.	Signal Name	Pin No.	Signal Name
R4	CAS	R13	A11	T7	BR
R5	V _{CCP}	R14	A14	T8	WR
R6	BB	R15	NC	Т9	RD
R7	AA2/RAS2	R16	NC	T10	A0
R8	XTAL	T2	NC	T11	A4
R9	BCLK	Т3	BCLK	T12	A7
R10	А3	T4	RESET	T13	A10
R11	A6	T5	PCAP	T14	A13
R12	A9	Т6	GND _{P1}	T15	NC

Notes:

- Signal names are based on configured functionality. Most connections supply a single signal. Some connections provide a signal with dual functionality, such as the MODx/IRQx pins that select an operating mode after RESET is deasserted, but act as interrupt lines during operation. Some signals have configurable polarity; these names are shown with and without overbars, such as HAS/HAS. Some connections have two or more configurable functions; names assigned to these connections indicate the function for a specific configuration. For example, connection N2 is data line H7 in non-multiplexed bus mode, data/address line HAD7 in multiplexed bus mode, or GPIO line PB7 when the GPIO function is enabled for this pin. Unlike the TQFP package, most of the GND pins are connected internally in the center of the connection array and act as heat sink for the chip. Therefore, except for GND_P and GND_{P1} that support the PLL, other GND signals do not support individual subsystems in the chip.
- 2. NC stands for Not Connected. The following pin groups are shorted to each other:
 - pins A2, B1, and B2
 - pins A15, B15, B16, C14, C15, C16, and D14
 - pins N3, R1, R2, and T2
 - pins N16, P13, P15, R15, R16, and T15

Do not connect any line, component, trace, or via to these pins.

 Table 3-4.
 DSP56301 MAP-BGA Signal Identification by Name

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
A0	T10	AA2	R7	D22	E15
A1	N9	AA3	P8	D23	D16
A10	T13	BB	R6	D3	K14
A11	R13	BCLK	Т3	D4	K16
A12	P12	BCLK	R9	D5	J14
A13	T14	BG	P7	D6	K15
A14	R14	BL	N4	D7	J16
A15	P14	BR	T7	D8	H16
A16	N13	BS	P2	D9	H14
A17	N14	CAS	R4	DE	M2
A18	P16	CLKOUT	P4	EXTAL	P9
A19	M13	D0	L14	GND	F10
A2	N10	D1	L16	GND	F11
A20	N15	D10	J15	GND	F6
A21	M14	D11	H13	GND	F7
A22	M15	D12	G13	GND	F8
A23	M16	D13	H15	GND	F9
А3	R10	D14	G16	GND	G10
A4	T11	D15	G14	GND	G11
A5	P10	D16	G15	GND	G6
A6	R11	D17	F16	GND	G7
A7	T12	D18	F13	GND	G8
A8	P11	D19	F14	GND	G9
A9	R12	D2	L15	GND	H10
AA0	P3	D20	F15	GND	H11
AA1	R3	D21	E16	GND	H6

 Table 3-4.
 DSP56301 MAP-BGA Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
GND	H7	HA10	D2	HAD23	A11
GND	H8	HA2	В9	HAD24	A12
GND	H9	HA3	F2	HAD25	B12
GND	J10	HA4	F1	HAD26	C12
GND	J11	HA5	E1	HAD27	A13
GND	J6	HA6	F3	HAD28	D12
GND	J7	HA7	E2	HAD29	B13
GND	J8	HA8	D1	HAD3	F3
GND	J9	HA9	E3	HAD30	A14
GND	K10	HAD0	F2	HAD31	B14
GND	K11	HAD1	F1	HAD4	E2
GND	K6	HAD10	D4	HAD5	D1
GND	K7	HAD11	C2	HAD6	E3
GND	K8	HAD12	C3	HAD7	D2
GND	K9	HAD13	C4	HAD8	C1
GND	L10	HAD14	В3	HAD9	D3
GND	L11	HAD15	А3	HAEN	B4
GND	L6	HAD16	A8	HBE0	E4
GND	L7	HAD17	A9	HBE1	C5
GND	L8	HAD18	C9	HBE2	В9
GND	L9	HAD19	B10	HBE3	C11
GND _{P1}	Т6	HAD2	E1	HBS	C7
GND _P	P6	HAD20	A10	HC0	E4
HA0	E4	HAD21	C10	HC1	C5
HA1	C5	HAD22	B11	HC2	В9

 Table 3-4.
 DSP56301 MAP-BGA Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
HC3	C11	HD9	A9	HWR	D7
HCLK	A4	HDAK	A5	ĪRQĀ	E14
HD0	C1	HDBDR	A7	ĪRQB	D15
HD1	D3	HDBEN	D8	ĪRQC	D13
HD10	C9	HDEVSEL	B7	ĪRQD	C13
HD11	B10	HDRQ	A6	MODA	E14
HD12	A10	HDS	B8	MODB	D15
HD13	C10	HFRAME	C8	MODC	D13
HD14	B11	HGNT	B4	MODD	C13
HD15	A11	HIDSEL	B8	NC	A15
HD16	A12	HINTA	H2	NC	A2
HD17	B12	HIRDY	A7	NC	B1
HD18	C12	HIRQ	В6	NC	B15
HD19	A13	HLOCK	C7	NC	B16
HD2	D4	HPAR	A5	NC	B2
HD20	D12	HPERR	A6	NC	C14
HD21	B13	HRD	B8	NC	C15
HD22	A14	HREQ	C6	NC	C16
HD23	B14	HRST/HRST	B5	NC	D14
HD3	C2	HRW	D7	NC	N16
HD4	С3	HSAK	B7	NC	N3
HD5	C4	HSERR	В6	NC	P13
HD6	В3	HSTOP	D7	NC	P15
HD7	А3	HTA	C6	NC	R1
HD8	A8	HTRDY	D8	NC	R2

3-20 Freescale Semiconductor

 Table 3-4.
 DSP56301 MAP-BGA Signal Identification by Name (Continued)

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
NC	R15	PB6	E3	RAS3	P8
NC	R16	PB7	D2	RD	Т9
NC	T2	PB8	C1	RESET	T4
NC	T15	PB9	D3	RXD	G2
NMI	P5	PC0	M1	SC00	M1
PB0	F2	PC1	L4	SC01	L4
PB1	F1	PC2	L3	SC02	L3
PB10	D4	PC3	K3	SC10	J4
PB11	C2	PC4	K4	SC11	J1
PB12	C3	PC5	L2	SC12	J2
PB13	C4	PCAP	T5	SCK0	К3
PB14	В3	PD0	J4	SCK1	K2
PB15	А3	PD1	J1	SCLK	H1
PB16	E4	PD2	J2	SRD0	K4
PB17	C5	PD3	K2	SRD1	L1
PB18	В9	PD4	L1	STD0	L2
PB19	C11	PD5	K1	STD1	K1
PB2	E1	PE0	G2	TA	N5
PB20	D8	PE1	J3	TCK	N1
PB21	A7	PE2	H1	TDI	N2
PB22	В7	PINIT	P5	TDO	МЗ
PB23	C7	PVCL	D6	TIO0	НЗ
PB3	F3	RAS0	P3	TIO1	G1
PB4	E2	RAS1	R3	TIO2	G3
PB5	D1	RAS2	R7	TMS	M4

DSP56301 MAP-BGA Signal Identification by Name (Continued) **Table 3-4.**

Signal Name	Pin No.	Signal Name	Pin No.	Signal Name	Pin No.
TRST	P1	V _{CC}	F5	V _{CC}	M10
TXD	J3	V _{CC}	G12	V _{CC}	M11
V _{CC}	D10	V _{CC}	G4	V _{CC}	M12
V _{CC}	D11	V _{CC}	G5	V _{CC}	M5
V _{CC}	D5	V _{CC}	H12	V _{CC}	M6
V _{CC}	D9	V _{CC}	H4	V _{CC}	M7
V _{CC}	E10	V _{CC}	H5	V _{CC}	M8
V _{CC}	E11	V _{CC}	J12	V _{CC}	M9
V _{CC}	E12	V _{CC}	J13	V _{CC}	N11
V _{CC}	E13	V _{CC}	J5	V _{CC}	N12
V _{CC}	E5	V _{CC}	K12	V _{CC}	N6
V _{CC}	E6	V _{CC}	K13	V _{CC}	N7
V _{CC}	E7	V _{CC}	K5	V _{CC}	N8
V _{CC}	E8	V _{CC}	L12	V _{CCP}	R5
V _{CC}	E9	V _{CC}	L13	WR	Т8
V _{CC}	F12	V _{CC}	L5	XTAL	R8
V _{CC}	F4				

Note: NC stands for Not Connected. The following pin groups are shorted to each other:

⁻pins A2, B1, and B2

⁻pins A15, B15, B16, C14, C15, C16, and D14

[—]pins N3, R1, R2, and T2

[—]pins N16, P13, P15, R15, R16, and T15
Do not connect any line, component, trace, or via to these pins.

3.4 MAP-BGA Package Mechanical Drawing

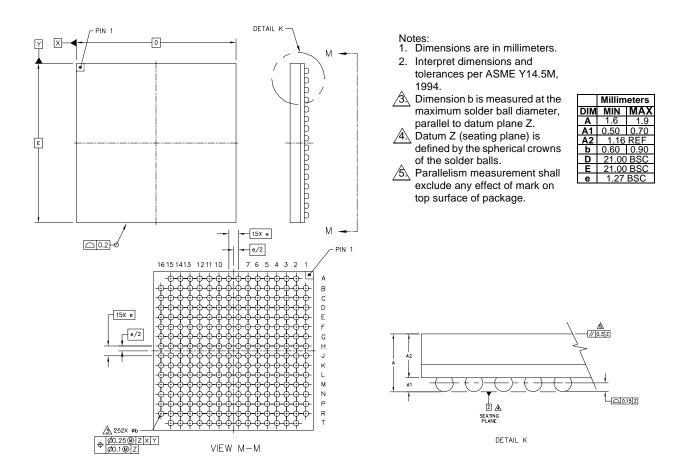


Figure 3-6. DSP56301 Mechanical Information, 252-pin MAP-BGA Package

DSP56301 Technical Data, Rev. 10

Design Considerations

4

4.1 Thermal Design Considerations

An estimate of the chip junction temperature, T_J, in °C can be obtained from this equation:

Equation 1:
$$T_I = T_A + (P_D \times R_{\theta IA})$$

Where:

 T_A = ambient temperature ${}^{\circ}C$

 $R_{\theta IA}$ = package junction-to-ambient thermal resistance °C/W

 P_D = power dissipation in package

Historically, thermal resistance has been expressed as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance, as in this equation:

Equation 2:
$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

Where:

 $R_{\theta JA}$ = package junction-to-ambient thermal resistance °C/W $R_{\theta JC}$ = package junction-to-case thermal resistance °C/W $R_{\theta CA}$ = package case-to-ambient thermal resistance °C/W

 $R_{\theta JC}$ is device-related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For example, the user can change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board (PCB) or otherwise change the thermal dissipation capability of the area surrounding the device on a PCB. This model is most useful for ceramic packages with heat sinks; some 90 percent of the heat flow is dissipated through the case to the heat sink and out to the ambient environment. For ceramic packages, in situations where the heat flow is split between a path to the case and an alternate path through the PCB, analysis of the device thermal performance may need the additional modeling capability of a system-level thermal simulation tool.

The thermal performance of plastic packages is more dependent on the temperature of the PCB to which the package is mounted. Again, if the estimates obtained from $R_{\theta JA}$ do not satisfactorily answer whether the thermal performance is adequate, a system-level model may be appropriate.

A complicating factor is the existence of three common ways to determine the junction-to-case thermal resistance in plastic packages.

- To minimize temperature variation across the surface, the thermal resistance is measured from the junction to the outside surface of the package (case) closest to the chip mounting area when that surface has a proper heat sink.
- To define a value approximately equal to a junction-to-board thermal resistance, the thermal resistance is measured from the junction to the point at which the leads attach to the case.

Design Considerations

• If the temperature of the package case (T_T) is determined by a thermocouple, thermal resistance is computed from the value obtained by the equation $(T_I - T_T)/P_D$.

As noted earlier, the junction-to-case thermal resistances quoted in this data sheet are determined using the first definition. From a practical standpoint, that value is also suitable to determine the junction temperature from a case thermocouple reading in forced convection environments. In natural convection, the use of the junction-to-case thermal resistance to estimate junction temperature from a thermocouple reading on the case of the package will yield an estimate of a junction temperature slightly higher than actual temperature. Hence, the new thermal metric, thermal characterization parameter or Ψ_{JT} , has been defined to be $(T_J - T_T)/P_D$. This value gives a better estimate of the junction temperature in natural convection when the surface temperature of the package is used. Remember that surface temperature readings of packages are subject to significant errors caused by inadequate attachment of the sensor to the surface and to errors caused by heat loss to the sensor. The recommended technique is to attach a 40-gauge thermocouple wire and bead to the top center of the package with thermally conductive epoxy.

4.2 Electrical Design Considerations

CAUTION

This device contains protective circuitry to guard against damage due to high static voltage or electrical fields. However, normal precautions are advised to avoid application of any voltages higher than maximum rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{CC}).

Use the following list of recommendations to ensure correct DSP operation.

- Provide a low-impedance path from the board power supply to each V_{CC} pin on the DSP and from the board ground to each GND pin.
- Use at least six 0.01– $0.1~\mu F$ bypass capacitors positioned as close as possible to the four sides of the package to connect the V_{CC} power source to GND.
- Ensure that capacitor leads and associated printed circuit traces that connect to the chip V_{CC} and GND pins are less than 0.5 inch per capacitor lead.
- Use at least a four-layer PCB with two inner layers for V_{CC} and GND.
- Because the DSP output signals have fast rise and fall times, PCB trace lengths should be minimal. This recommendation particularly applies to the address and data buses as well as the IRQA, IRQB, IRQC, IRQD, TA, and BG pins. Maximum PCB trace lengths on the order of 6 inches are recommended.
- Consider all device loads as well as parasitic capacitance due to PCB traces when you calculate
 capacitance. This is especially critical in systems with higher capacitive loads that could create higher
 transient currents in the V_{CC} and GND circuits.
- All inputs must be terminated (that is, not allowed to float) by CMOS levels except for the three pins with internal pull-up resistors (TRST, TMS, DE).
- Take special care to minimize noise levels on the V_{CCP}, GND_P, and GND_{P1} pins.
- The following pins must be asserted after power-up: RESET and TRST.

DSP56301 Technical Data, Rev. 10

- If multiple DSP devices are on the same board, check for cross-talk or excessive spikes on the supplies due to synchronous operation of the devices.
- RESET must be asserted when the chip is powered up. A stable EXTAL signal should be supplied before deassertion of RESET.
- At power-up, ensure that the voltage difference between the 5 V tolerant pins and the chip V_{CC} never exceeds 3.5 V.

4.3 Power Consumption Considerations

Power dissipation is a key issue in portable DSP applications. Some of the factors affecting current consumption are described in this section. Most of the current consumed by CMOS devices is alternating current (ac), which is charging and discharging the capacitances of the pins and internal nodes.

Current consumption is described by this formula:

Equation 3:
$$I = C \times V \times f$$

Where:

C = node/pin capacitance

V = voltage swing

f = frequency of node/pin toggle

Example 1. Current Consumption

For a Port A address pin loaded with 50 pF capacitance, operating at 3.3 V, with a 66 MHz clock, toggling at its maximum possible rate (33 MHz), the current consumption is expressed in **Equation 4**.

Equation 4:
$$I = 50 \times 10^{-12} \times 3.3 \times 33 \times 10^{6} = 5.48 \text{ mA}$$

The maximum internal current (I_{CCI} max) value reflects the typical possible switching of the internal buses on best-case operation conditions—not necessarily a real application case. The typical internal current (I_{CCItyp}) value reflects the average switching of the internal buses on typical operating conditions. Perform the following steps for applications that require very low current consumption:

- 1. Set the EBD bit when you are not accessing external memory.
- 2. Minimize external memory accesses, and use internal memory accesses.
- **3.** Minimize the number of pins that are switching.
- **4.** Minimize the capacitive load on the pins.
- **5.** Connect the unused inputs to pull-up or pull-down resistors.
- **6.** Disable unused peripherals.
- 7. Disable unused pin activity (for example, CLKOUT, XTAL).

One way to evaluate power consumption is to use a current-per-MIPS measurement methodology to minimize specific board effects (that is, to compensate for measured board current not caused by the DSP). A benchmark power consumption test algorithm is listed in **Appendix A**. Use the test algorithm, specific test current measurements, and the following equation to derive the current-per-MIPS value.

Design Considerations

Equation 5:
$$I/MIPS = I/MHz = (I_{typF2} - I_{typF1})/(F2 - F1)$$

Where:

 I_{typF2} = current at F2 I_{typF1} = current at F1

F2 = high frequency (any specified operating frequency)

F1 = low frequency (any specified operating frequency lower than F2)

Note: F1 should be significantly less than F2. For example, F2 could be 66 MHz and F1 could be 33 MHz. The degree of difference between F1 and F2 determines the amount of precision with which the current rating can be determined for an application.

4.4 PLL Performance Issues

The following explanations should be considered as general observations on expected PLL behavior. There is no test that replicates these exact numbers. These observations were measured on a limited number of parts and were not verified over the entire temperature and voltage ranges.

4.4.1 Phase Skew Performance

The phase skew of the PLL is defined as the time difference between the falling edges of EXTAL and CLKOUT for a given capacitive load on CLKOUT, over the entire process, temperature and voltage ranges. As defined in **Figure 2-2**, *External Clock Timing*, on page -5 for input frequencies greater than 15 MHz and the MF \leq 4, this skew is greater than or equal to 0.0 ns and less than 1.8 ns; otherwise, this skew is not guaranteed. However, for MF < 10 and input frequencies greater than 10 MHz, this skew is between -1.4 ns and +3.2 ns.

4.4.2 Phase Jitter Performance

The phase jitter of the PLL is defined as the variations in the skew between the falling edges of EXTAL and CLKOUT for a given device in specific temperature, voltage, input frequency, MF, and capacitive load on CLKOUT. These variations are a result of the PLL locking mechanism. For input frequencies greater than 15 MHz and MF \leq 4, this jitter is less than \pm 0.6 ns; otherwise, this jitter is not guaranteed. However, for MF < 10 and input frequencies greater than 10 MHz, this jitter is less than \pm 2 ns.

4.4.3 Frequency Jitter Performance

The frequency jitter of the PLL is defined as the variation of the frequency of CLKOUT. For small MF (MF < 10) this jitter is smaller than 0.5 per cent. For mid-range MF (10 < MF < 500) this jitter is between 0.5 per cent and approximately 2 per cent. For large MF (MF > 500), the frequency jitter is 2–3 per cent.

4.5 Input (EXTAL) Jitter Requirements

The allowed jitter on the frequency of EXTAL is 0.5 percent. If the rate of change of the frequency of EXTAL is slow (that is, it does not jump between the minimum and maximum values in one cycle) or the frequency of the jitter is fast (that is, it does not stay at an extreme value for a long time), then the allowed jitter can be 2 percent. The phase and frequency jitter performance results are valid only if the input jitter is less than the prescribed values.

4-4 Freescale Semiconductor

Power Consumption Benchmark



The following benchmark program permits evaluation of DSP power usage in a test situation. It enables the PLL, disables the external clock, and uses repeated multiply-accumulate (MAC) instructions with a set of synthetic DSP application data to emulate intensive sustained DSP operation.

```
******************
;* CHECKS Typical Power Consumption
;*
      page 200,55,0,0,0
      nolist
I VEC EQU$000000; Interrupt vectors for program debug only
START EQU$8000; MAIN (external) program starting address
INT_PROG EQU$100 ; INTERNAL program memory starting address
INT XDAT EQU$0 ; INTERNAL X-data memory starting address
INT_YDAT EQU$0 ; INTERNAL Y-data memory starting address
       INCLUDE "ioequ.asm"
      INCLUDE "intequ.asm"
      list
      org
             P:START
      movep #$0123FF,x:M_BCR; BCR: Area 3 : 1 w.s (SRAM)
; Area 2 : 0 w.s (SSRAM)
; Default: 1 w.s (SRAM)
      movep #$0d0000,x:M PCTL; XTAL disable
; PLL enable
; CLKOUT disable
;Load the program
      move
             #INT PROG, r0
      move
             #PROG START, r1
      do
             #(PROG_END-PROG_START),PLOAD_LOOP
             p:(r1)+,x0
      move
      move
             x0,p:(r0)+
      nop
PLOAD LOOP
; Load the X-data
             #INT XDAT, r0
      move
             #XDAT_START, r1
      move
```

DSP56301 Technical Data, Rev. 10

Power Consumption Benchmark

```
#(XDAT END-XDAT START),XLOAD LOOP
               p:(r1)+,x0
       move
       move
               x0, x: (r0) +
XLOAD LOOP
;Load the Y-data
       move
               #INT YDAT, r0
       move
               #YDAT START, r1
       do
               #(YDAT END-YDAT START),YLOAD LOOP
               p:(r1)+,x0
       move
               x0,y:(r0)+
       move
YLOAD LOOP
               INT PROG
       jmp
PROG_START
               #$0,r0
       move
               #$0,r4
       move
       move
               #$3f,m0
       move
               #$3f,m4
       clr
               а
       clr
               b
       move
               #$0,x0
       move
               #$0,x1
       move
               #$0,y0
       move
               #$0,y1
       bset
               #4,omr
                               ; ebd
               #60, end
sbr
       dor
               x0,y0,ax:(r0)+,x1
       mac
                                      y: (r4) + , y1
       mac
               x1,y1,ax:(r0)+,x0
                                      y: (r4) + , y0
       add
               a,b
               x0,y0,ax:(r0)+,x1
       mac
               x1,y1,a
                                      y: (r4) + , y0
       mac
               b1,x:$ff
       move
_end
       bra
               sbr
       nop
       nop
       nop
       nop
PROG END
       nop
       nop
XDAT START
       org
               x:0
               $262EB9
       dc
               $86F2FE
       dc
               $E56A5F
       dc
               $616CAC
       dс
               $8FFD75
       dс
               $9210A
       dc
               $A06D7B
       dс
               $CEA798
       dс
               $8DFBF1
       dc
               $A063D6
```

DSP56301 Technical Data, Rev. 10

	dc	\$6C6657					
	dc	\$C2A544					
	dc	\$A3662D					
	dc	\$A4E762					
	dc	\$84F0F3					
	dc	\$E6F1B0					
	dc	\$B3829					
	dc	\$8BF7AE					
	dc	\$63A94F					
	dc	\$EF78DC					
	dc	\$242DE5					
	dc	\$A3E0BA					
	dc	\$EBAB6B					
	dc	\$8726C8					
	dc	\$CA361					
	dc	\$2F6E86					
	dc	\$A57347					
	dc	\$4BE774					
	dc	\$8F349D					
	dc	\$A1ED12					
	dc	\$4BFCE3					
	dc	\$EA26E0					
	dc	\$CD7D99					
	dc	\$4BA85E					
	dc	\$27A43F					
	dc	\$A8B10C					
	dc	\$D3A55					
	dc	\$25EC6A					
	dc	\$2A255B					
	dc	\$A5F1F8					
	dc	\$2426D1					
	dc	\$AE6536					
	dc	\$CBBC37					
	dc	\$6235A4					
	dc	\$37F0D					
	dc	\$63BEC2					
	dc	\$A5E4D3					
	dc	\$8CE810					
	dc	\$3FF09					
	dc	\$60E50E					
	dc	\$CFFB2F					
	dc	\$40753C					
	dc	\$8262C5					
	dc	\$CA641A					
	dc	\$EB3B4B					
	dc	\$2DA928					
	dc	\$AB6641					
	dc	\$28A7E6					
	dc	\$4E2127					
	dc	\$482FD4					
	dc	\$7257D					
	dc	\$E53C72					
	dc	\$1A8C3					
	dc	\$E27540					
XDAT_EN	ID						
IDIE (2015)							
YDAT_ST		0					
;	org	y:0					
	dc	\$5B6DA					
	dc	\$C3F70B					

dc	\$6A39E8
dc	\$81E801
dc	\$C666A6
dc	\$46F8E7
dc	\$AAEC94
dc	\$24233D
dc	\$802732
dc	\$2E3C83
dc	\$A43E00
dc	\$C2B639
dc	\$85A47E
dc	\$ABFDDF
dc	\$F3A2C
dc	\$2D7CF5
dc	\$E16A8A
dc	\$ECB8FB
dc	\$4BED18
dc	\$43F371
dc	\$83A556
dc	\$E1E9D7
dc	\$ACA2C4
dc	\$ACA2C4 \$8135AD
dc	\$2CE0E2
dc	\$8F2C73
dc	\$432730
dc	\$A87FA9
dc	\$4A292E
dc	\$A63CCF
dc	\$6BA65C
dc	\$E06D65
dc	\$1AA3A
dc	\$A1B6EB
dc	\$48AC48
dc	\$EF7AE1
dc	\$6E3006
dc	\$62F6C7
dc	\$6064F4
dc	\$87E41D
dc	\$CB2692
dc	\$2C3863
dc	\$C6BC60
dc	\$43A519
dc	\$6139DE
dc	\$ADF7BF
dc	\$4B3E8C
dc	\$6079D5
dc	\$E0F5EA
dc	\$8230DB
dc	\$A3B778
dc	\$2BFE51
dc	\$E0A6B6
dc	\$68FFB7
dc	\$28F324
dc	\$8F2E8D
dc	\$667842
dc	\$83E053
dc	\$A1FD90
dc	\$6B2689
dc	\$85B68E

dc

\$622EAF

DSP56301 Technical Data, Rev. 10

A-4 Freescale Semiconductor

```
dc
           $6162BC
     dс
           $E4A245
YDAT END
EQUATES for DSP56301 I/O registers and ports
     Reference: DSP56301 Specifications Revision 3.00
;
     Last update:
                 November 15 1993
;
       Changes:
                 GPIO for ports C,D and E,
                 HI32
                 DMA status reg
                     PLL control reg
                 AAR
                 SCI registers address
                 SSI registers addr. + split TSR from SSISR
     December 19 1993 (cosmetic - page and opt directives)
     August 9 1994 ESSI and SCI control registers bit update
;
page 132,55,0,0,0
     opt
           mex
ioequ ident 1,0
      EQUATES for I/O Port Programming
;------
      Register Addresses
M DATH EQU $FFFFCF; Host port GPIO data Register
M DIRH EQU $FFFFCE; Host port GPIO direction Register
M PCRC EQU $FFFFBF; Port C Control Register
M PRRC EQU $FFFFBE; Port C Direction Register
M PDRC EQU $FFFFBD ; Port C GPIO Data Register
M_PCRD EQU $FFFFAF ; Port D Control register
M_PRRD EQU $FFFFAE ; Port D Direction Data Register
M PDRD EQU $FFFFAD; Port D GPIO Data Register
M PCRE EQU $FFFF9F; Port E Control register
M PRRE EQU $FFFF9E; Port E Direction Register
M PDRE EQU $FFFF9D; Port E Data Register
M OGDB EQU $FFFFFC; OnCE GDB Register
;-----
    EOUATES for Host Interface
;-----
  Register Addresses
M DTXS EQU $FFFFCD; DSP SLAVE TRANSMIT DATA FIFO (DTXS)
M DTXM EQU $FFFFCC; DSP MASTER TRANSMIT DATA FIFO (DTXM)
M DRXR EQU $FFFFCB; DSP RECEIVE DATA FIFO (DRXR)
M DPSR EQU $FFFFCA; DSP PCI STATUS REGISTER (DPSR)
```

```
M DSR EQU $FFFFC9; DSP STATUS REGISTER (DSR)
M DPAR EQU $FFFFC8; DSP PCI ADDRESS REGISTER (DPAR)
M DPMC EQU $FFFFC7; DSP PCI MASTER CONTROL REGISTER (DPMC)
M DPCR EQU $FFFFC6; DSP PCI CONTROL REGISTER (DPCR)
M DCTR EQU $FFFFC5 ; DSP CONTROL REGISTER (DCTR)
        Host Control Register Bit Flags
M HCIE EOU 0 ; Host Command Interrupt Enable
M STIE EQU 1 ; Slave Transmit Interrupt Enable
M SRIE EQU 2 ; Slave Receive Interrupt Enable
M HF35 EQU $38 ; Host Flags 5-3 Mask
M HF3 EQU 3 ; Host Flag 3
             ; Host Flag 4
M HF4 EQU 4
M_HF5 EQU 5 ; Host Flag 5
M_HINT EQU 6 ; Host Interrupt A
M HDSM EQU 13 ; Host Data Strobe Mode
M HRWP EQU 14 ; Host RD/WR Polarity
M HTAP EQU 15 ; Host Transfer Acknowledge Polarity
M HDRP EQU 16 ; Host Dma Request Polarity
M HRSP EOU 17 ; Host Reset Polarity
M HIRP EQU 18 ; Host Interrupt Request Polarity
M HIRC EQU 19 ; Host Interupt Request Control
M HM0 EQU 20 ; Host Interface Mode
M HM1 EQU 21 ; Host Interface Mode
M HM2 EQU 22 ; Host Interface Mode
M HM EQU $700000 ; Host Interface Mode Mask
        Host PCI Control Register Bit Flags
M PMTIE EQU 1 ; PCI Master Transmit Interrupt Enable
M PMRIE EQU 2 ; PCI Master Receive Interrupt Enable
M PMAIE EQU 4 ; PCI Master Address Interrupt Enable
M PPEIE EQU 5 ; PCI Parity Error Interrupt Enable
M PTAIE EQU 7 ; PCI Transaction Abort Interrupt Enable
M PTTIE EQU 9 ; PCI Transaction Termination Interrupt Enable
M PTCIE EQU 12 ; PCI Transfer Complete Interrupt Enable
M CLRT EQU 14 ; Clear Transmitter
M_MTT EQU 15 ; Master Transfer Terminate
M SERF EQU 16 ; HSERR~ Force
M MACE EQU 18 ; Master Access Counter Enable
M MWSD EQU 19 ; Master Wait States Disable
M RBLE EQU 20 ; Receive Buffer Lock Enable
M IAE EQU 21 ; Insert Address Enable
        Host PCI Master Control Register Bit Flags
M ARH EQU $00ffff; DSP PCI Transaction Address (High)
M BL EQU $3f0000; PCI Data Burst Length
M FC EQU $c00000; Data Transfer Format Control
        Host PCI Address Register Bit Flags
M ARL EQU $00ffff; DSP PCI Transaction Address (Low)
M C EQU $0f0000; PCI Bus Command
M BE EQU $f00000; PCI Byte Enables
        DSP Status Register Bit Flags
M HCP EQU 0
            ; Host Command pending
```

DSP56301 Technical Data, Rev. 10

A-6 Freescale Semiconductor

```
M_STRQ EQU 1 ; Slave Transmit Data Request
M SRRQ EQU 2 ; Slave Receive Data Request
M HF02 EOU $38; Host Flag 0-2 Mask
M HF0 EQU 3 ; Host Flag 0
M HF1 EQU 4
            ; Host Flag 1
           ; Host Flag 2
M HF2 EQU 5
       DSP PCI Status Register Bit Flags
M MWS EQU 0
            ; PCI Master Wait States
M MTRQ EQU 1 ; PCI Master Transmit Data Request
M MRRQ EQU 2 ; PCI Master Receive Data Request
M_MARQ EQU 4 ; PCI Master Address Request
             ; PCI Address Parity Error
M APER EQU 5
                ; PCI Data Parity Error
M DPER EOU 6
             ; PCI Master Abort
M MAB EQU 7
M_TDIS EQU 9 ; PCT Taget Abort ; PCT Taget Abort
M_TDIS EQU 9 ; PCI Target Disconnect
M_TRTY EQU 10 ; PCI Target Retry
M TO EQU 11
             ; PCI Time Out Termination
M RDC EQU $3F0000; Remaining Data Count Mask (RDC5-RDC0)
M RDC0 EQU 16 ; Remaining Data Count 0
             ; Remaining Data Count 1; Remaining Data Count 2; Remaining Data Count 3
M RDC1 EQU 17
M RDC2 EQU 18
M RDC3 EQU 19
              ; Remaining Data Count 4
M RDC4 EQU 20
              ; Remaining Data Count 5
M RDC5 EOU 21
              ; Hi32 Active
M HACT EQU 23
;------
       EQUATES for Serial Communications Interface (SCI)
;
;-----
       Register Addresses
M STXH EQU $FFFF97; SCI Transmit Data Register (high)
M STXM EQU $FFFF96; SCI Transmit Data Register (middle)
M STXL EQU $FFFF95; SCI Transmit Data Register (low)
M SRXH EQU $FFFF9A; SCI Receive Data Register (high)
M SRXM EQU $FFFF99; SCI Receive Data Register (middle)
M SRXL EQU $FFFF98; SCI Receive Data Register (low)
M STXA EQU $FFFF94; SCI Transmit Address Register
M SCR EQU $FFFF9C; SCI Control Register
M SSR EQU $FFFF93; SCI Status Register
M SCCR EQU $FFFF9B; SCI Clock Control Register
       SCI Control Register Bit Flags
               ; Word Select Mask (WDS0-WDS3)
M WDS EQU $7
               ; Word Select 0
M WDS0 EQU 0
M WDS1 EQU 1
               ; Word Select 1
               ; Word Select 2
M WDS2 EQU 2
M SSFTD EQU 3
                ; SCI Shift Direction
M SBK EOU 4
               ; Send Break
                ; Wakeup Mode Select
M WAKE EQU 5
              ; Receiver Wakeup Enable
M RWU EQU 6
M WOMS EQU 7
                ; Wired-OR Mode Select
```

```
M SCRE EQU 8
                ; SCI Receiver Enable
              ; SCI Transmitter Enable
M SCTE EQU 9
               ; Idle Line Interrupt Enable
M ILIE EOU 10
               ; SCI Receive Interrupt Enable
M SCRIE EOU 11
M SCTIE EQU 12
                ; SCI Transmit Interrupt Enable
M TMIE EQU 13 ; Timer Interrupt Enable
M TIR EQU 14 ; Timer Interrupt Rate
M SCKP EQU 15 ; SCI Clock Polarity
M REIE EQU 16 ; SCI Error Interrupt Enable (REIE)
       SCI Status Register Bit Flags
                ; Transmitter Empty
M TRNE EQU 0
               ; Transmit Data Register Empty
M TDRE EQU 1
               ; Receive Data Register Full
M RDRF EOU 2
               ; Idle Line Flag
M IDLE EQU 3
M OR EQU 4
            ; Overrun Error Flag
M PE EOU 5
             ; Parity Error
             ; Framing Error Flag
M FE EQU 6
M R8 EQU 7
              ; Received Bit 8 (R8) Address
       SCI Clock Control Register
M CD EQU $FFF
              ; Clock Divider Mask (CD0-CD11)
              ; Clock Out Divider
M COD EQU 12
               ; Clock Prescaler
M SCP EQU 13
             ; Receive Clock Mode Source Bit
M RCM EOU 14
              ; Transmit Clock Source Bit
M TCM EQU 15
;-----
      EQUATES for Synchronous Serial Interface (SSI)
;
       Register Addresses Of SSIO
M TX00 EQU $FFFFBC; SSI0 Transmit Data Register 0
M TX01 EQU $FFFFBB; SSIO Transmit Data Register 1
M TX02 EQU $FFFFBA; SSIO Transmit Data Register 2
M TSRO EQU $FFFFB9; SSIO Time Slot Register
M RX0 EQU $FFFFB8; SSI0 Receive Data Register
M SSISRO EQU $FFFFB7; SSIO Status Register
M CRBO EQU $FFFFB6; SSIO Control Register B
M CRAO EQU $FFFFB5; SSIO Control Register A
M TSMAO EQU $FFFFB4; SSIO Transmit Slot Mask Register A
M TSMB0 EQU $FFFFB3; SSI0 Transmit Slot Mask Register B
M RSMAO EQU $FFFFB2; SSIO Receive Slot Mask Register A
M RSMBO EQU $FFFFB1; SSIO Receive Slot Mask Register B
       Register Addresses Of SSI1
M TX10 EQU $FFFFAC; SSI1 Transmit Data Register 0
M_TX11 EQU $FFFFAB; SSI1 Transmit Data Register 1
M TX12 EQU $FFFFAA; SSI1 Transmit Data Register 2
M TSR1 EQU $FFFFA9; SSI1 Time Slot Register
M RX1 EQU $FFFFA8; SSI1 Receive Data Register
M SSISR1 EQU $FFFFA7; SSI1 Status Register
M CRB1 EQU $FFFFA6; SSI1 Control Register B
M CRA1 EQU $FFFFA5; SSI1 Control Register A
M TSMA1 EQU $FFFFA4; SSI1 Transmit Slot Mask Register A
```

DSP56301 Technical Data, Rev. 10

A-8 Freescale Semiconductor

```
M TSMB1 EQU $FFFFA3; SSI1 Transmit Slot Mask Register B
M RSMA1 EQU $FFFFA2; SSI1 Receive Slot Mask Register A
M RSMB1 EQU $FFFFA1; SSI1 Receive Slot Mask Register B
        SSI Control Register A Bit Flags
               ; Prescale Modulus Select Mask (PMO-PM7)
M PM EQU $FF
M PSR EQU 11
               ; Prescaler Range
M DC EQU $1F000 ; Frame Rate Divider Control Mask (DC0-DC7)
M ALC EQU 18 ; Alignment Control (ALC)
M WL EQU $380000; Word Length Control Mask (WLO-WL7)
M SSC1 EQU 22 ; Select SC1 as TR #0 drive enable (SSC1)
        SSI Control Register B Bit Flags
M OF EQU $3
              ; Serial Output Flag Mask
M OFO EQU 0
             ; Serial Output Flag 0
M_OF1 EQU 1 ; Serial Output Flag 1
M SCD EQU $1C ; Serial Control Direction Mask
M SCD0 EQU 2 ; Serial Control 0 Direction
M\_SCD1 EQU 3 ; Serial Control 1 Direction M\_SCD2 EQU 4 ; Serial Control 2 Direction
M FSL EQU $180; Frame Sync Length Mask (FSL0-FSL1)
M FSL0 EQU 7 ; Frame Sync Length 0
M_FSL1 EQU 8 ; Frame Sync Length 1
{\tt M\_FSR} EQU 9 ; Frame Sync Relative Timing
M FSP EQU 10 ; Frame Sync Polarity
M_CKP EQU 11 ; Clock Polarity
M SYN EQU 12 ; Sync/Async Control
M MOD EQU 13 ; SSI Mode Select
M SSTE EOU $1C000; SSI Transmit enable Mask
M SSTE2 EQU 14; SSI Transmit #2 Enable
M SSTE1 EQU 15 ; SSI Transmit #1 Enable
M SSTE0 EQU 16; SSI Transmit #0 Enable
M SSRE EQU 17 ; SSI Receive Enable
M SSTIE EQU 18; SSI Transmit Interrupt Enable
M SSRIE EQU 19; SSI Receive Interrupt Enable
M STLIE EQU 20; SSI Transmit Last Slot Interrupt Enable
M SRLIE EQU 21; SSI Receive Last Slot Interrupt Enable
M STEIE EQU 22; SSI Transmit Error Interrupt Enable
M SREIE EQU 23 ; SSI Receive Error Interrupt Enable
        SSI Status Register Bit Flags
M IF EQU $3
               ; Serial Input Flag Mask
              ; Serial Input Flag 0
M IFO EQU O
               ; Serial Input Flag 1
M IF1 EQU 1
               ; Transmit Frame Sync Flaq
M TFS EOU 2
               ; Receive Frame Sync Flag
M RFS EQU 3
               ; Transmitter Underrun Error FLag
M TUE EQU 4
M ROE EQU 5
               ; Receiver Overrun Error Flag
M TDE EQU 6
               ; Transmit Data Register Empty
M RDF EQU 7
                ; Receive Data Register Full
        SSI Transmit Slot Mask Register A
M SSTSA EQU $FFFF ; SSI Transmit Slot Bits Mask A (TSO-TS15)
```

```
SSI Transmit Slot Mask Register B
;
M SSTSB EQU $FFFF ; SSI Transmit Slot Bits Mask B (TS16-TS31)
        SSI Receive Slot Mask Register A
M SSRSA EQU $FFFF ; SSI Receive Slot Bits Mask A (RSO-RS15)
        SSI Receive Slot Mask Register B
M SSRSB EQU $FFFF ; SSI Receive Slot Bits Mask B (RS16-RS31)
        EQUATES for Exception Processing
        Register Addresses
M IPRC EQU $FFFFFF; Interrupt Priority Register Core
M IPRP EQU $FFFFFE; Interrupt Priority Register Peripheral
        Interrupt Priority Register Core (IPRC)
M IAL EQU $7
                ; IRQA Mode Mask
                ; IRQA Mode Interrupt Priority Level (low)
M IALO EQU 0
                ; IRQA Mode Interrupt Priority Level (high)
M IAL1 EQU 1
M IAL2 EOU 2
                ; IRQA Mode Trigger Mode
M IBL EQU $38 ; IRQB Mode Mask
                 ; IRQB Mode Interrupt Priority Level (low)
M IBLO EQU 3
                ; IRQB Mode Interrupt Priority Level (high)
M IBL1 EQU 4
                 ; IRQB Mode Trigger Mode
M IBL2 EQU 5
M_ICL EQU $1C0 ; IRQC Mode Mask
               ; IRQC Mode Interrupt Priority Level (low)
M ICLO EOU 6
                ; IRQC Mode Interrupt Priority Level (high)
M ICL1 EQU 7
M ICL2 EQU 8
                ; IRQC Mode Trigger Mode
M IDL EQU $E00 ; IRQD Mode Mask
                ; IRQD Mode Interrupt Priority Level (low)
M IDLO EQU 9
M IDL1 EQU 10 ; IRQD Mode Interrupt Priority Level (high)
M IDL2 EQU 11 ; IRQD Mode Trigger Mode
M DOL EQU $3000 ; DMAO Interrupt priority Level Mask
              ; DMAO Interrupt Priority Level (low)
M DOLO EQU 12
M DOL1 EQU 13
                 ; DMA0 Interrupt Priority Level (high)
M D1L EQU $C000 ; DMA1 Interrupt Priority Level Mask
               ; DMA1 Interrupt Priority Level (low)
; DMA1 Interrupt Priority Level (high)
M D1L0 EQU 14
M D1L1 EOU 15
M D2L EQU $30000 ; DMA2 Interrupt priority Level Mask
\label{eq:md2} \mbox{M\_D2L0 EQU 16} \qquad \mbox{; DMA2 Interrupt Priority Level (low)}
M D2L1 EQU 17
                ; DMA2 Interrupt Priority Level (high)
M D3L EQU $C0000; DMA3 Interrupt Priority Level Mask
               ; DMA3 Interrupt Priority Level (low)
M D3L0 EQU 18
M D3L1 EOU 19
                 ; DMA3 Interrupt Priority Level (high)
M D4L EQU $300000; DMA4 Interrupt priority Level Mask
M D4L0 EQU 20 ; DMA4 Interrupt Priority Level (low)
M D4L1 EQU 21
                 ; DMA4 Interrupt Priority Level (high)
```

DSP56301 Technical Data, Rev. 10

A-10 Freescale Semiconductor

```
M D5L EQU $C00000; DMA5 Interrupt priority Level Mask
M D5L0 EQU 22 ; DMA5 Interrupt Priority Level (low)
M D5L1 EOU 23
               ; DMA5 Interrupt Priority Level (high)
       Interrupt Priority Register Peripheral (IPRP)
M HPL EQU $3
              ; Host Interrupt Priority Level Mask
               ; Host Interrupt Priority Level (low)
M HPLO EOU 0
M HPL1 EQU 1
               ; Host Interrupt Priority Level (high)
              ; SSIO Interrupt Priority Level Mask
M SOL EQU $C
              ; SSIO Interrupt Priority Level (low)
M SOLO EQU 2
               ; SSIO Interrupt Priority Level (high)
M SOL1 EQU 3
M_S1L EQU $30 ; SSI1 Interrupt Priority Level Mask
M_S1L0 EQU 4 ; SSI1 Interrupt Priority Level (low)
               ; SSI1 Interrupt Priority Level (high)
M S1L1 EQU 5
M SCL EQU $CO ; SCI Interrupt Priority Level Mask
M_SCL0 EQU 6 ; SCI Interrupt Priority Level (low)
M_SCL1 EQU 7 ; SCI Interrupt Priority Level (high)
M TOL EQU $300 ; TIMER Interrupt Priority Level Mask
               ; TIMER Interrupt Priority Level (low)
M TOLO EOU 8
M TOL1 EQU 9
               ; TIMER Interrupt Priority Level (high)
;-----
       EQUATES for TIMER
;-----
       Register Addresses Of TIMERO
M TCSR0 EQU $FFFF8F; TIMER0 Control/Status Register
M TLRO EQU $FFFF8E; TIMERO Load Reg
M_TCPR0 EQU $FFFF8D; TIMER0 Compare Register
M TCRO EQU $FFFF8C; TIMERO Count Register
       Register Addresses Of TIMER1
M TCSR1 EQU $FFFF8B; TIMER1 Control/Status Register
M TLR1 EQU $FFFF8A; TIMER1 Load Req
M TCPR1 EQU $FFFF89; TIMER1 Compare Register
M TCR1 EQU $FFFF88; TIMER1 Count Register
       Register Addresses Of TIMER2
M TCSR2 EQU $FFFF87; TIMER2 Control/Status Register
M TLR2 EQU $FFFF8; TIMER2 Load Req
M TCPR2 EQU $FFFF85; TIMER2 Compare Register
M TCR2 EQU $FFFF84 ; TIMER2 Count Register
M TPLR EQU $FFFF83; TIMER Prescaler Load Register
M TPCR EQU $FFFF82; TIMER Prescalar Count Register
       Timer Control/Status Register Bit Flags
              ; Timer Enable
M TE EQU 0
              ; Timer Overflow Interrupt Enable
M TOIE EQU 1
                ; Timer Compare Interrupt Enable
M TCIE EQU 2
```

```
; Timer Control Mask (TC0-TC3)
M TC EQU $F0
; Timer Restart Mode
M_DIR EQU 11 ; Direction Bit
M_DI EQU 12 ; Data Input
M_DO EQU 13 ; Data Output
M PCE EQU 15 ; Prescaled Clock Enable
{\tt M\_TOF} EQU 20 ; Timer Overflow Flag
M TCF EQU 21
              ; Timer Compare Flag
       Timer Prescaler Register Bit Flags
M PS EQU $600000 ; Prescaler Source Mask
M PS0 EQU 21
M PS1 EQU 22
      Timer Control Bits
M_TC0 EQU 4 ; Timer Control 0
M_TC1 EQU 5 ; Timer Control 1
M_TC2 EQU 6 ; Timer Control 2
M_TC3 EQU 7 ; Timer Control 3
;-----
;
       EQUATES for Direct Memory Access (DMA)
       Register Addresses Of DMA
M DSTR EQU $FFFFF4; DMA Status Register
M DORO EQU $FFFFF3; DMA Offset Register 0
M DOR1 EQU $FFFFF2; DMA Offset Register 1
M DOR2 EQU $FFFFF1; DMA Offset Register 2
M DOR3 EQU $FFFFF0; DMA Offset Register 3
       Register Addresses Of DMA0
M DSR0 EQU $FFFFEF; DMA0 Source Address Register
M DDR0 EQU $FFFFEE; DMA0 Destination Address Register
M DCOO EQU $FFFFED; DMAO Counter
M DCR0 EQU $FFFFEC; DMA0 Control Register
       Register Addresses Of DMA1
M DSR1 EQU $FFFFEB; DMA1 Source Address Register
M DDR1 EQU $FFFFEA; DMA1 Destination Address Register
M DCO1 EQU $FFFFE9; DMA1 Counter
M DCR1 EQU $FFFFE8; DMA1 Control Register
       Register Addresses Of DMA2
M DSR2 EQU $FFFFE7; DMA2 Source Address Register
M DDR2 EQU $FFFFE6; DMA2 Destination Address Register
M DCO2 EQU $FFFFE5; DMA2 Counter
M DCR2 EQU $FFFFE4; DMA2 Control Register
       Register Addresses Of DMA4
```

DSP56301 Technical Data, Rev. 10

A-12 Freescale Semiconductor

```
M DSR3 EQU $FFFFE3; DMA3 Source Address Register
M DDR3 EQU $FFFFE2; DMA3 Destination Address Register
M DCO3 EQU $FFFFE1; DMA3 Counter
M DCR3 EQU $FFFFE0; DMA3 Control Register
        Register Addresses Of DMA4
M DSR4 EQU $FFFFDF; DMA4 Source Address Register
M DDR4 EQU $FFFFDE; DMA4 Destination Address Register
M DCO4 EQU $FFFFDD; DMA4 Counter
M DCR4 EQU $FFFFDC; DMA4 Control Register
        Register Addresses Of DMA5
M DSR5 EQU $FFFFDB; DMA5 Source Address Register
M DDR5 EQU $FFFFDA; DMA5 Destination Address Register
M DCO5 EQU $FFFFD9; DMA5 Counter
M DCR5 EQU $FFFFD8; DMA5 Control Register
       DMA Control Register
M DSS EQU $3 ; DMA Source Space Mask (DSS0-Dss1)
M DSS0 EQU 0 ; DMA Source Memory space 0
M DSS1 EQU 1 ; DMA Source Memory space 1
M_DDS EQU $C ; DMA Destination Space Mask (DDS-DDS1)
M_DDS0 EQU 2 ; DMA Destination Memory Space 0 M_DDS1 EQU 3 ; DMA Destination Memory Space 1
M DAM EQU $3F0; DMA Address Mode Mask (DAM5-DAM0)
M_DAMO EQU 4 ; DMA Address Mode 0
M DAM1 EQU 5 ; DMA Address Mode 1
M DAM2 EQU 6 ; DMA Address Mode 2
M DAM3 EOU 7 ; DMA Address Mode 3
M DAM4 EQU 8 ; DMA Address Mode 4
M DAM5 EQU 9 ; DMA Address Mode 5
M D3D EQU 10 ; DMA Three Dimensional Mode
M DRS EQU $F800; DMA Request Source Mask (DRS0-DRS4)
M DCON EQU 16 ; DMA Continuous Mode
M DPR EOU $60000; DMA Channel Priority
M DPR0 EQU 17 ; DMA Channel Priority Level (low)
M DPR1 EQU 18 ; DMA Channel Priority Level (high)
M DTM EQU $380000; DMA Transfer Mode Mask (DTM2-DTM0)
M DTMO EQU 19 ; DMA Transfer Mode 0
M DTM1 EQU 20 ; DMA Transfer Mode 1
M DTM2 EQU 21 ; DMA Transfer Mode 2
M DIE EQU 22 ; DMA Interrupt Enable bit
              ; DMA Channel Enable bit
M DE EQU 23
        DMA Status Register
M DTD EQU $3F ; Channel Transfer Done Status MASK (DTD0-DTD5)
{	t M\_DTD0} EQU 0 ; DMA Channel Transfer Done Status 0
M DTD1 EQU 1
                 ; DMA Channel Transfer Done Status 1
M DTD2 EQU 2
                ; DMA Channel Transfer Done Status 2
M DTD3 EQU 3
                ; DMA Channel Transfer Done Status 3
                ; DMA Channel Transfer Done Status 4
M DTD4 EQU 4
                 ; DMA Channel Transfer Done Status 5
M DTD5 EQU 5
M DACT EQU 8 ; DMA Active State
M DCH EQU $E00; DMA Active Channel Mask (DCH0-DCH2)
M DCHO EQU 9 ; DMA Active Channel 0
```

```
M DCH1 EQU 10 ; DMA Active Channel 1
M DCH2 EQU 11 ; DMA Active Channel 2
;-----
      EQUATES for Phase Lock Loop (PLL)
;------
      Register Addresses Of PLL
M PCTL EQU $FFFFFD; PLL Control Register
      PLL Control Register
M MF EQU $FFF ; Multiplication Factor Bits Mask (MF0-MF11)
M_DF EQU $7000 ; Division Factor Bits Mask (DF0-DF2)
M\_XTLR EQU 15 ; XTAL Range select bit
M XTLD EQU 16 ; XTAL Disable Bit
M PSTP EQU 17 ; STOP Processing State Bit
M PEN EQU 18
             ; PLL Enable Bit
M PCOD EQU 19 ; PLL Clock Output Disable Bit
M PD EQU $F00000; PreDivider Factor Bits Mask (PD0-PD3)
;-----
      EQUATES for BIU
;-----
      Register Addresses Of BIU
M BCR EQU $FFFFFB; Bus Control Register
M DCR EQU $FFFFFA; DRAM Control Register
M AARO EQU $FFFFF9; Address Attribute Register 0
M AAR1 EQU $FFFFF8; Address Attribute Register 1
M AAR2 EQU $FFFFF7; Address Attribute Register 2
M AAR3 EQU $FFFFF6; Address Attribute Register 3
M IDR EQU $FFFFF5; ID Register
      Bus Control Register
M BAOW EQU $1F ; Area 0 Wait Control Mask (BAOW0-BAOW4)
M BA1W EQU $3E0 ; Area 1 Wait Control Mask (BA1W0-BA14)
M BA2W EQU $1C00 ; Area 2 Wait Control Mask (BA2W0-BA2W2)
M BA3W EQU $E000 ; Area 3 Wait Control Mask (BA3W0-BA3W3)
M BDFW EQU $1F0000; Default Area Wait Control Mask (BDFW0-BDFW4)
M_BBS EQU 21 ; Bus State
             ; Bus Lock Hold
M BLH EQU 22
M BRH EQU 23 ; Bus Request Hold
      DRAM Control Register
             ; In Page Wait States Bits Mask (BCW0-BCW1)
M BCW EOU $3
M BRW EQU $C
              ; Out Of Page Wait States Bits Mask (BRW0-BRW1)
M_BPS EQU $300 ; DRAM Page Size Bits Mask (BPS0-BPS1)
M BPLE EQU 11
              ; Page Logic Enable
```

DSP56301 Technical Data, Rev. 10

A-14 Freescale Semiconductor

```
M BME EQU 12
               ; Mastership Enable
              ; Refresh Enable
; Software Triggered Refresh
M BRE EQU 13
M BSTR EOU 14
M BRF EQU $7F8000; Refresh Rate Bits Mask (BRF0-BRF7)
                ; Refresh prescaler
M BRP EQU 23
       Address Attribute Registers
M BAT EOU $3
                ; External Access Type and Pin Definition Bits Mask (BATO-BAT1)
M BAAP EOU 2
                ; Address Attribute Pin Polarity
M BPEN EQU 3
                 ; Program Space Enable
                ; X Data Space Enable
M BXEN EOU 4
                ; Y Data Space Enable
M BYEN EQU 5
M BAM EQU 6
                ; Address Muxing
M_BPAC EQU 7 ; Packing Enable
M BNC EQU $F00 ; Number of Address Bits to Compare Mask (BNC0-BNC3)
M BAC EQU $FFF000; Address to Compare Bits Mask (BAC0-BAC11)
       control and status bits in SR
M CP EQU $c00000 ; mask for CORE-DMA priority bits in SR
               ; Carry
M CA EQU 0
M V EQU 1
               ; Overflow
              ; Zero
M Z EQU 2
             ; Negative
M N EQU 3
             ; Unnormalized
M U EQU 4
             ; Extension
M E EOU 5
             ; Limit
M L EQU 6
             ; Scaling Bit
M S EQU 7
              ; Interupt Mask Bit 0
M IO EQU 8
               ; Interupt Mask Bit 1
M I1 EQU 9
M SO EQU 10
               ; Scaling Mode Bit 0
               ; Scaling Mode Bit 1
M S1 EOU 11
M SC EQU 13
               ; Sixteen Bit Compatibility
M DM EQU 14
                ; Double Precision Multiply
               ; DO-Loop Flag
M LF EQU 15
               ; DO-Forever Flag
M FV EQU 16
               ; Sixteen-Bit Arithmetic
M SA EQU 17
               ; Instruction Cache Enable
M CE EOU 19
               ; Arithmetic Saturation
M SM EQU 20
M RM EQU 21
               ; Rounding Mode
M CP0 EQU22
               ; bit 0 of priority bits in SR
                ; bit 1 of priority bits in SR
M CP1 EQU 23
       control and status bits in OMR
M CDP EQU$300 ; mask for CORE-DMA priority bits in OMR
                ; Operating Mode A
M MA EQU 0
                ; Operating Mode B
M MB EQU 1
               ; Operating Mode C
M MC EQU 2
               ; Operating Mode D
M MD EQU 3
M EBD EOU 4
                ; External Bus Disable bit in OMR
               ; Stop Delay
M SD EQU 6
               ; bit 0 of priority bits in OMR
M CDP0 EQU 8
M CDP1 EQU 9
                 ; bit 1 of priority bits in OMR
M BEN EQU 10
                ; Burst Enable
                ; TA Synchronize Select
M TAS EQU 11
M BRT EOU 12
                ; Bus Release Timing
                ; Stack Extension space select bit in OMR.
M XYS EQU 16
             ; Extensed stack UNderflow flag in OMR.
M EUN EQU 17
M EOV EQU 18
                 ; Extended stack OVerflow flag in OMR.
```

```
M WRP EQU 19
            ; Extended WRaP flag in OMR.
M SEN EOU 20
           ; Stack Extension Enable bit in OMR.
;***********************************
    EQUATES for DSP56301 interrupts
    Reference: DSP56301 Specifications Revision 3.00
    Last update: November 15 1993 (Debug request & HI32 interrupts)
            December 19 1993 (cosmetic - page and opt directives)
          August 16 1994 (change interrupt addresses to be
;
               relative to I VEC)
page
         132,55,0,0,0
     opt
          mex
intequ ident 1,0
     if
        @DEF(I VEC)
     ; leave user definition as is.
I VEC equ
          $0
     endif
; Non-Maskable interrupts
;-----
I RESET EQU I VEC+$00 ; Hardware RESET
I STACK EQU I_VEC+$02 ; Stack Error
I ILL EQU I VEC+$04 ; Illegal Instruction
I DBG EQU I VEC+$06 ; Debug Request
I TRAP EQU I VEC+$08 ; Trap
I NMI EQU I VEC+$0A ; Non Maskable Interrupt
;-----
; Interrupt Request Pins
;------
I_IRQA EQU I_VEC+$10 ; IRQA
I_IRQB EQU I_VEC+$12 ; IRQB
I_IRQC EQU I_VEC+$14 ; IRQC
I IRQD EQU I VEC+$16 ; IRQD
;-----
; DMA Interrupts
;-----
I DMA0 EQU I VEC+$18 ; DMA Channel 0
I_DMA1 EQU I_VEC+$1A ; DMA Channel 1
I_DMA2 EQU I_VEC+$1C ; DMA Channel 2
I_DMA3 EQU I_VEC+$1E ; DMA Channel 3
I DMA4
     EQU I_VEC+$20 ; DMA Channel 4
I DMA5
     EQU I VEC+$22 ; DMA Channel 5
;------
; Timer Interrupts
;-----
I TIMOC EQU I VEC+$24 ; TIMER 0 compare
I TIMOOF EQU I VEC+$26 ; TIMER 0 overflow
```

DSP56301 Technical Data, Rev. 10

```
I TIM1C EQU I VEC+$28
                   ; TIMER 1 compare
\label{eq:continuous_section} \mbox{I\_TIM1OF EQU} \quad \mbox{I\_VEC+$2A} \quad \  ; \ \mbox{TIMER 1 overflow}
\label{eq:compare} \mbox{I\_TIM2C} \ \ \mbox{EQU} \ \ \mbox{I\_VEC+$2C} \ \ ; \ \mbox{TIMER} \ \mbox{2 compare}
I TIM2OF EQU I VEC+$2E ; TIMER 2 overflow
;-----
; ESSI Interrupts
;-----
I SIORD EQU I VEC+$30 ; ESSIO Receive Data
I SIORDE EQU I VEC+$32 ; ESSIO Receive Data With Exception Status
I SIORLS EQU I VEC+$34 ; ESSIO Receive last slot
I SIOTD EQU I VEC+$36 ; ESSIO Transmit data
I_SIOTDE EQU I_VEC+$38 ; ESSIO Transmit Data With Exception Status
I_SIOTLS EQU I_VEC+$3A ; ESSIO Transmit last slot
<code>I_SI1RD</code> EQU <code>I_VEC+$40</code> ; ESSI1 Receive Data
I_SI1RDE EQU I_VEC+$42 ; ESSI1 Receive Data With Exception Status
<code>I_SI1RLS EQU I_VEC+$44</code> ; <code>ESSI1 Receive last slot</code>
I_SI1TD EQU I_VEC+$46 ; ESSI1 Transmit data
<code>I_SI1TDE EQU I_VEC+$48</code> ; <code>ESSI1 Transmit Data With Exception Status</code>
I SI1TLS EQU I VEC+$4A ; ESSI1 Transmit last slot
;-----
; SCI Interrupts
;-----
I SCIRD EQU I VEC+$50 ; SCI Receive Data
I_SCIRDE EQU I_VEC+$52 ; SCI Receive Data With Exception Status
I_SCITD EQU I_VEC+$54 ; SCI Transmit Data
I_SCIIL EQU I_VEC+$56 ; SCI Idle Line
I SCITM EQU I VEC+$58 ; SCI Timer
;-----
; HOST Interrupts
:-----
I HPTT EQU I VEC+$60 ; Host PCI Transaction Termination
I HPTA EQU I VEC+$62 ; Host PCI Transaction Abort
I HPPE EQU I VEC+$64 ; Host PCI Parity Error
I_HPTC EQU I_VEC+$66 ; Host PCI Transfer Complete
I_HPMR      EQU      I_VEC+$68      ; Host PCI Master Receive
      EQU I_VEC+$6A ; Host Slave Receive
I HSR
I_HPMT EQU I_VEC+$6C ; Host PCI Master Transmit
I HPMA EQU I_VEC+$70 ; Host PCI Master Address
I HCNMI EQU I VEC+$72 ; Host Command/Host NMI (Default)
;-----
: INTERRUPT ENDING ADDRESS
;-----
I_INTEND EQU I_VEC+$FF ; last address of interrupt vector space
```

Ordering Information

Consult a Freescale Semiconductor sales office or authorized distributor to determine product availability and place an order.

Part	Supply Voltage	Package Type	Pin Count	Core Frequency (MHz)	Solder Spheres	Order Number
DSP56301 3.3 V	Thin Quad Flat Pack (TQFP)	208	80	Lead-free	DSP56301AG80	
				Lead-bearing	DSP56301PW80	
			100	Lead-free	DSP56301AG100	
				Lead-bearing	DSP56301PW100	
		Molded Array Process-Ball Grid	252	80	Lead-free	DSP56301VL80
	Array (MAP-BGA)			Lead-bearing	DSP56301VF80	
			100	Lead-free	DSP56301VL100	
					Lead-bearing	DSP56301VF100

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